Characterization report of Vendor D VCSELs

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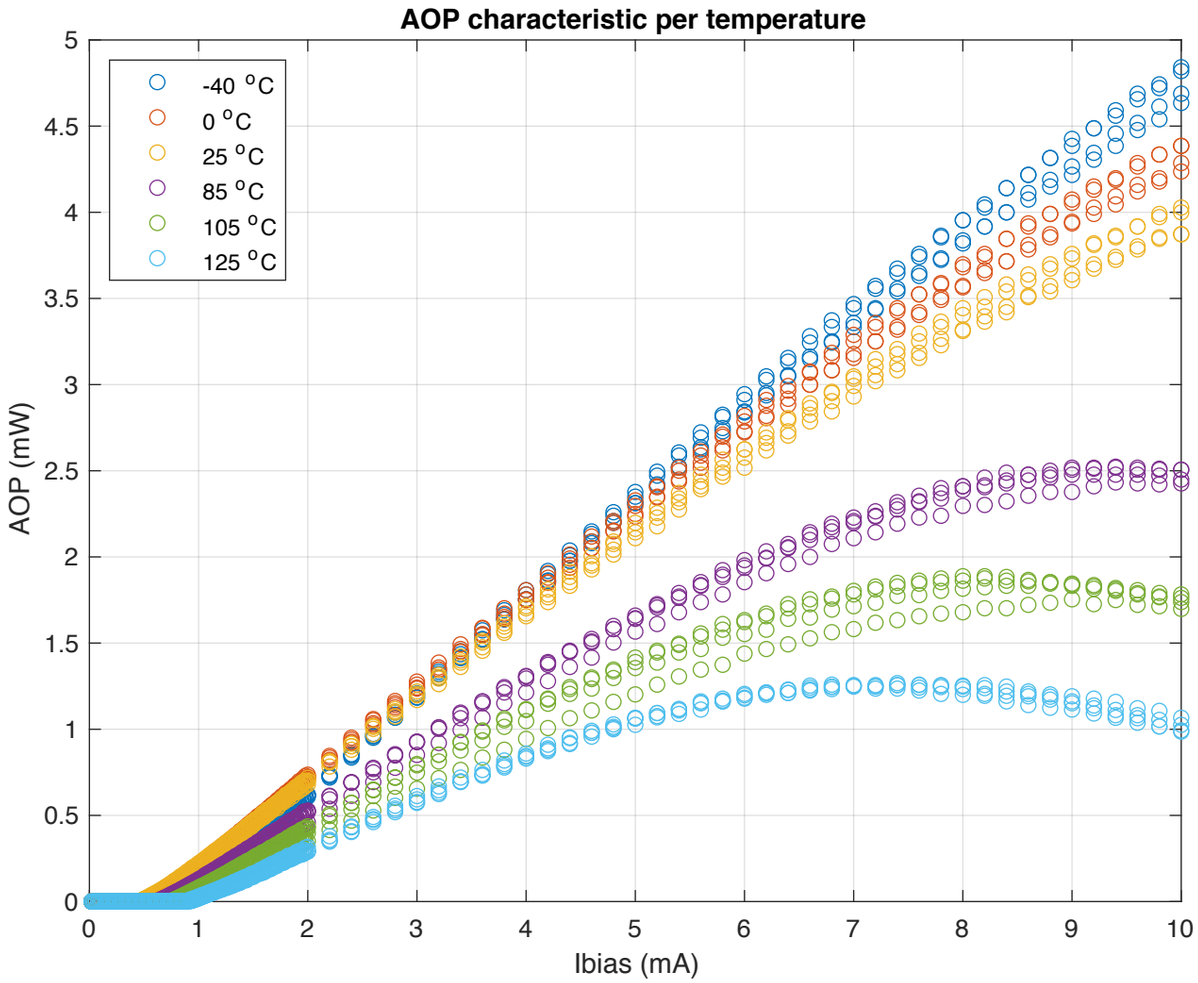
IEEE 802.3 OMEGA Task Force - July 2020 Plenary

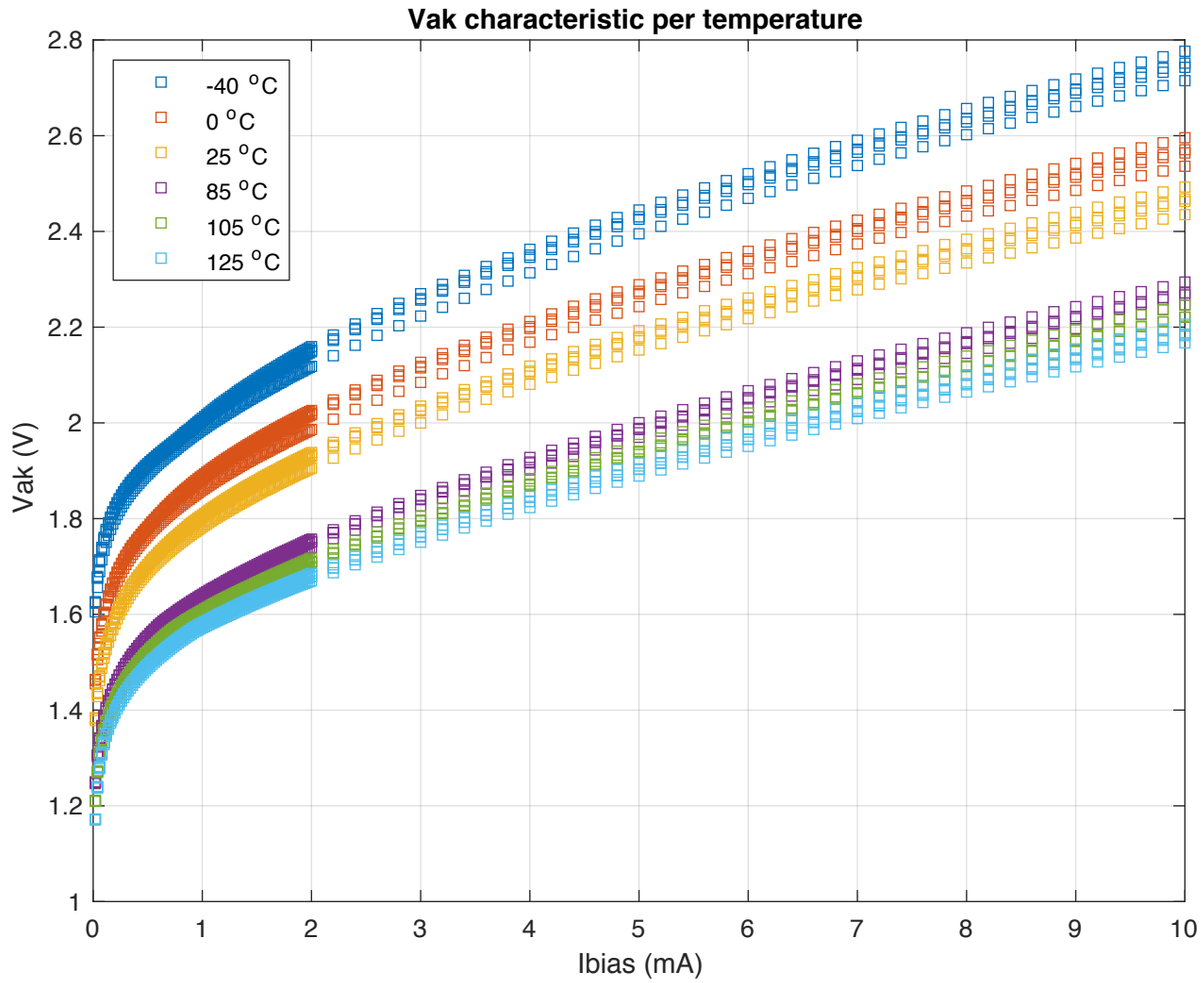
Introduction

- KDPOF has characterized 3 different Vendor D VCSEL designs
  - 25Gbps (designed for NRZ, 25GBd) multimode VCSEL for 850 nm, low threshold
  - 25Gbps (designed for NRZ, 25GBd) multimode VCSEL for 850 nm, high threshold
  - 25Gbps (designed for NRZ, 25GBd) multimode VCSEL for 990 nm
- L-I-V, AC and RIN have been measured according to test methodologies explained in perezaranda_OMEGA_01_0720_VCSEL_test_methods.pdf
- All the test parameters have been measured at -40, 0, 25, 85, 105 and 125 ºC backside temperature
- Eye diagrams for 26.5625 GBd NRZ are shown
  - These eye diagrams are not intended to assess suitability of an specific VCSEL for OMEGA application.
  - These eye diagrams are intended to illustrate the effect of temperature and current in the VCSELs response
- Next step will be to carry out link budget analysis

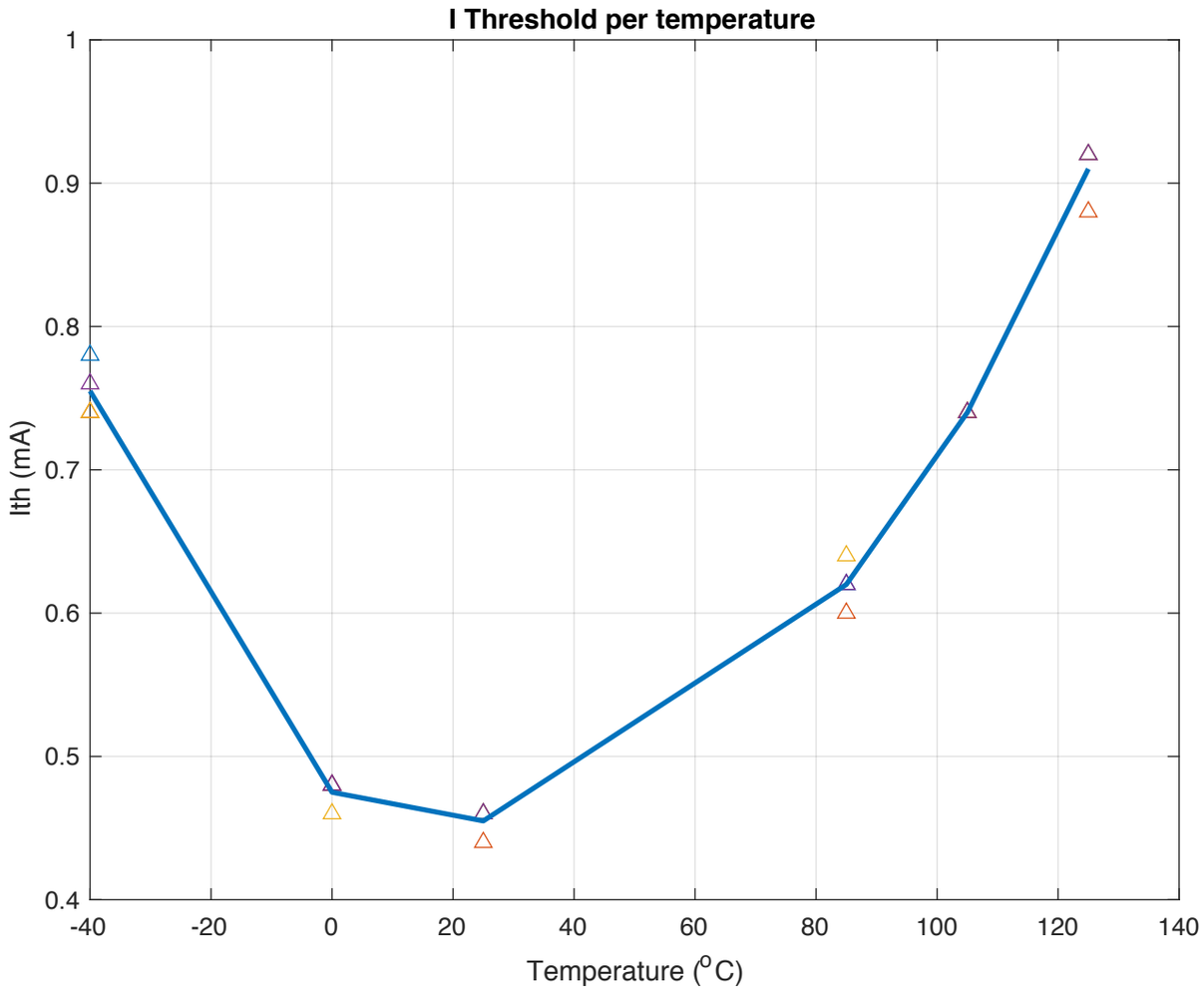
25Gbps multimode VCSEL for 850 nm, low threshold

L-I-V characteristic

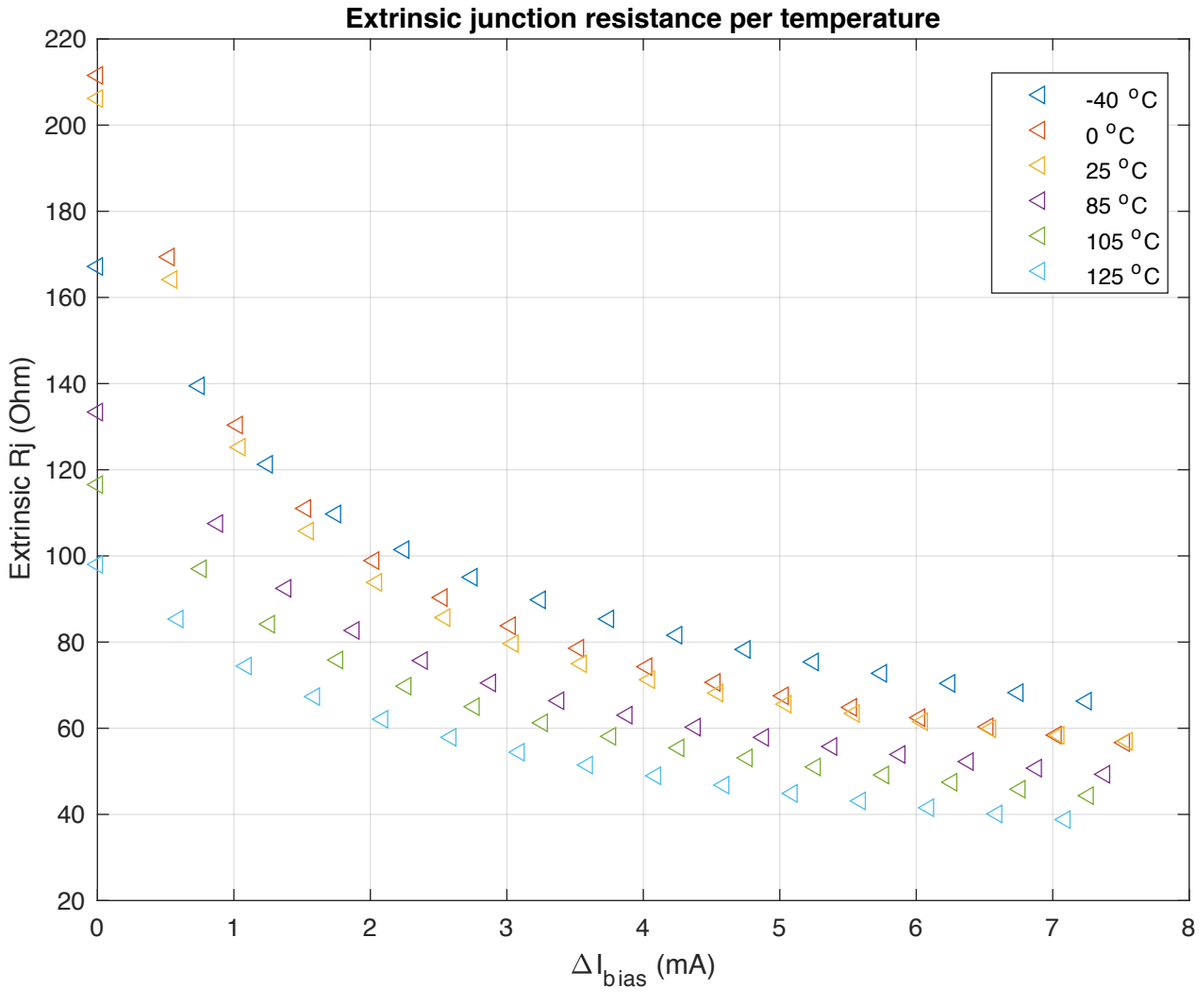


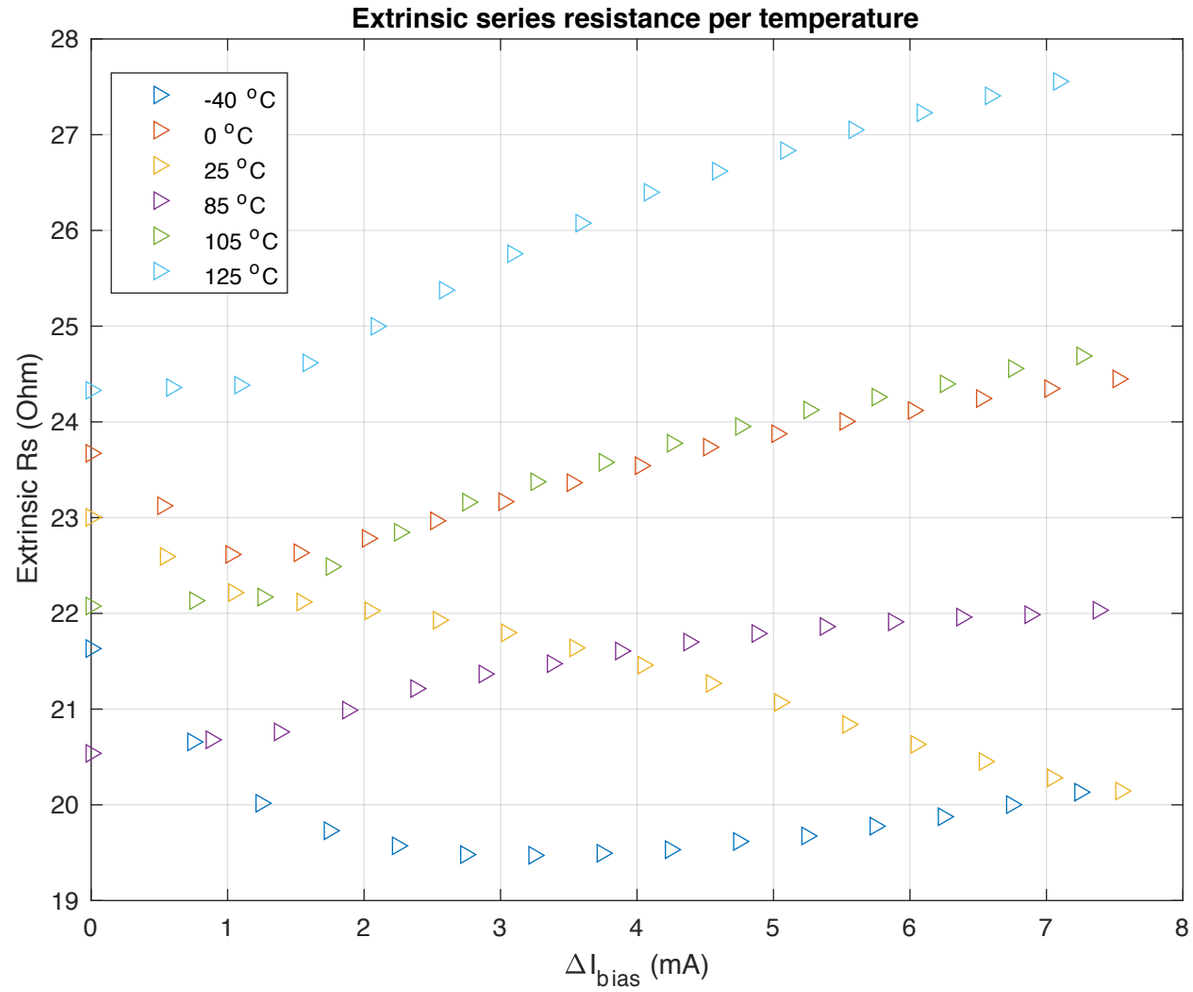


Threshold current characteristic

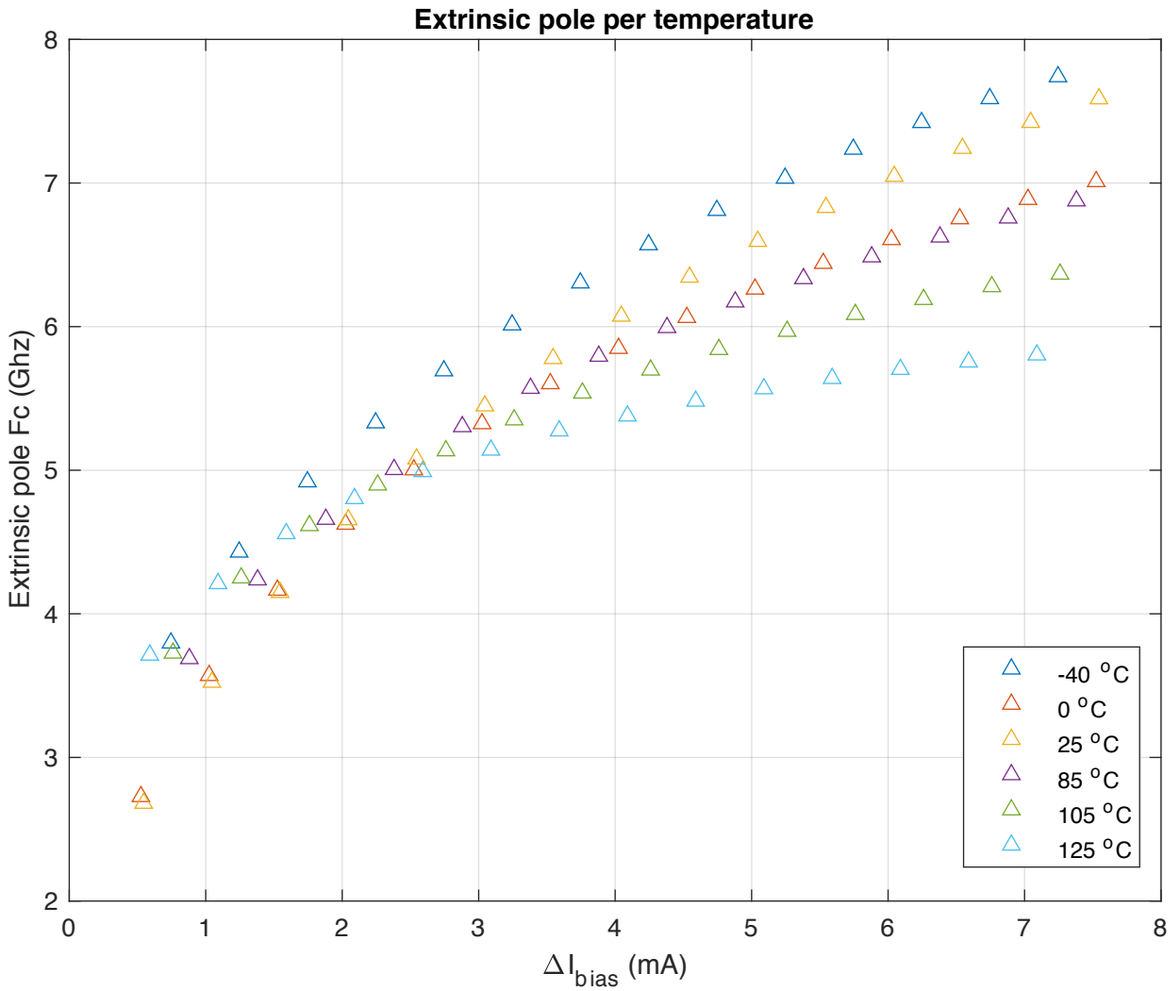


Small signal frequency response



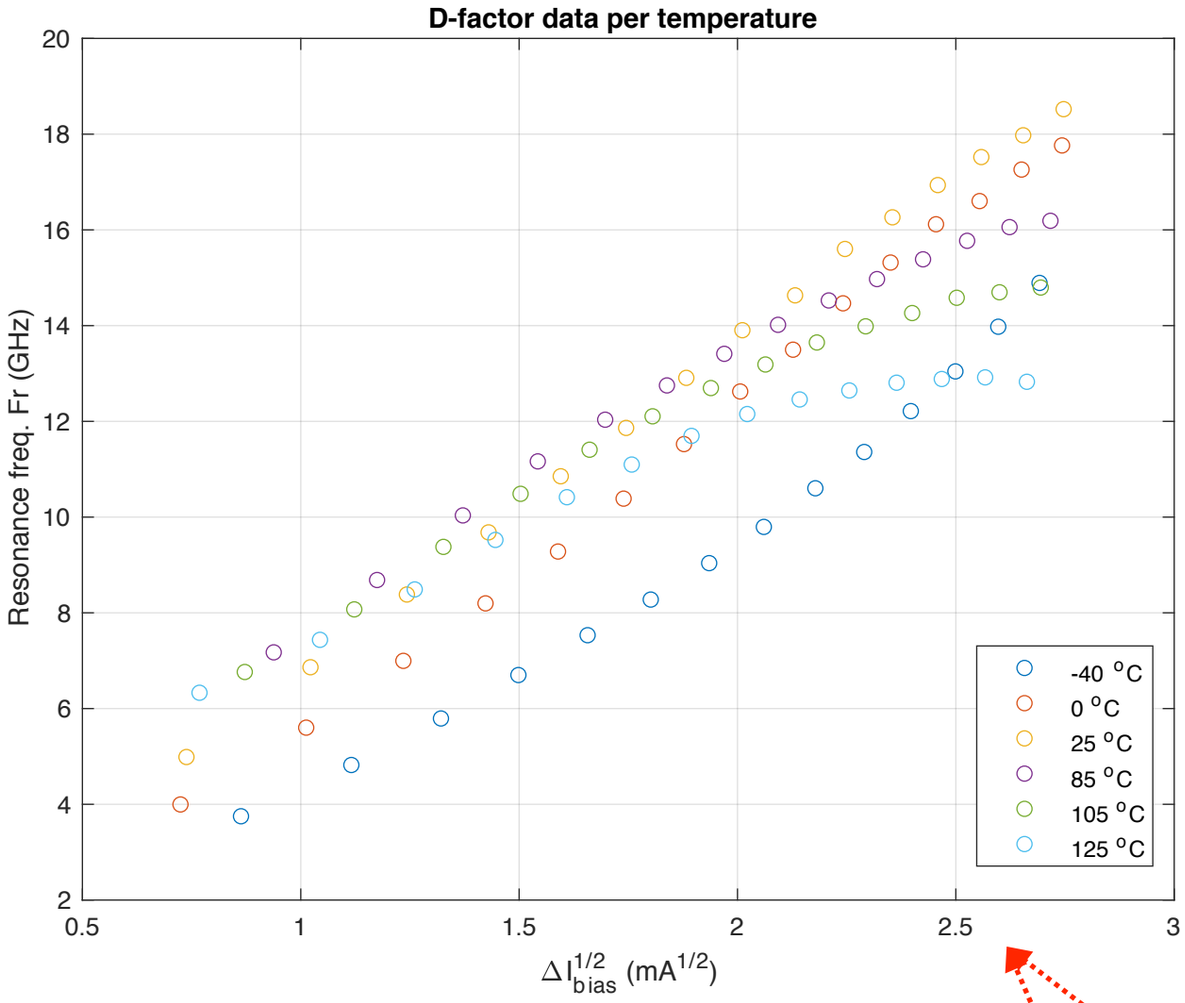


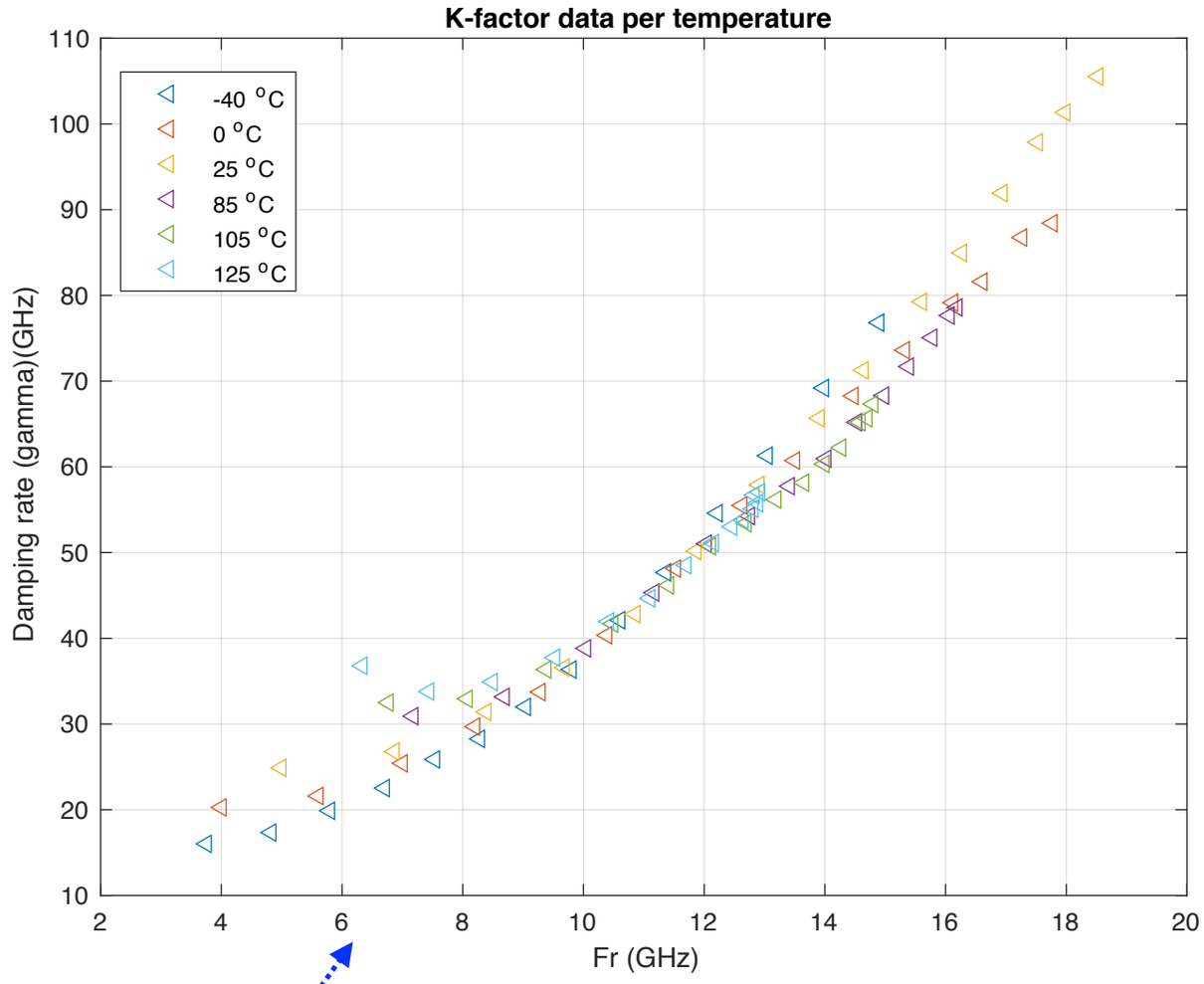
Small signal frequency response



$$H(f) = C \cdot \frac{f_r^2}{f_r^2 - f^2 + j\frac{f}{2\pi}\gamma} \cdot \frac{1}{1 + j\frac{f}{f_p}}. \quad \text{(see [1])}$$

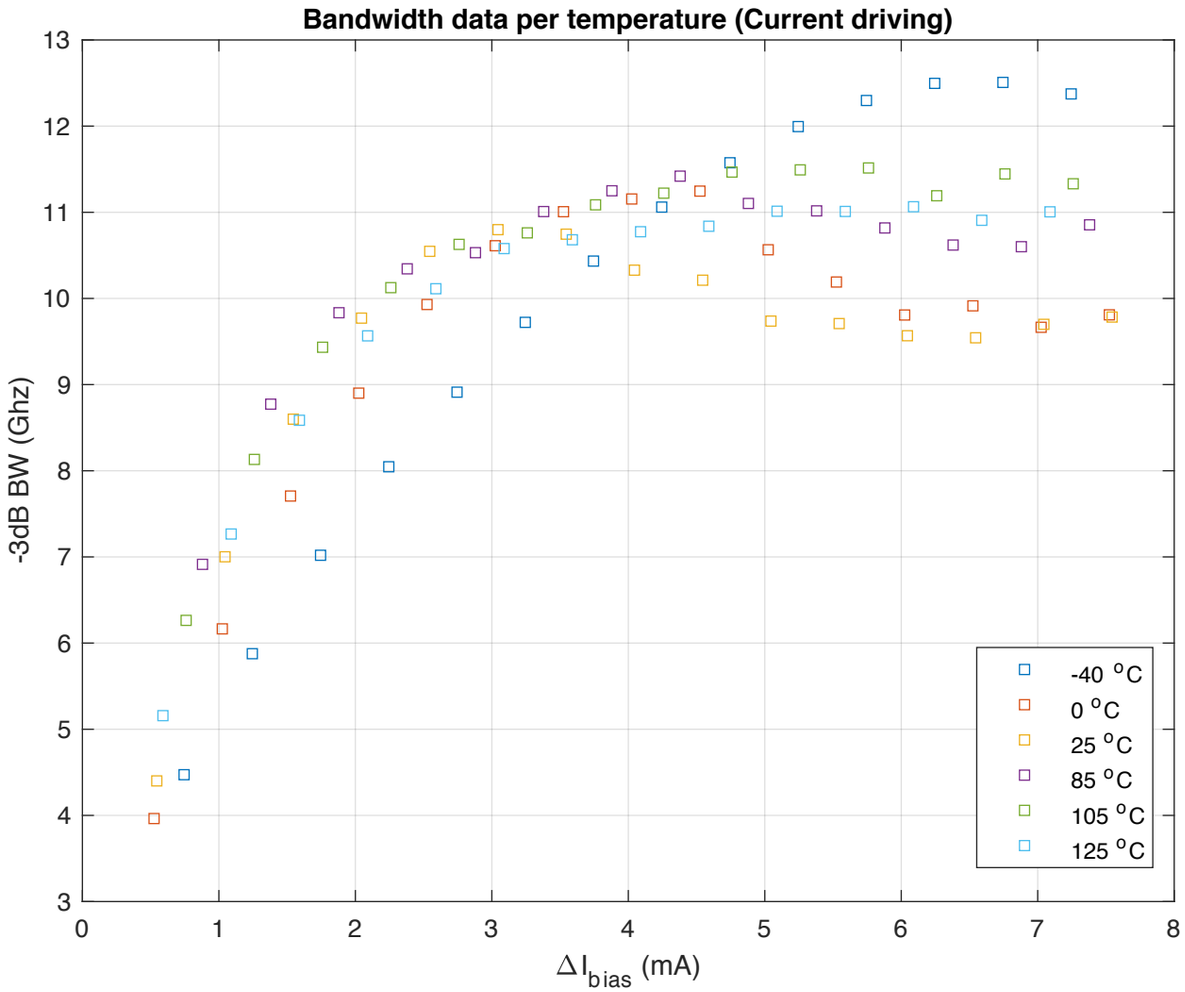
Small signal frequency response

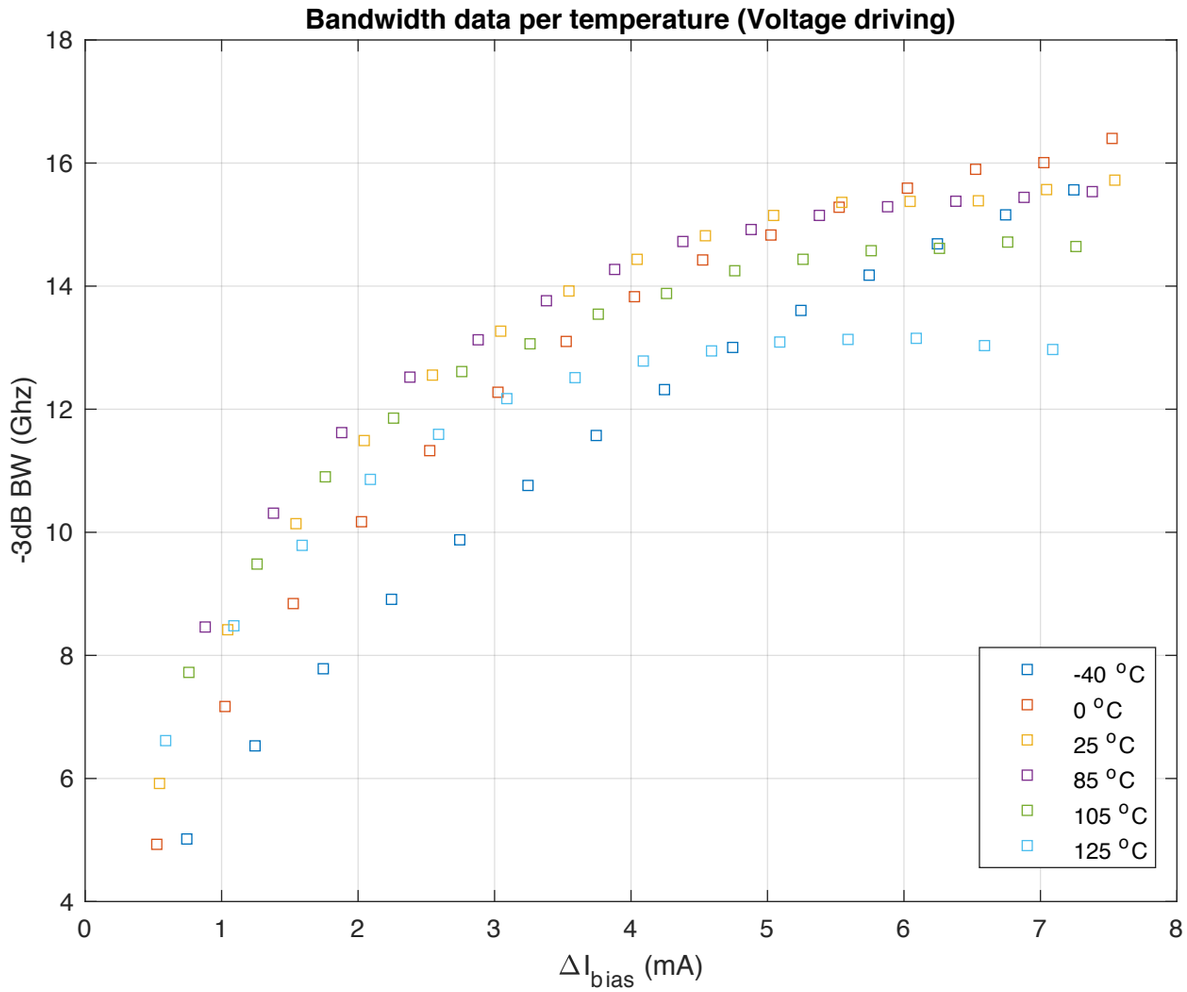




$$H(f) = C \cdot \frac{f_r^2}{f_r^2 - f^2 + j\frac{f}{2\pi}\gamma} \cdot \frac{1}{1 + j\frac{f}{f_p}}.$$ (see [1])

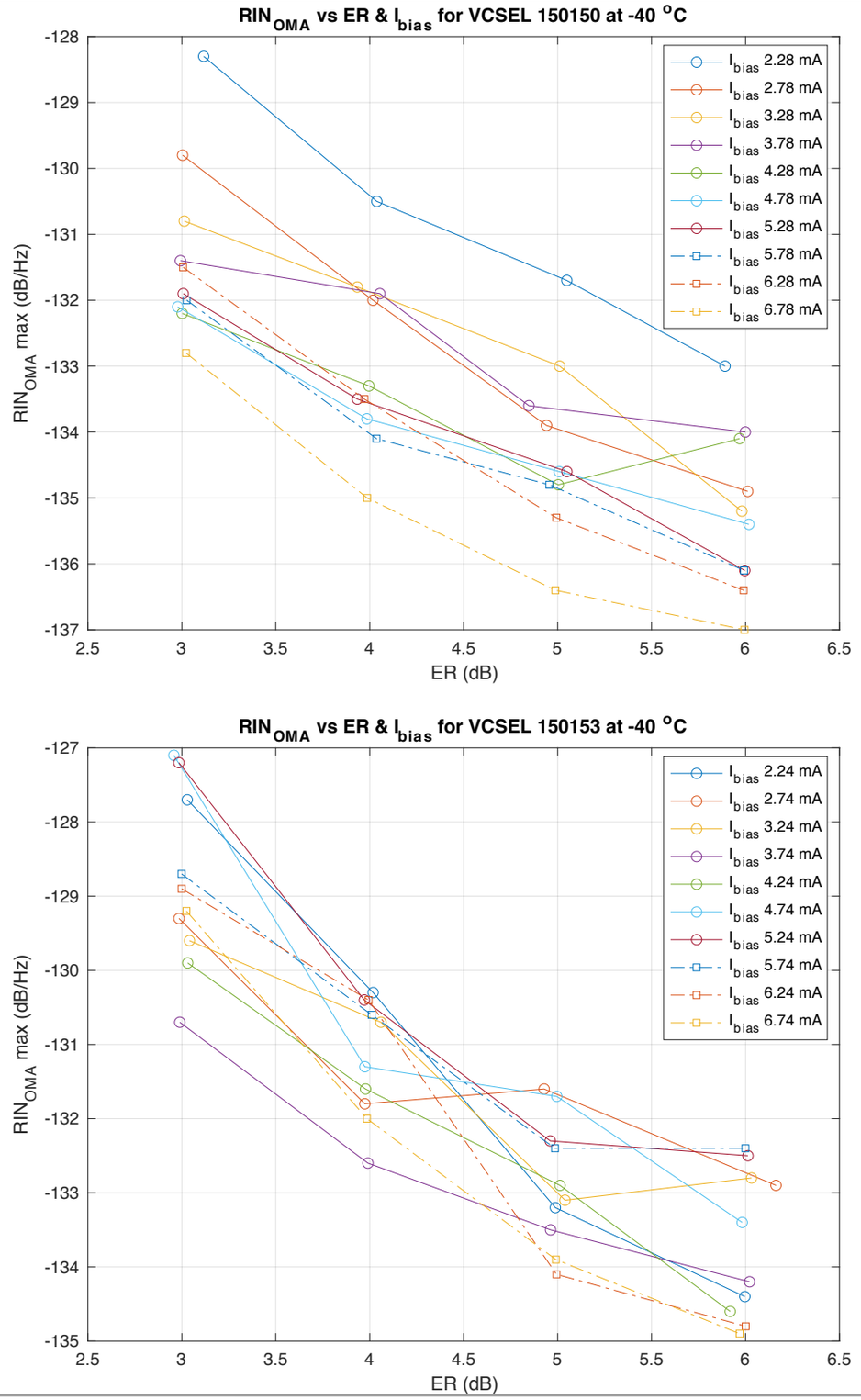
Small signal frequency response

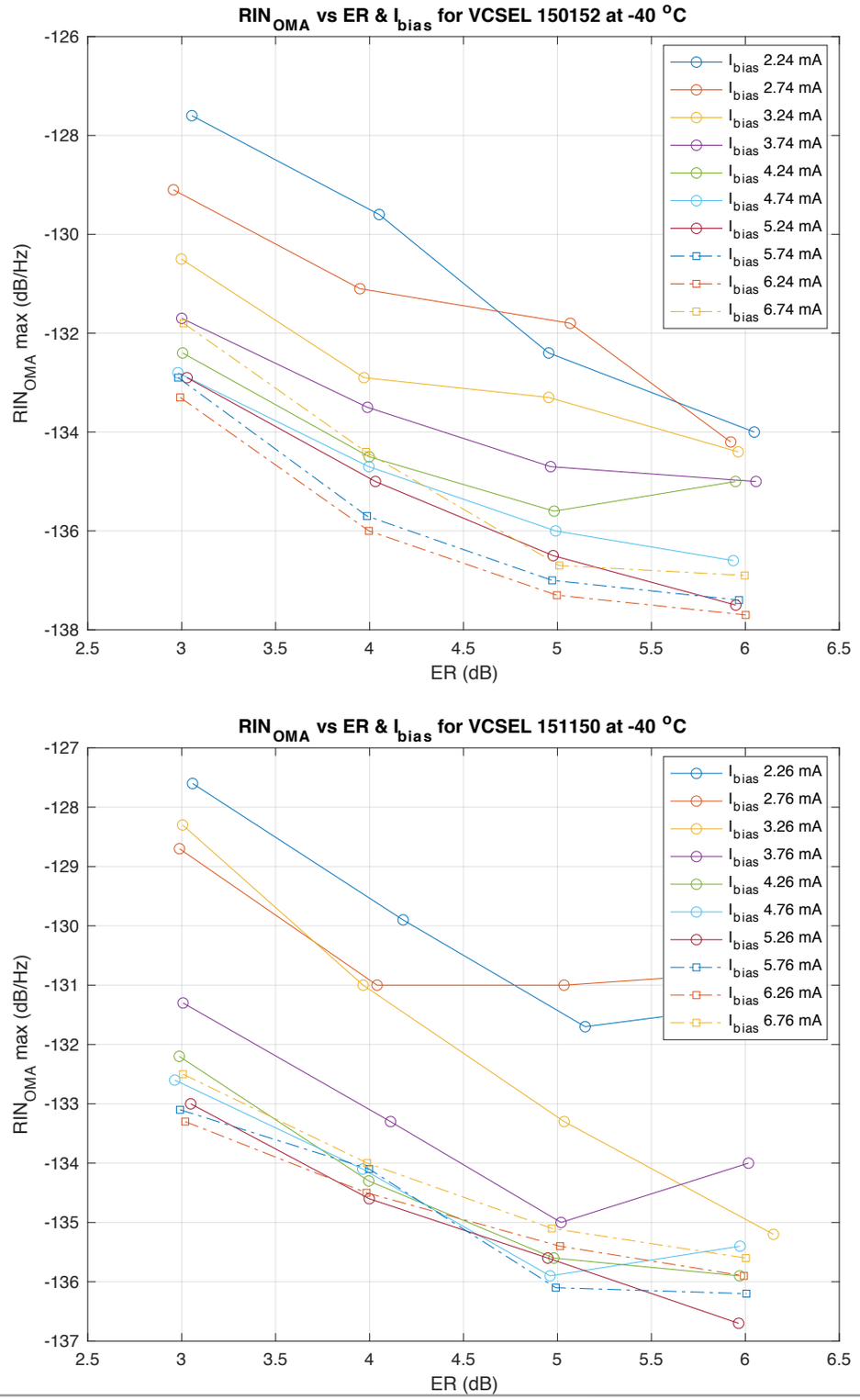




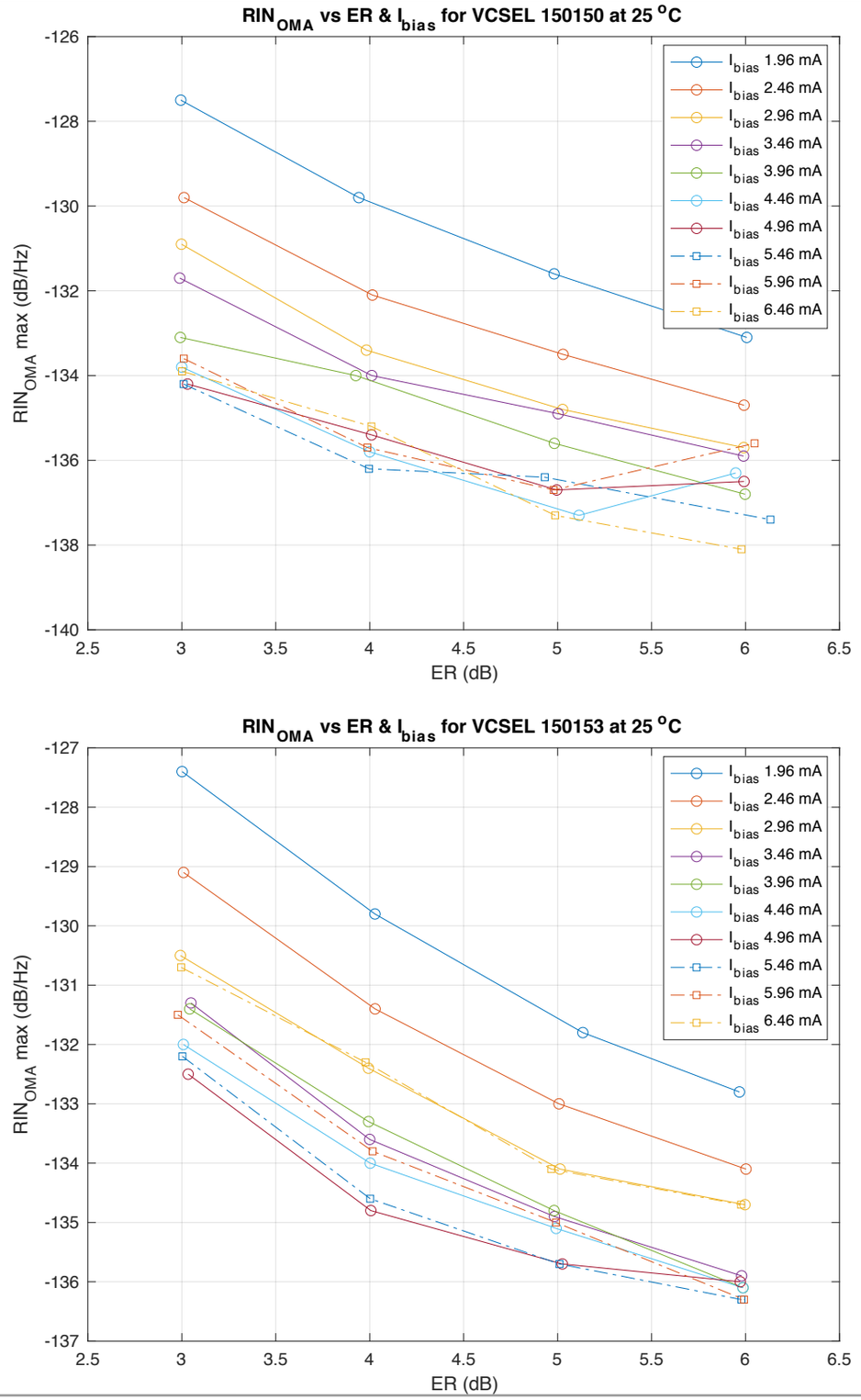
Considered source impedance 100 Ω

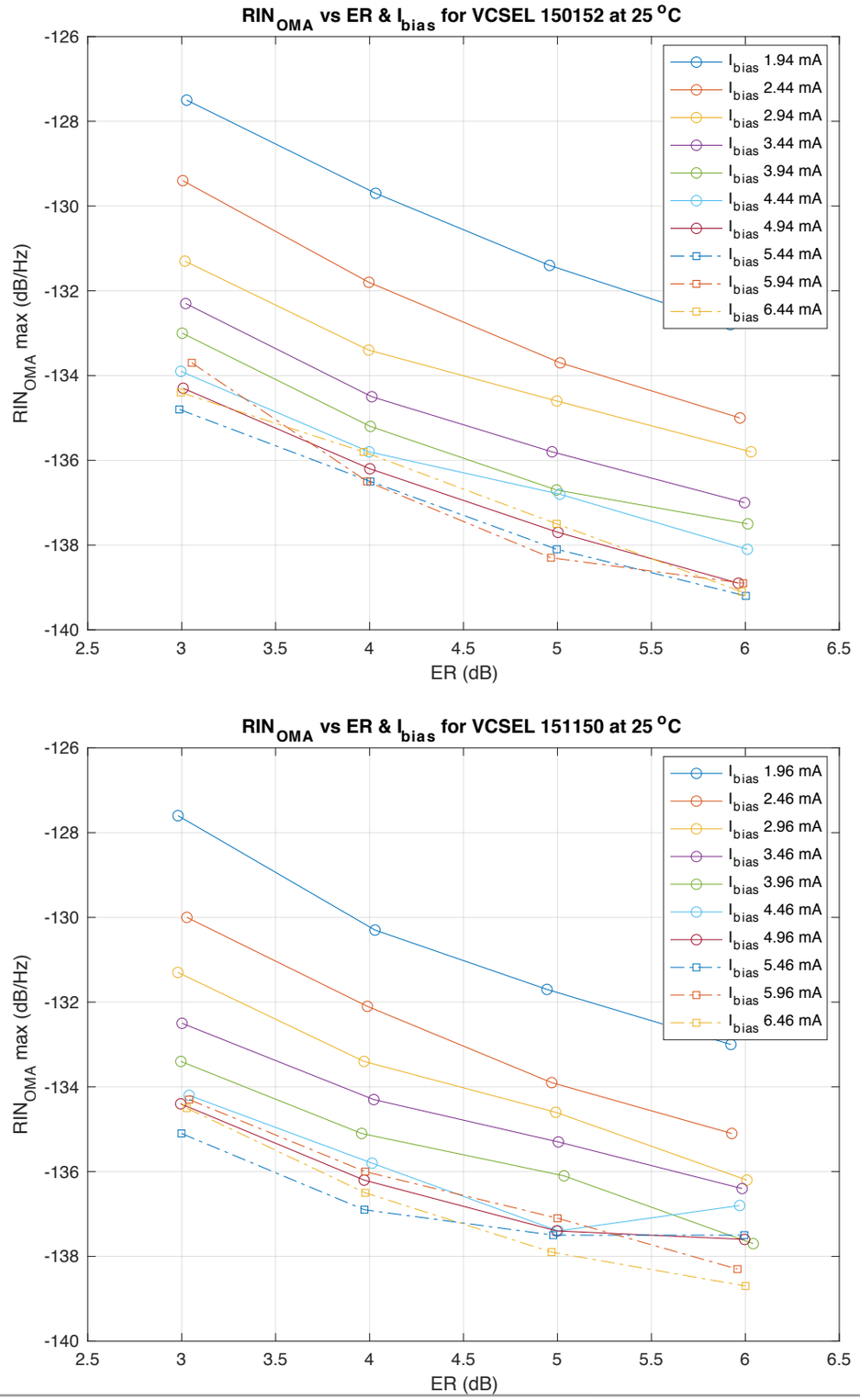
Relative intensity noise (RIN_{OMA}) at -40ºC



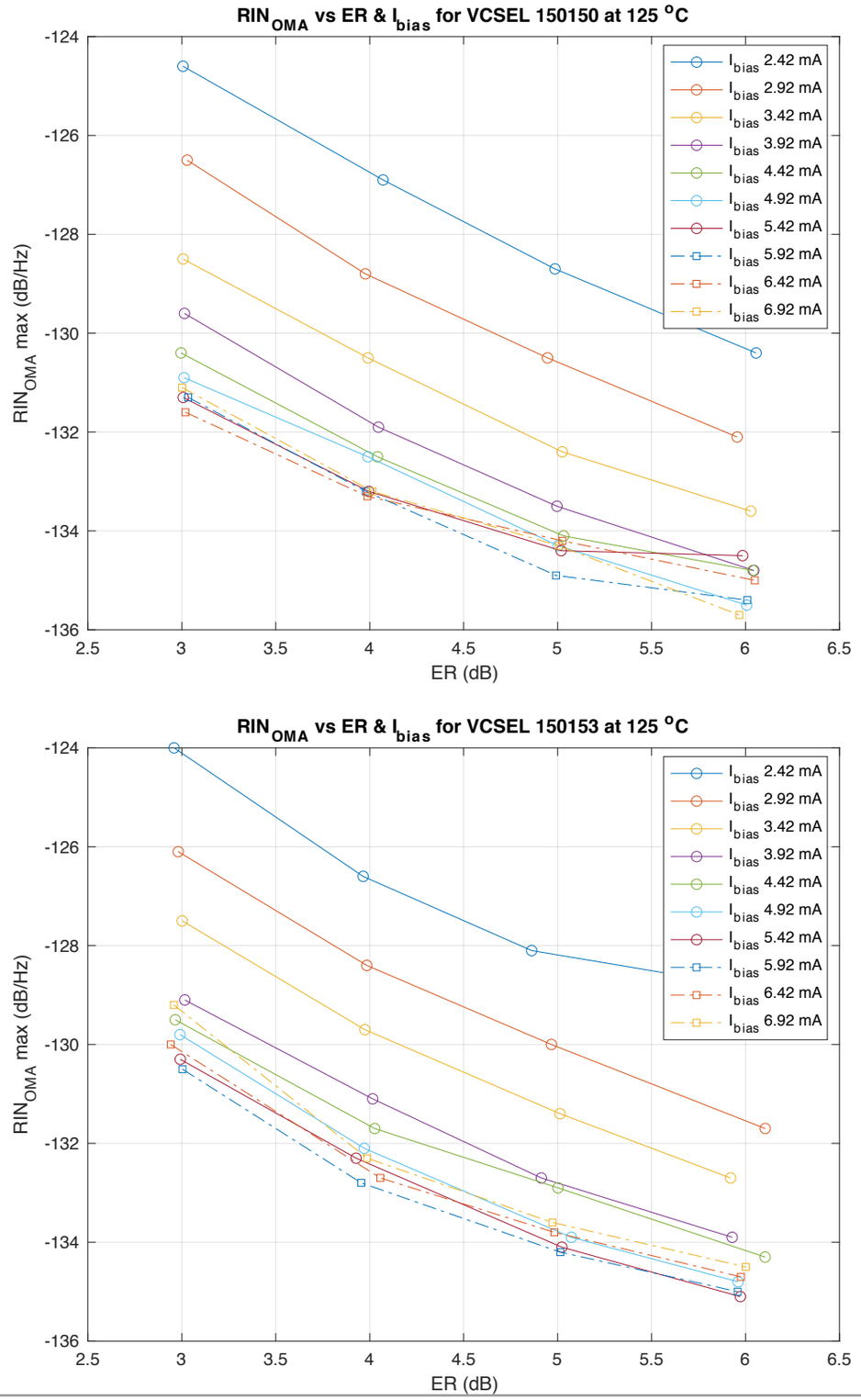


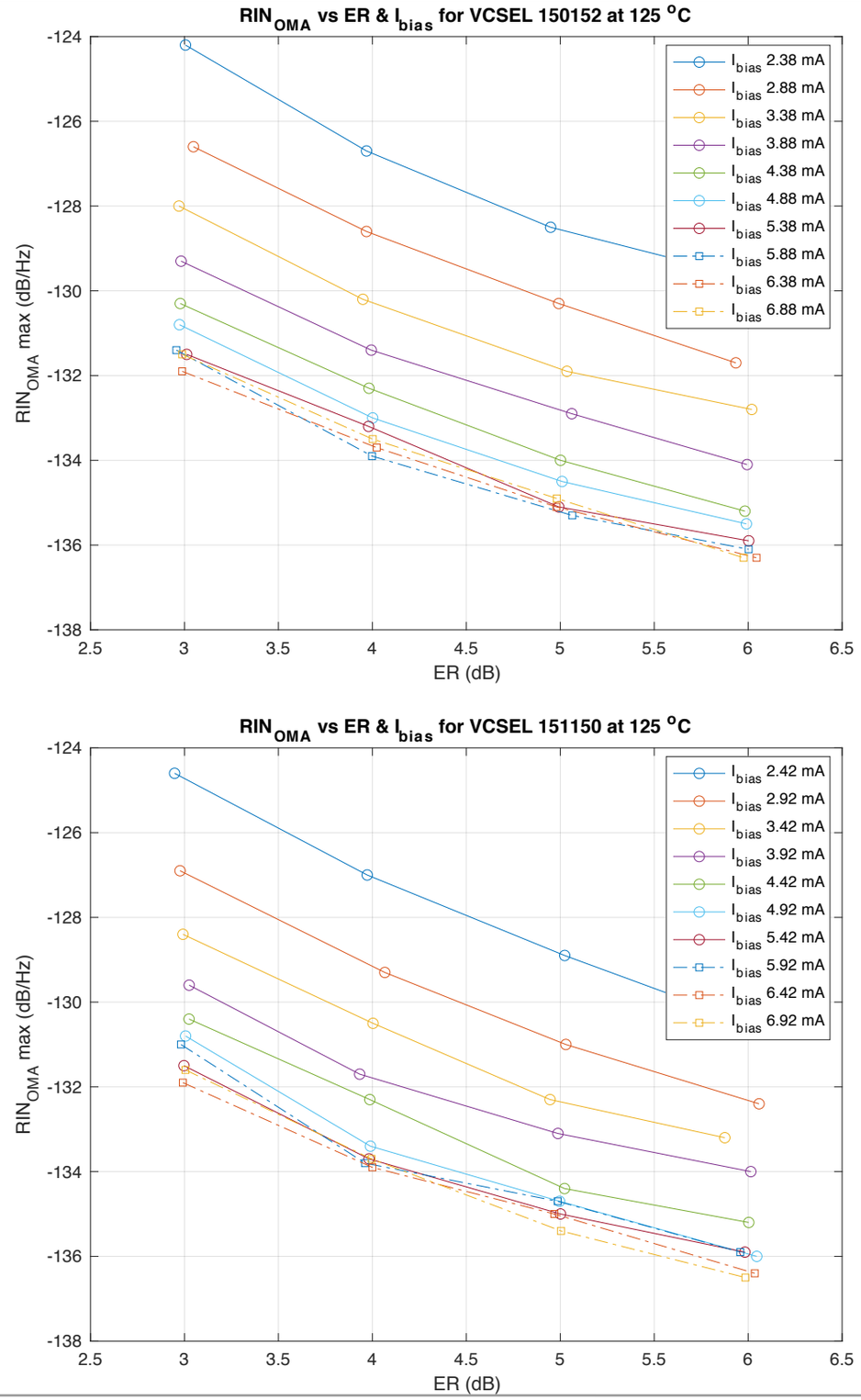
Relative intensity noise (RIN_{OMA}) at 25ºC



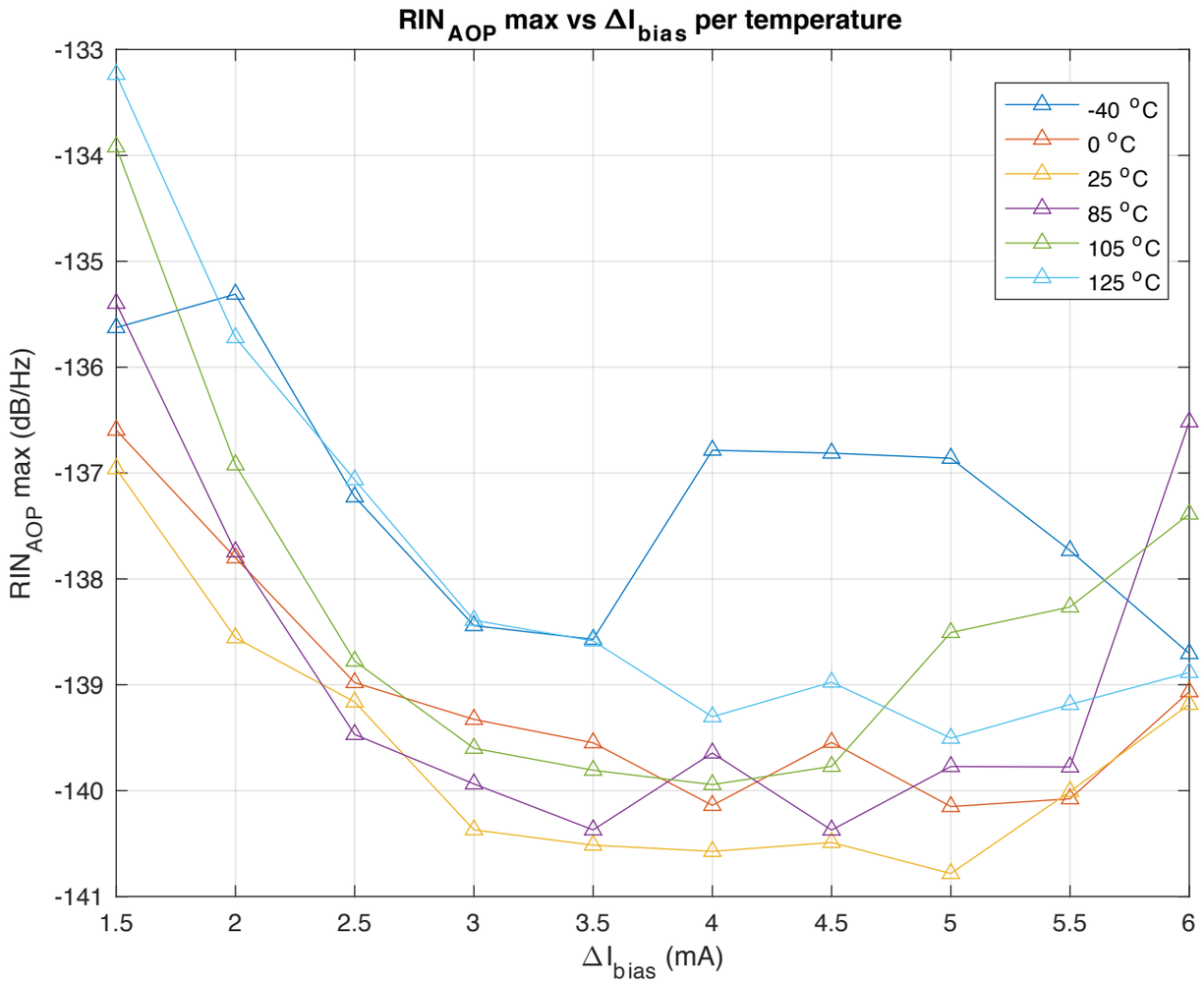


Relative intensity noise (RIN_{OMA}) at 125ºC





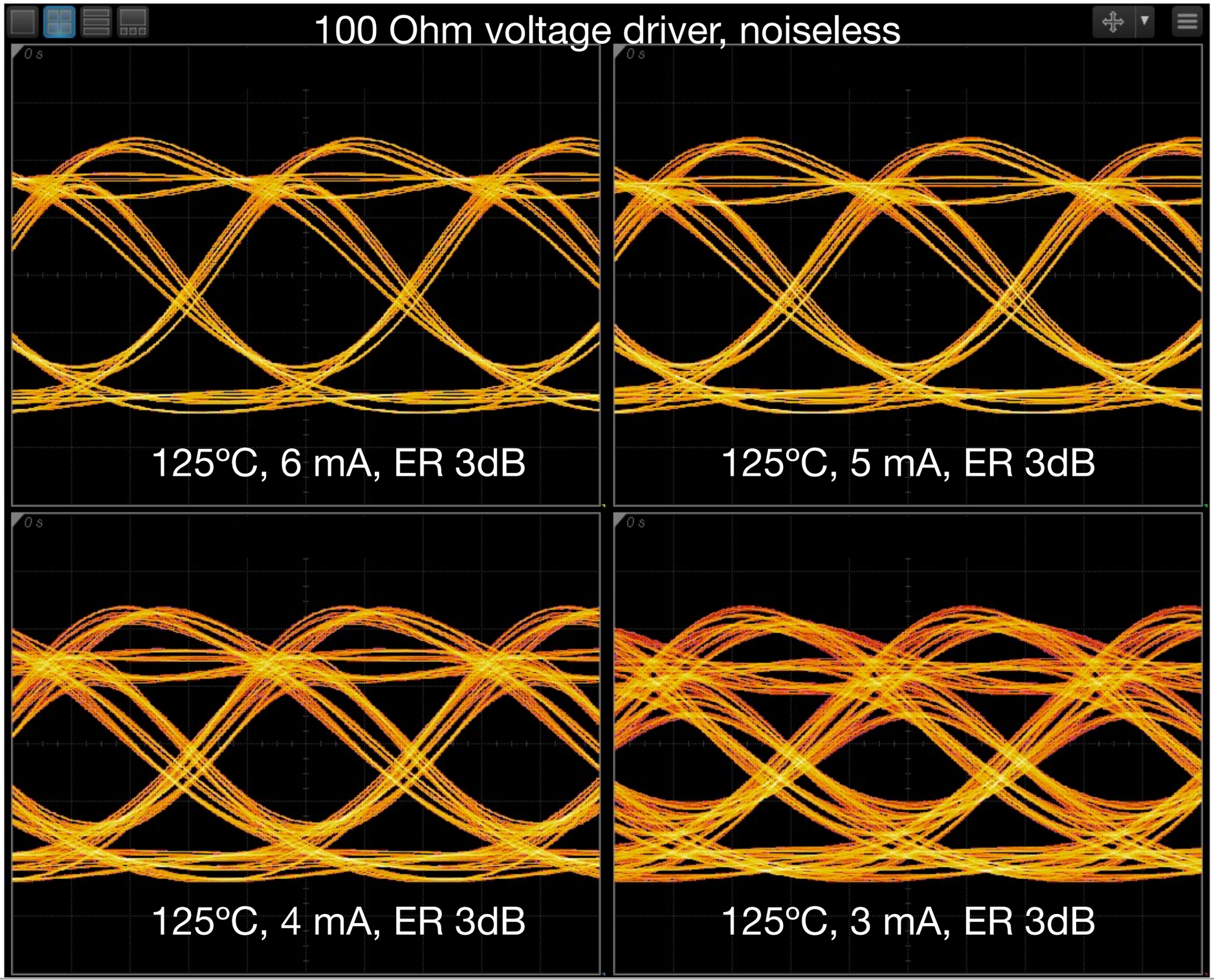
Normalized max RIN (RIN_{AOP})



$$RIN_{AOP}\left(dB/Hz\right) = RIN_{OMA}\left(dB/Hz\right) - 20\cdot\log_{10}\left(\frac{ER_L+1}{ER_L-1}\right)$$

$$ER_L = 10^{ER(dB)/10}$$

Eye diagram for 26.5625 GBd NRZ



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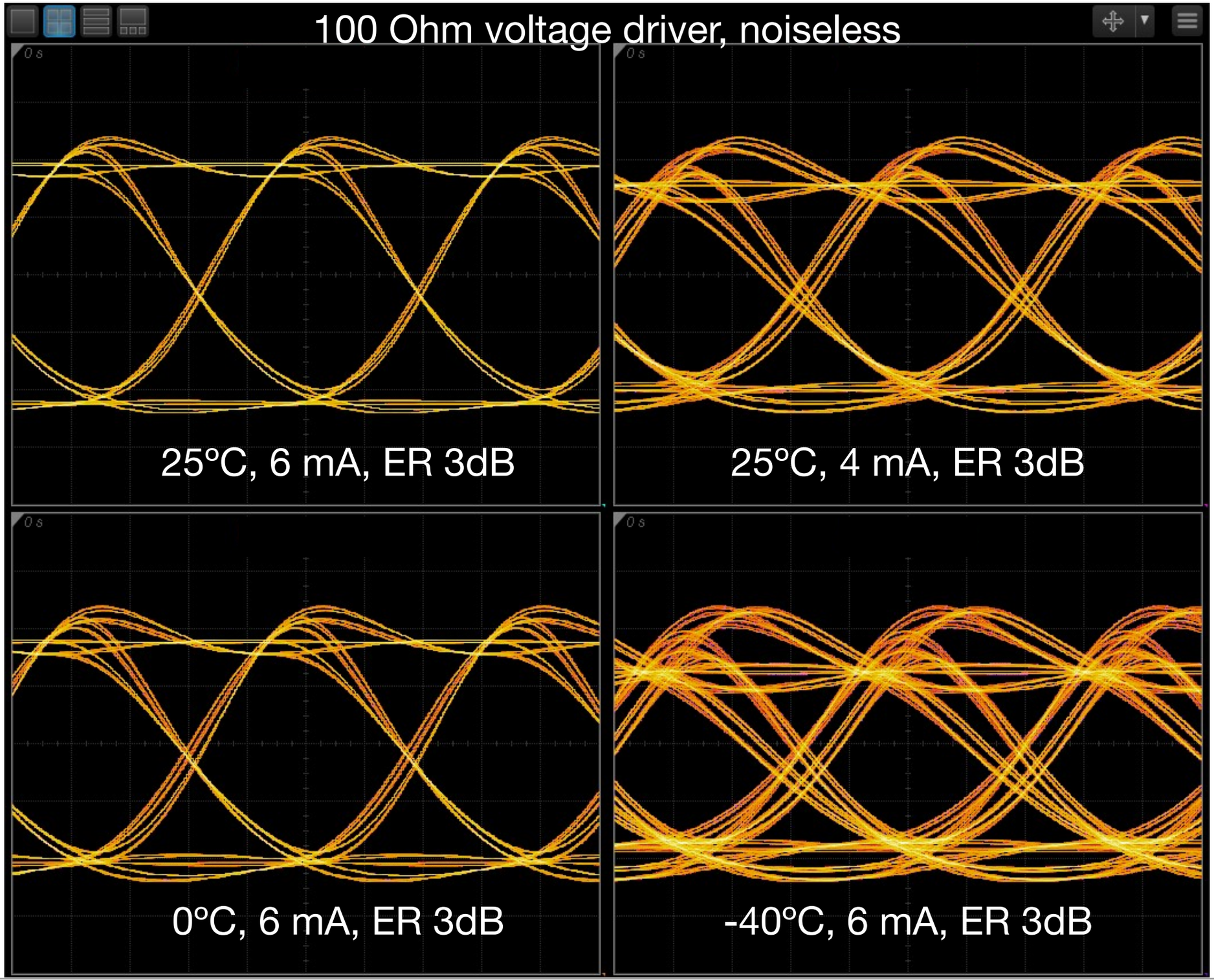

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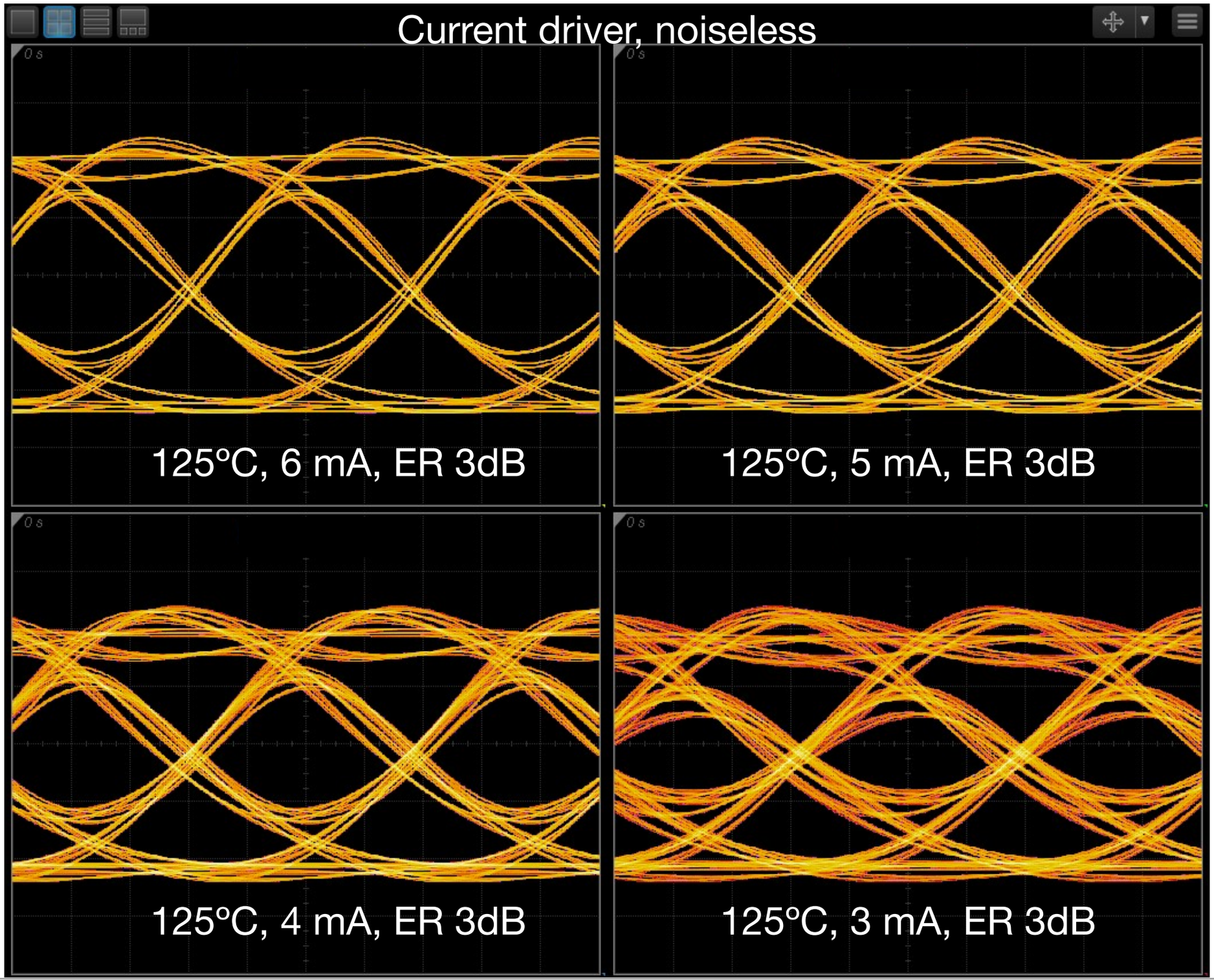

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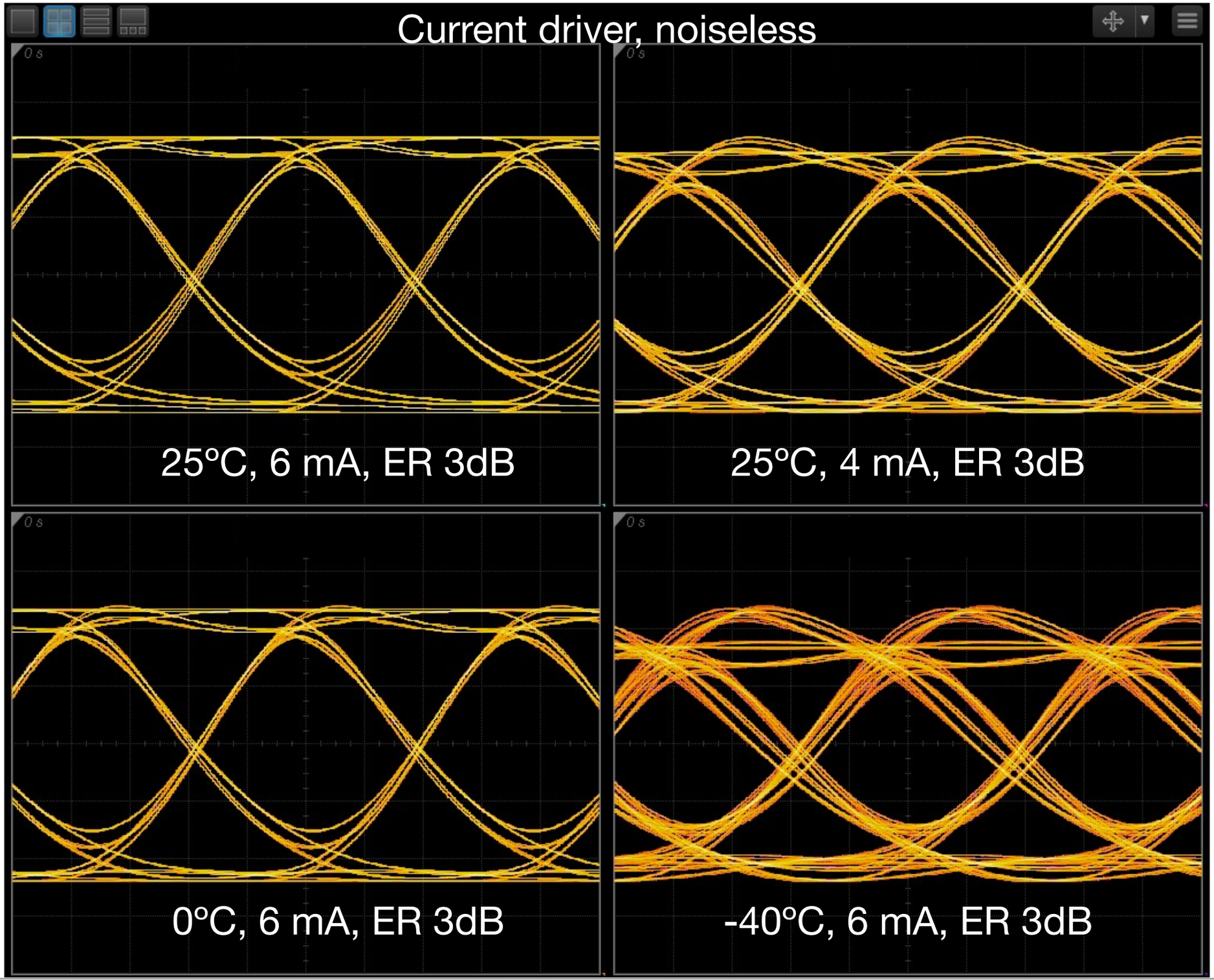

25Gbps multimode VCSEL for 850 nm, high threshold

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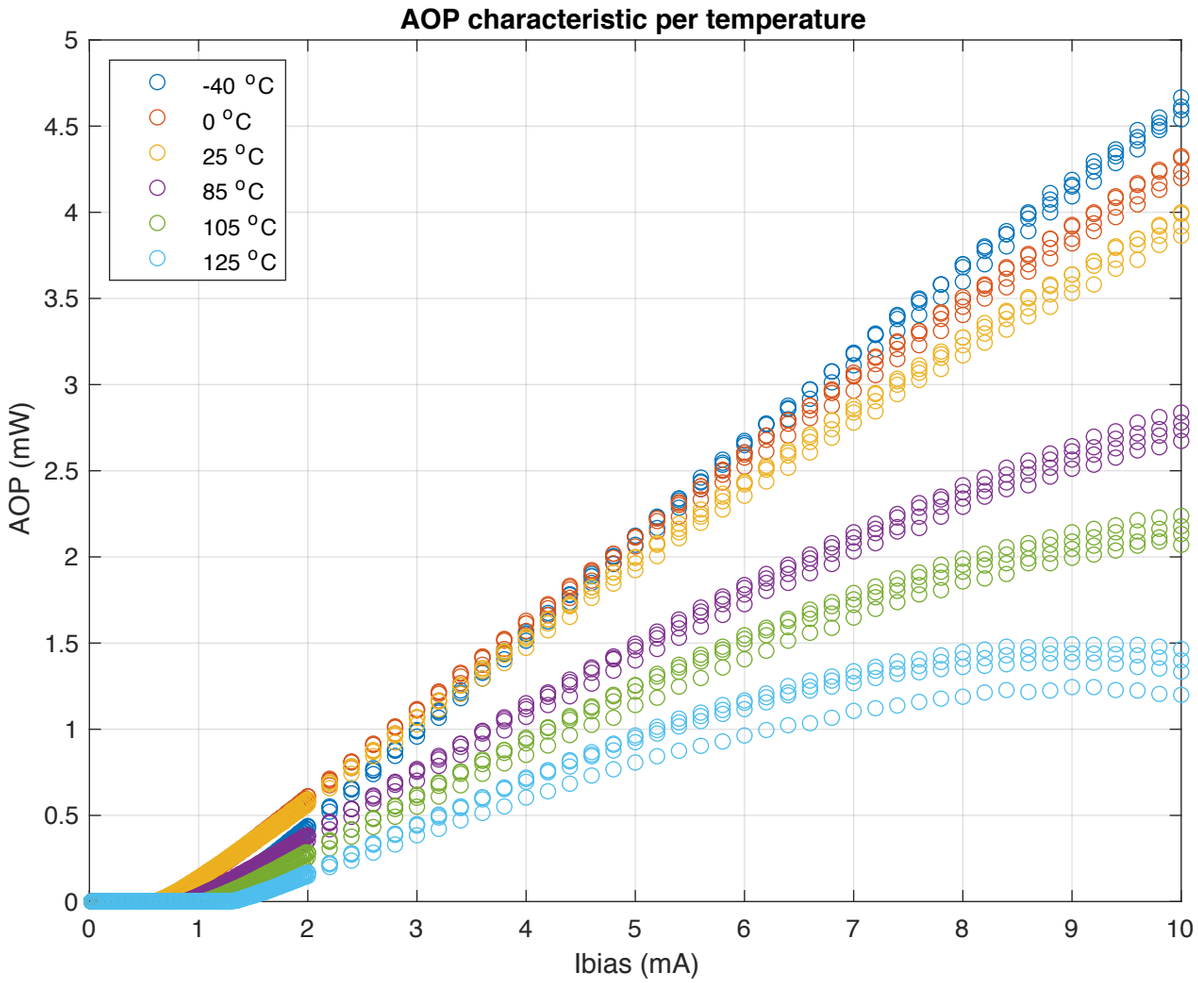
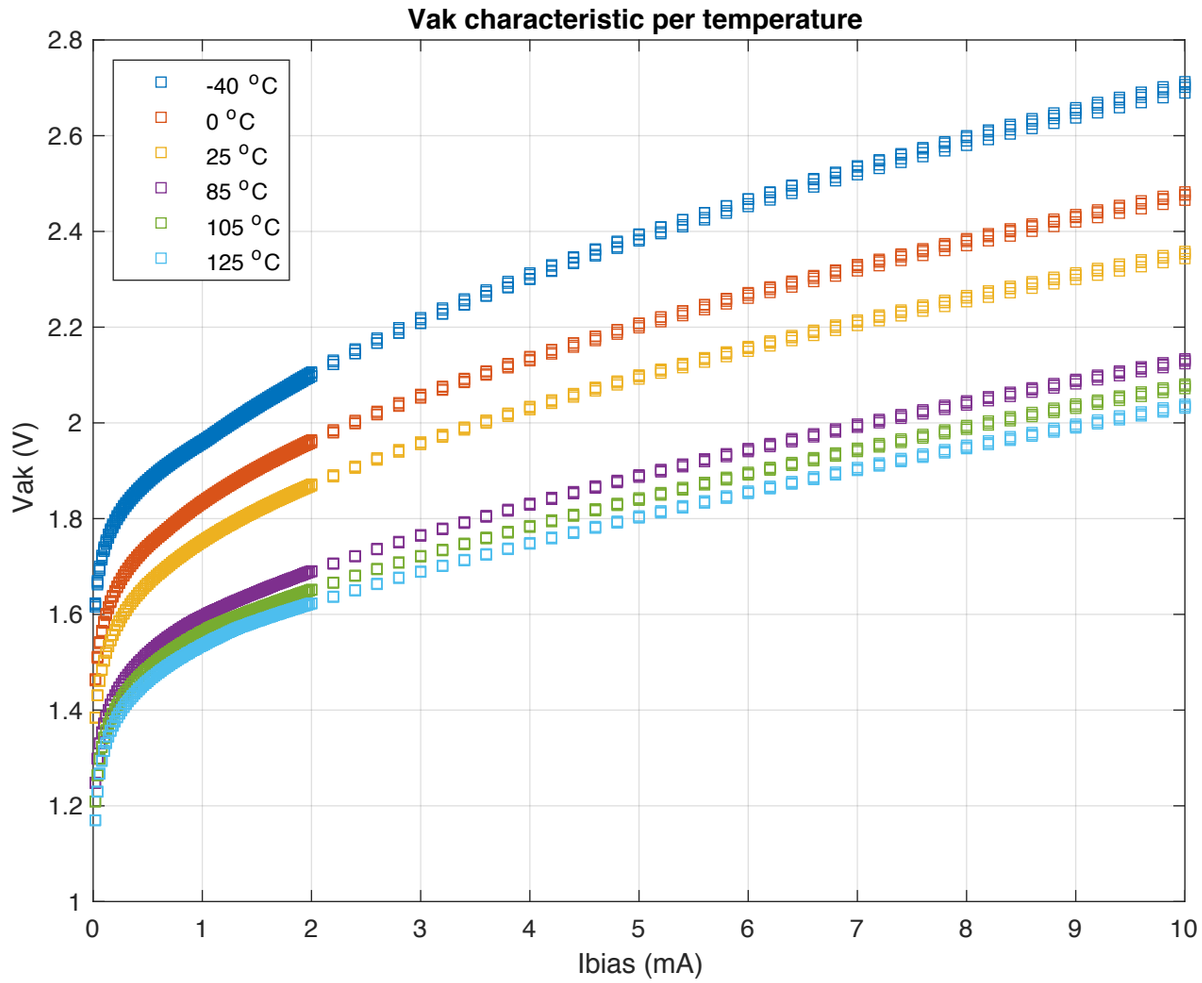
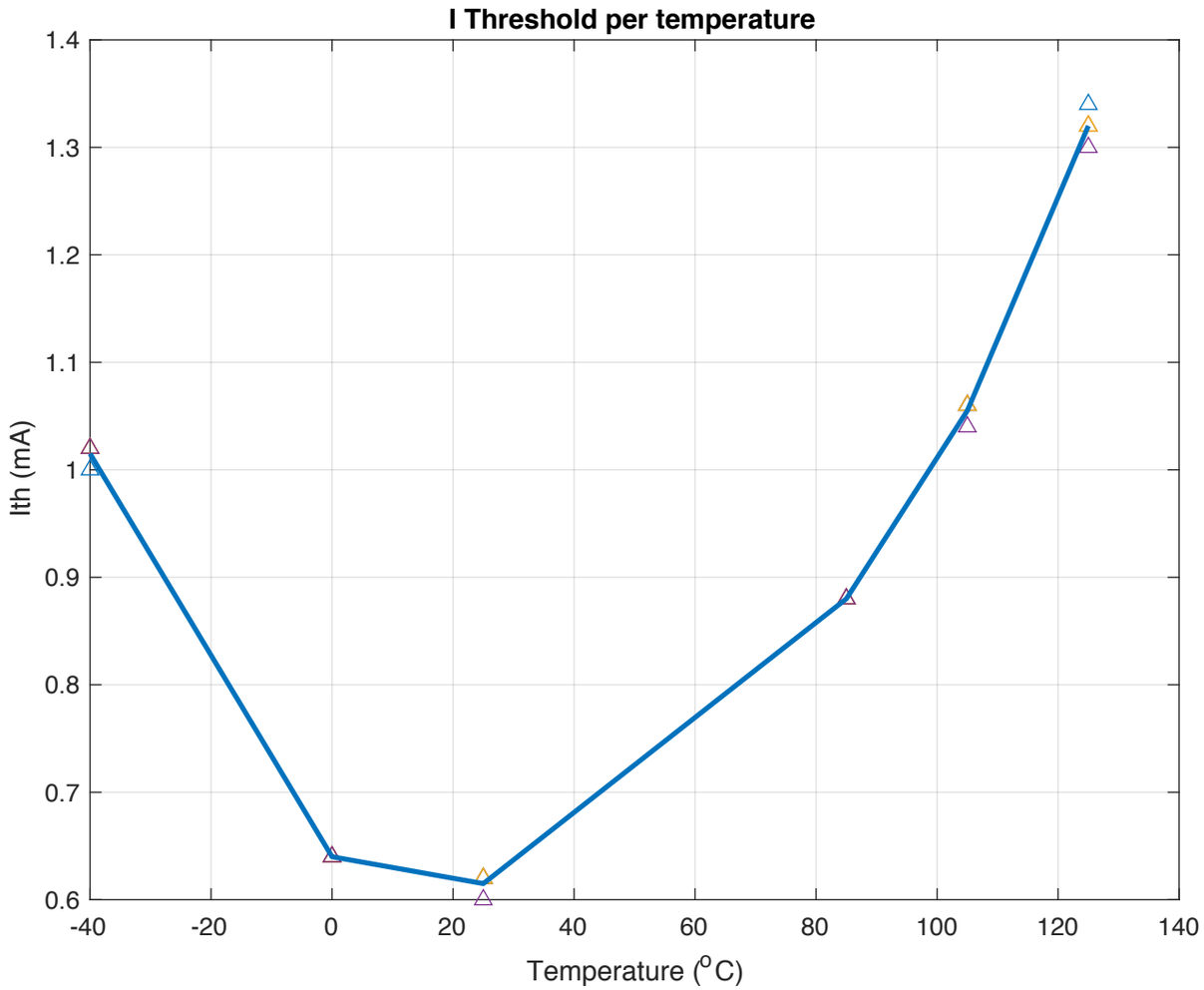
L-I-V characteristic

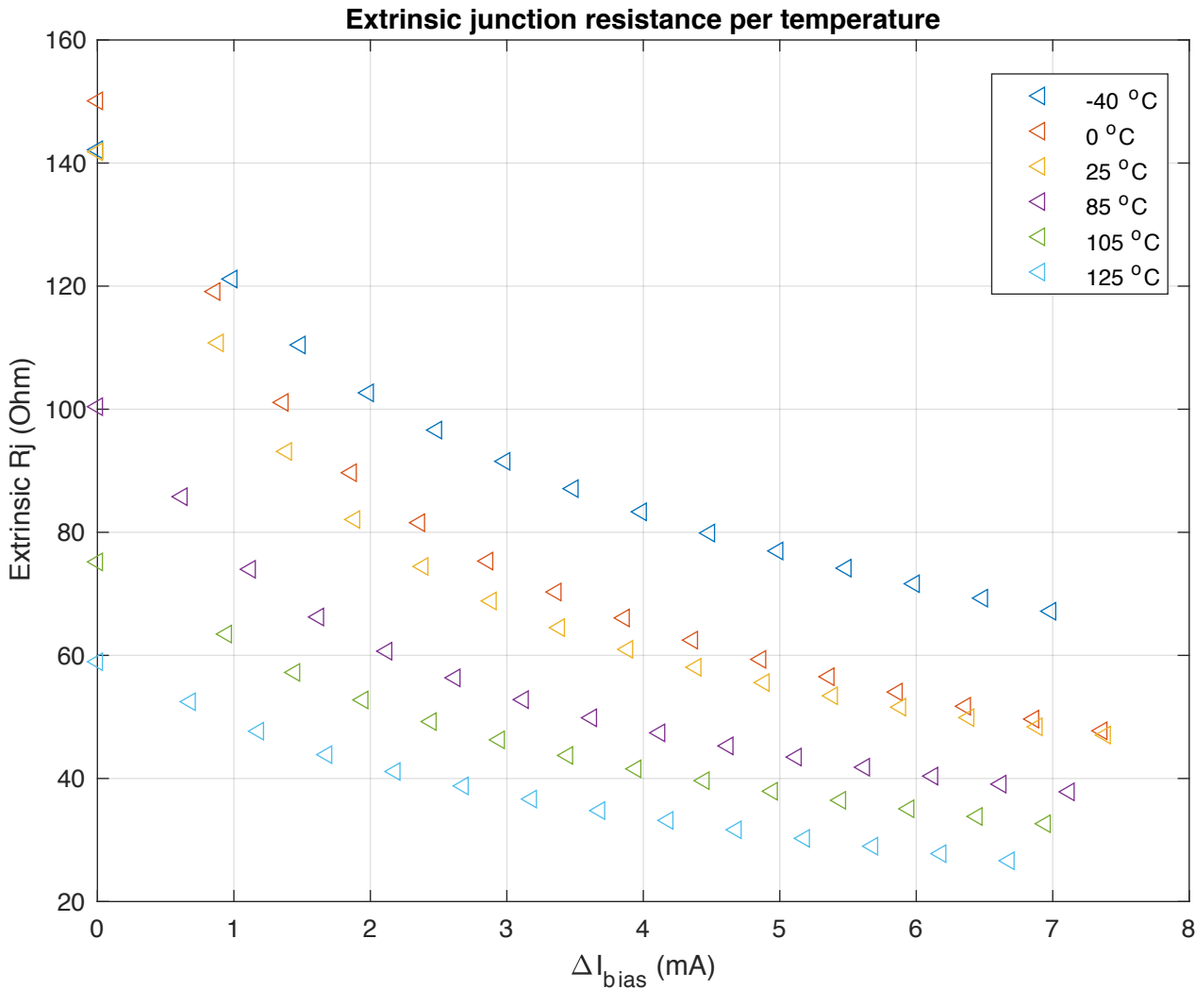


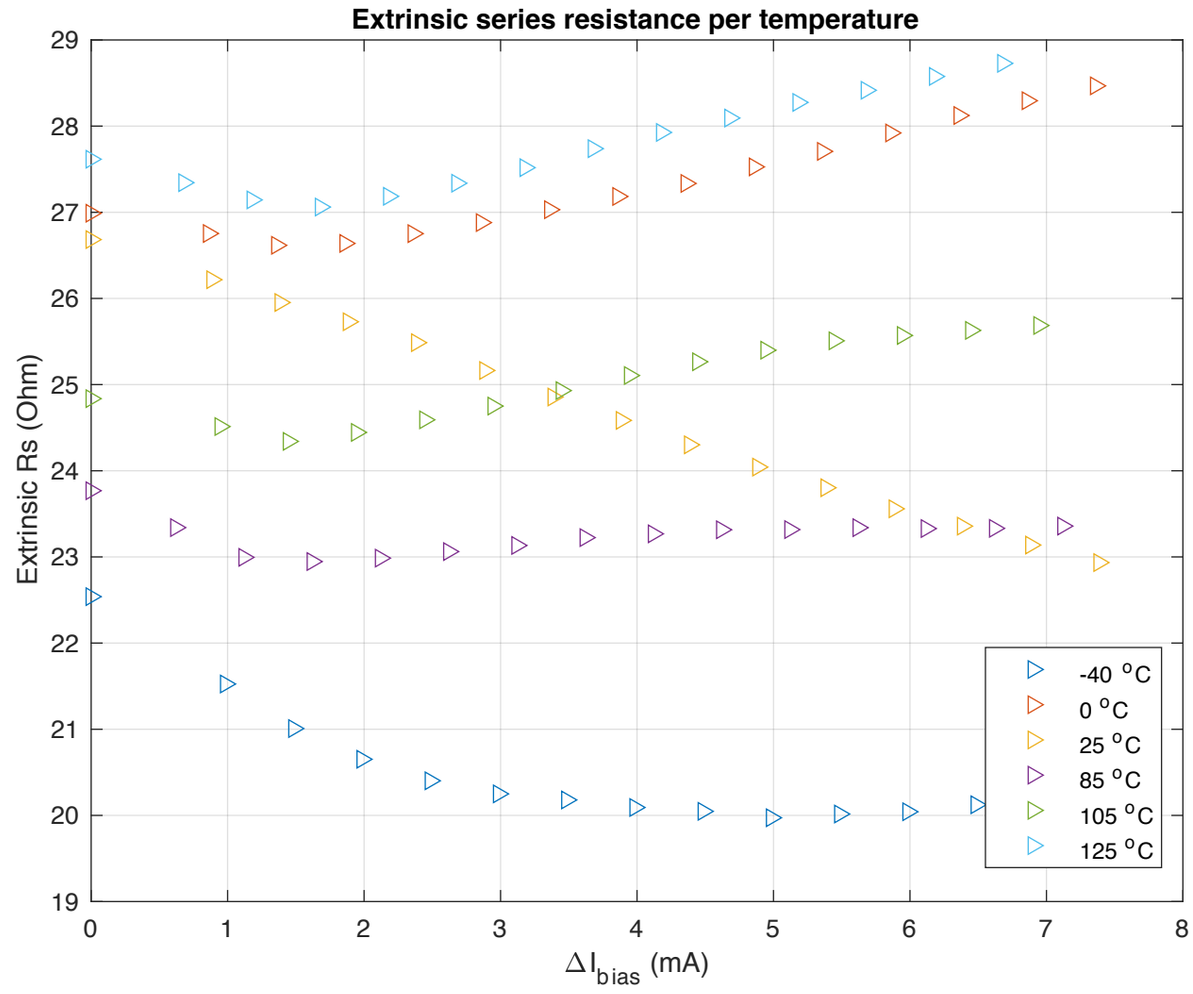


Threshold current characteristic



Small signal frequency response





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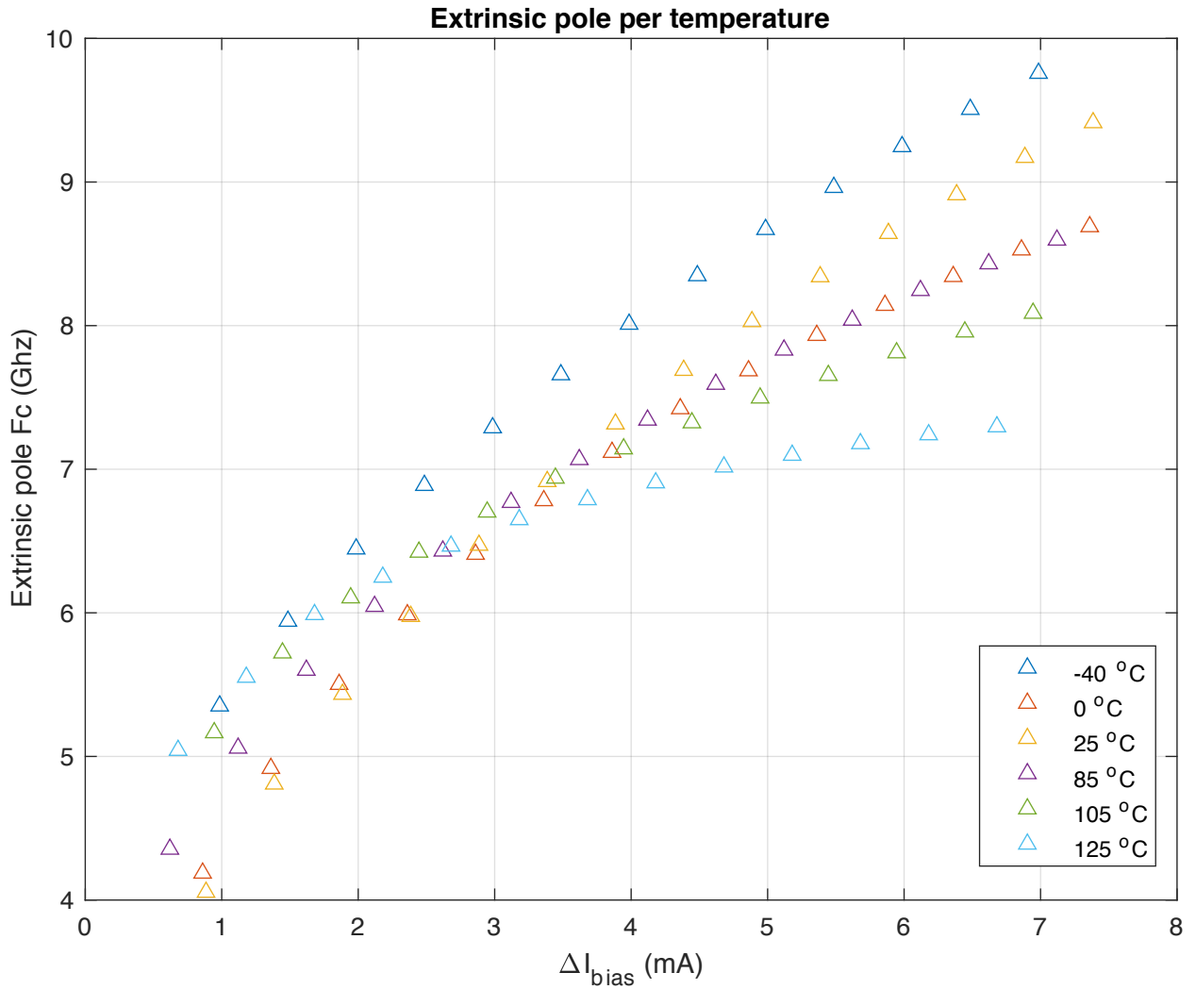

$$H(f) = C \cdot \frac{f_r^2}{f_r^2 - f^2 + j\frac{f}{2\pi}\gamma} \cdot \frac{1}{1 + j\frac{f}{f_p}}. \quad \text{(see [1])}$$

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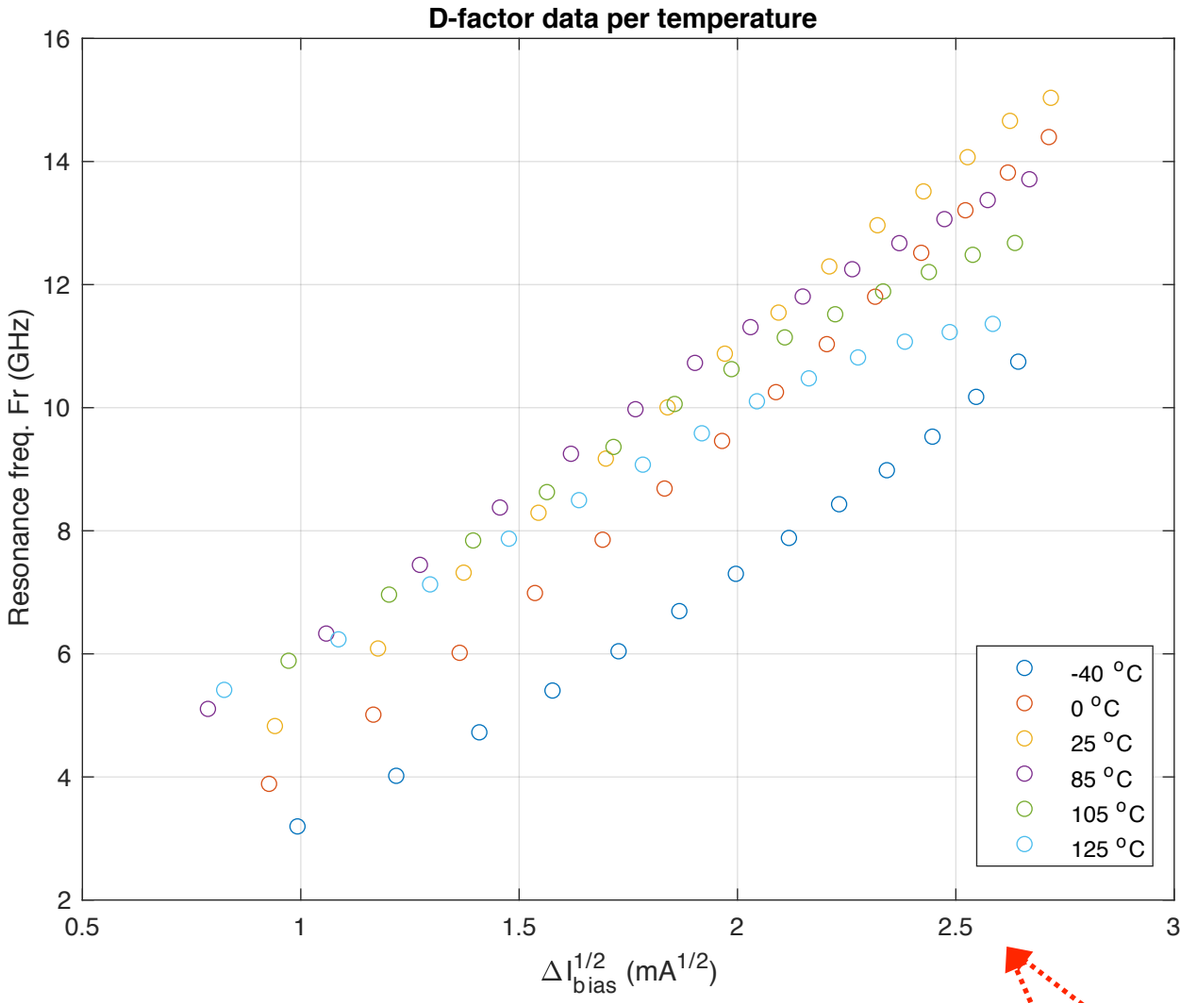

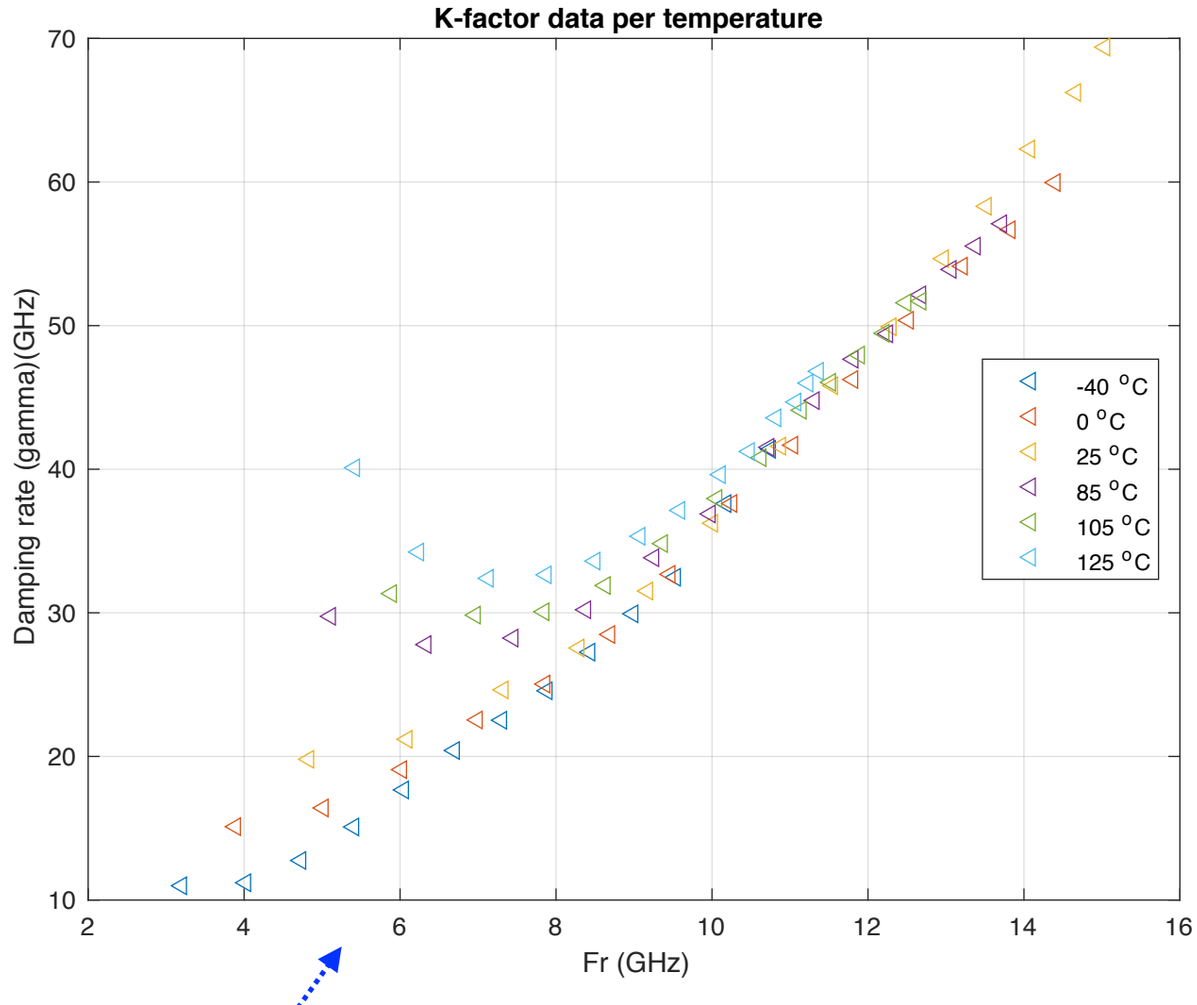

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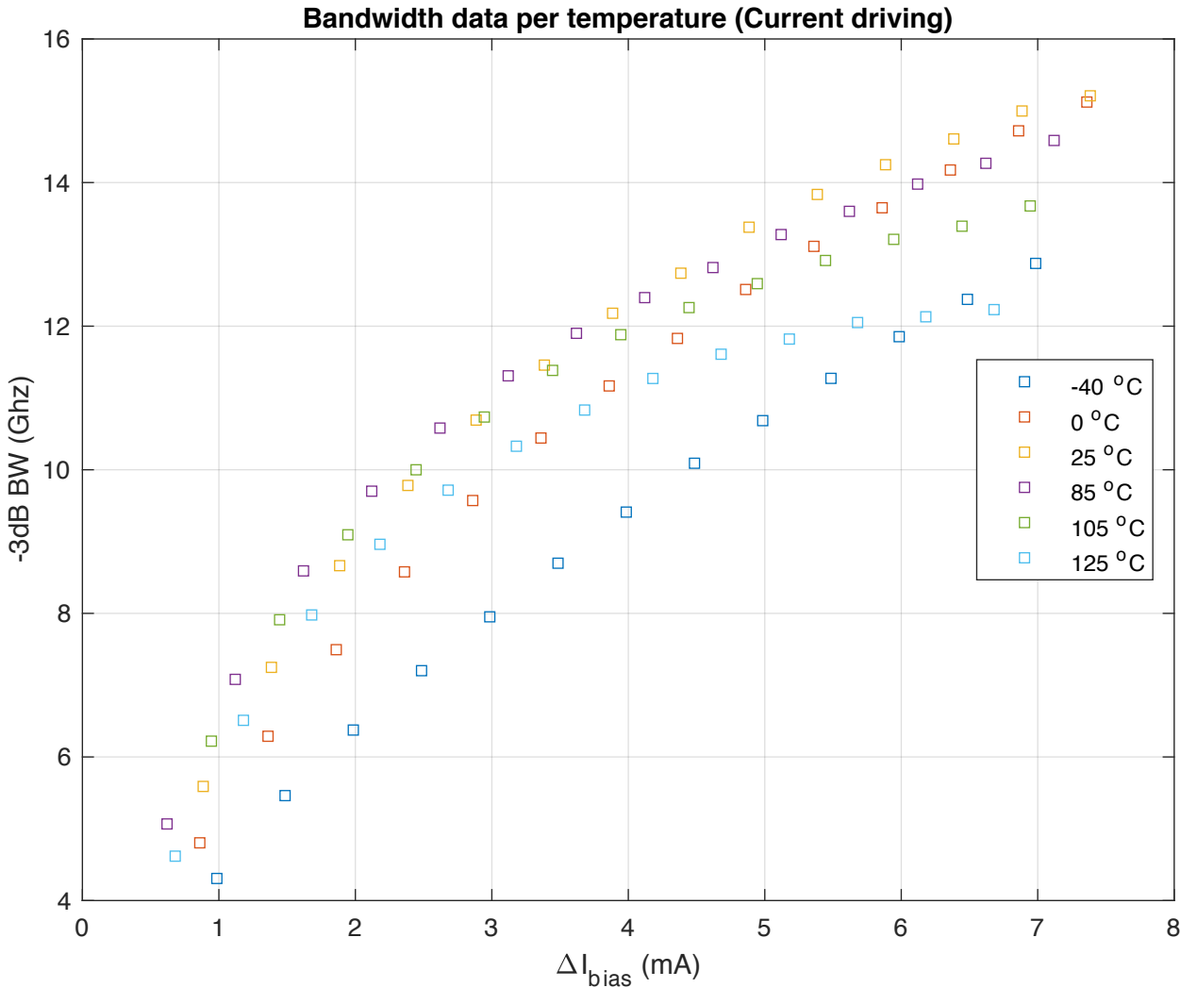

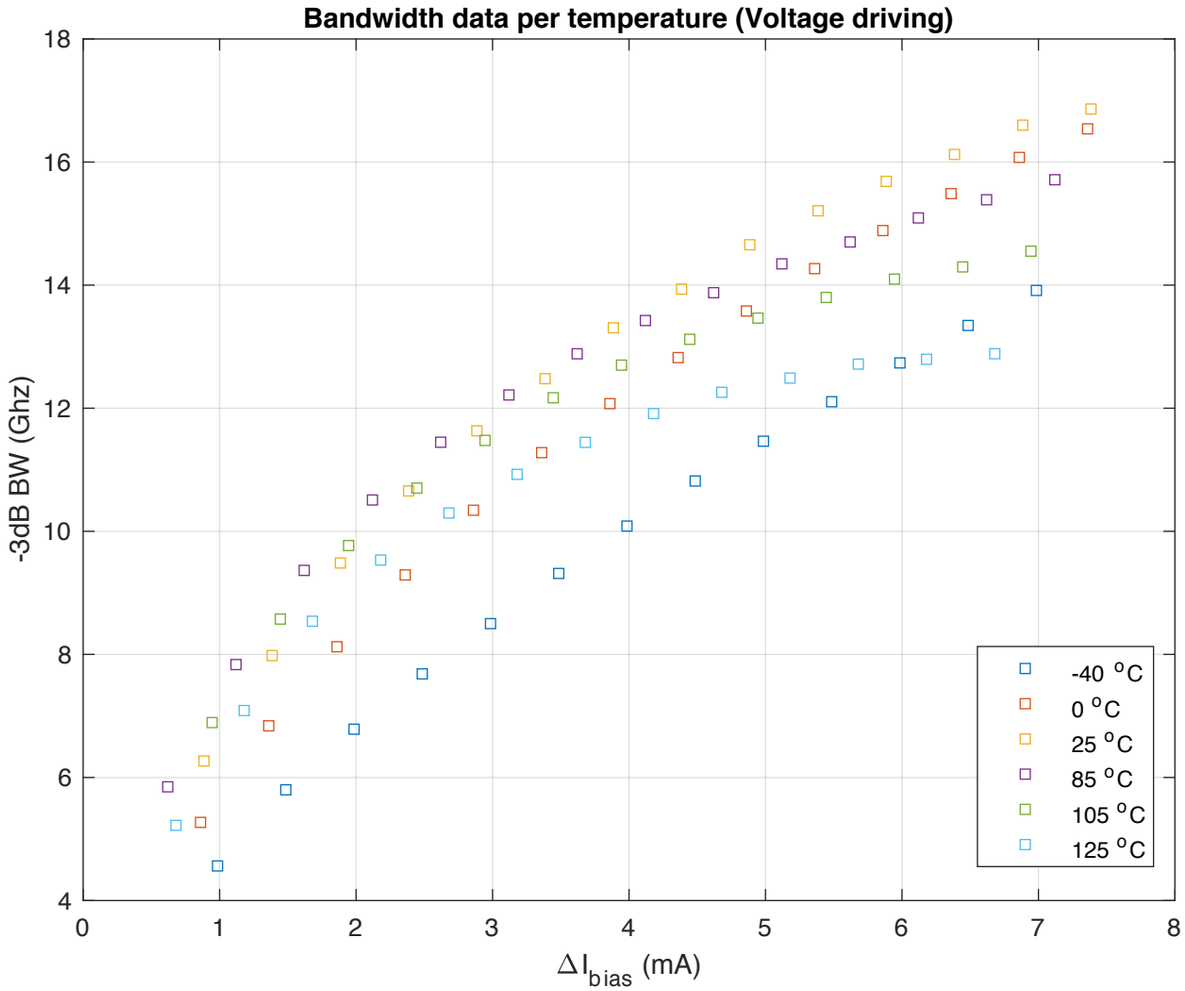

Considered source impedance 100 Ω

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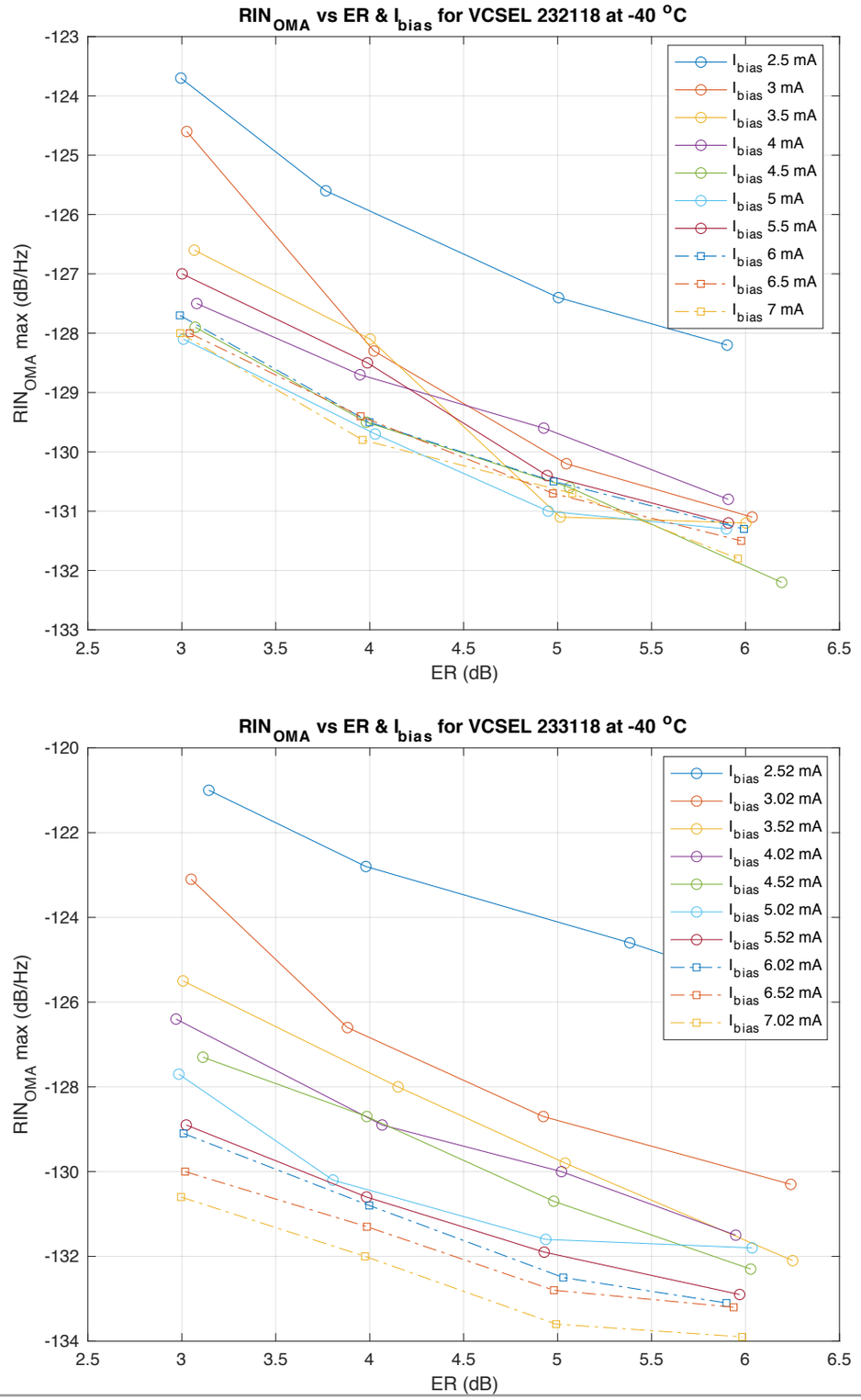
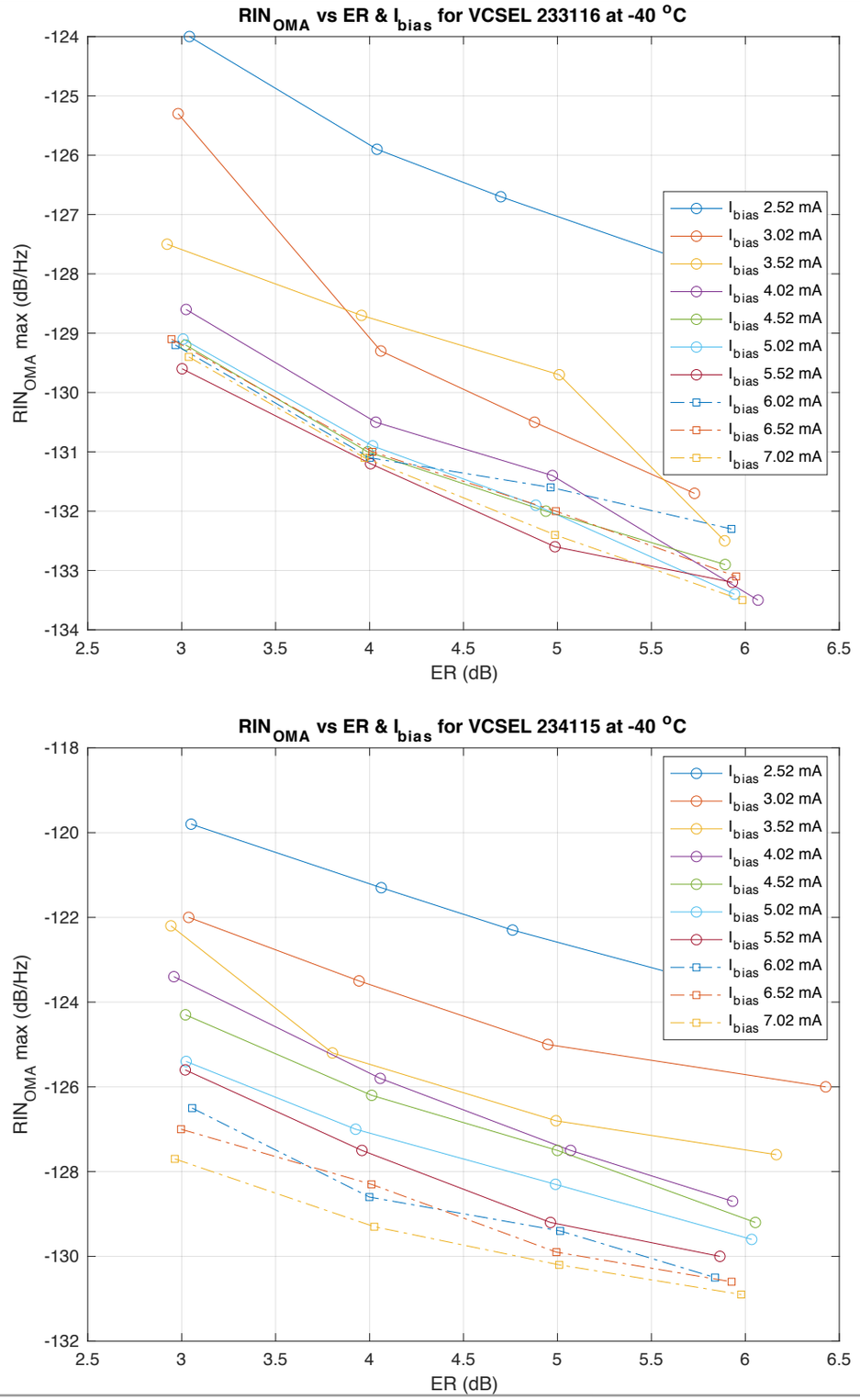
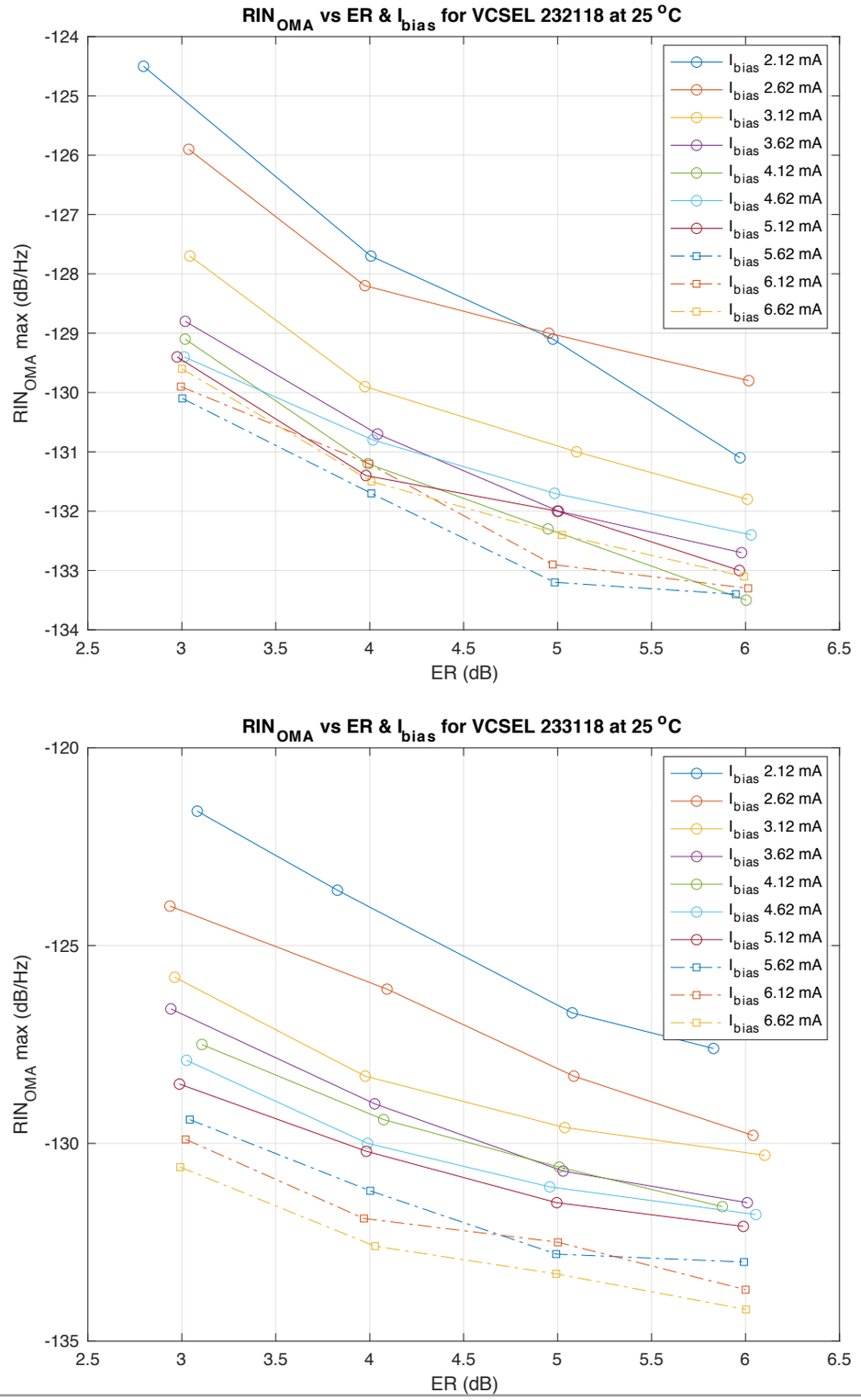
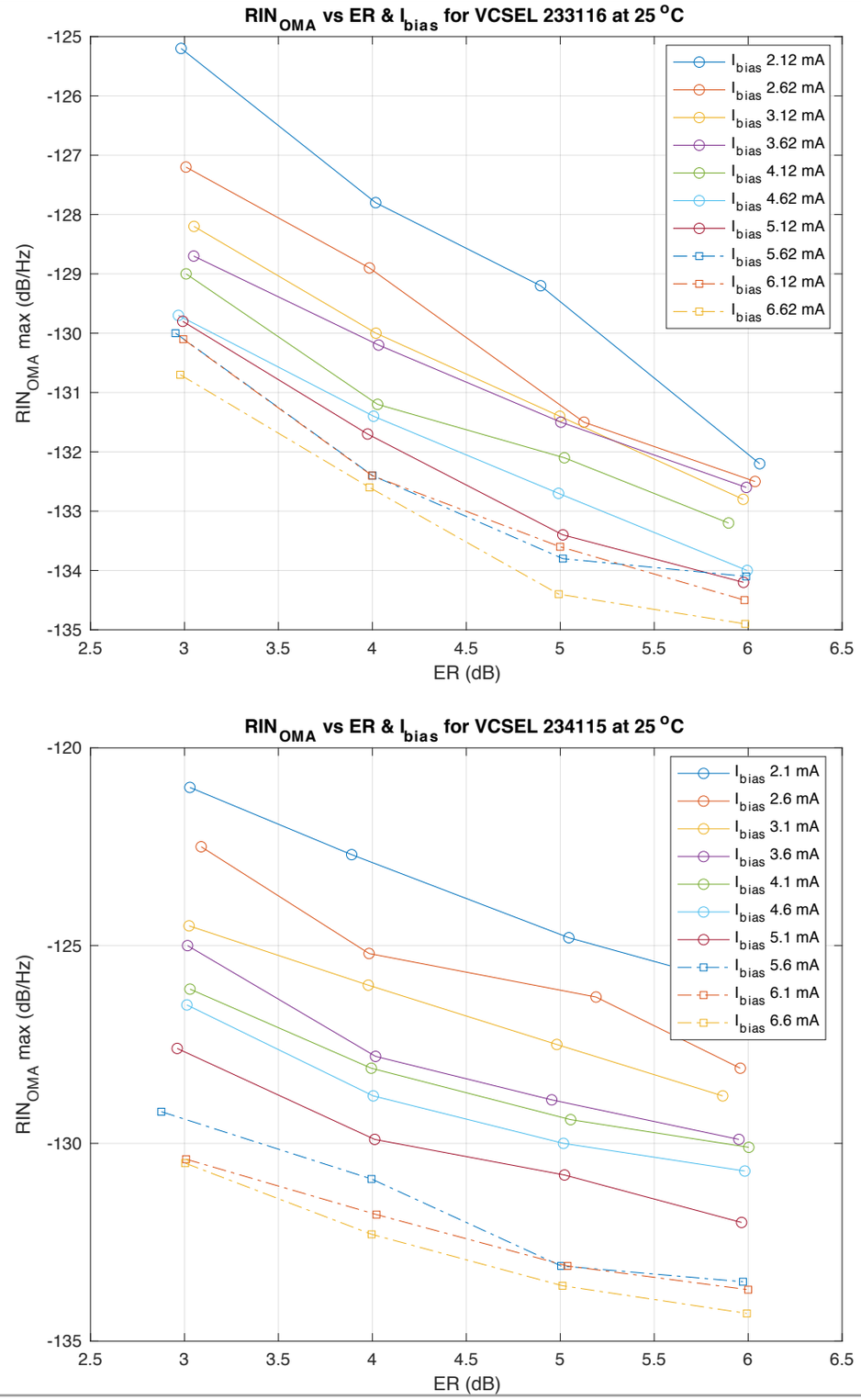


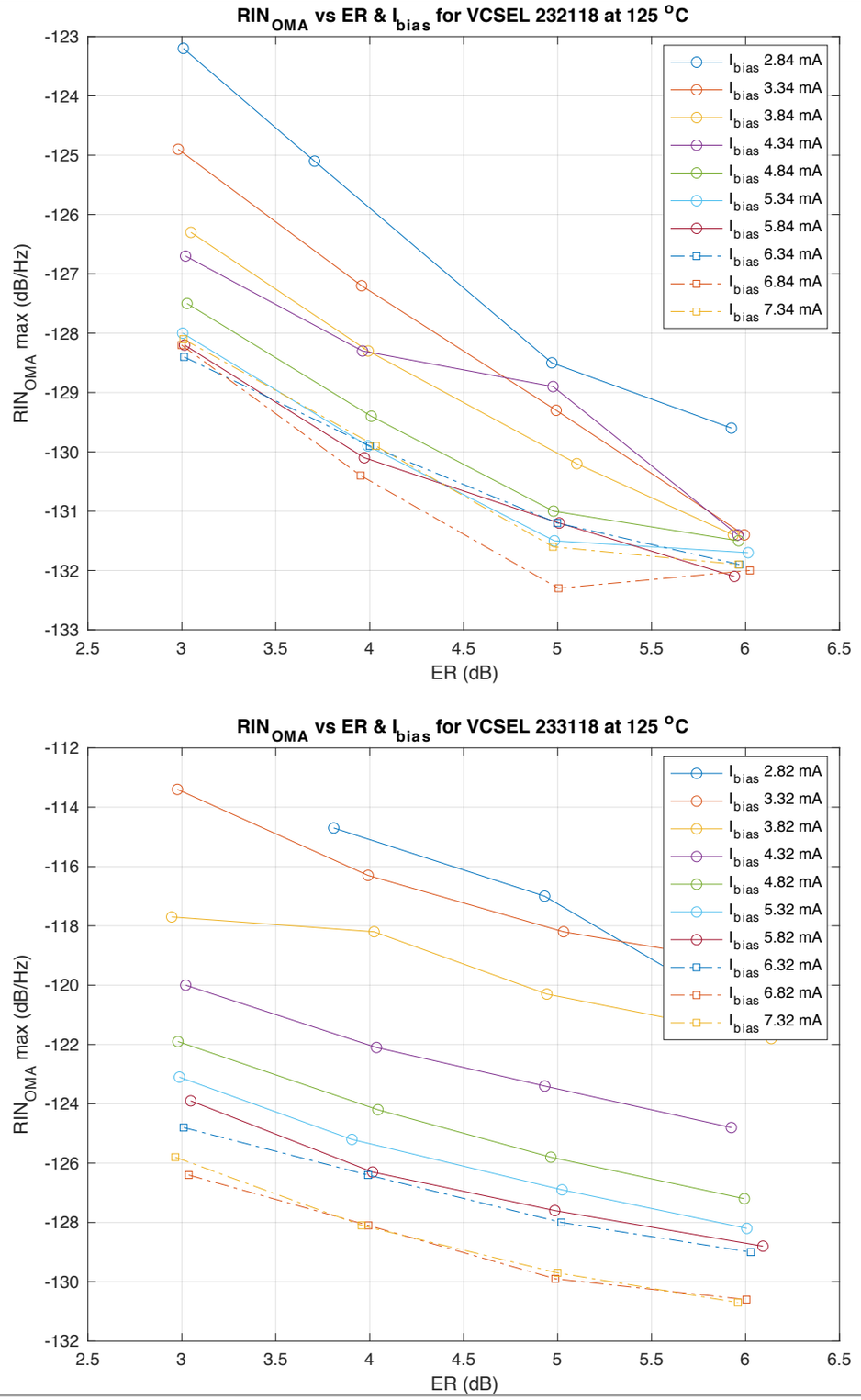


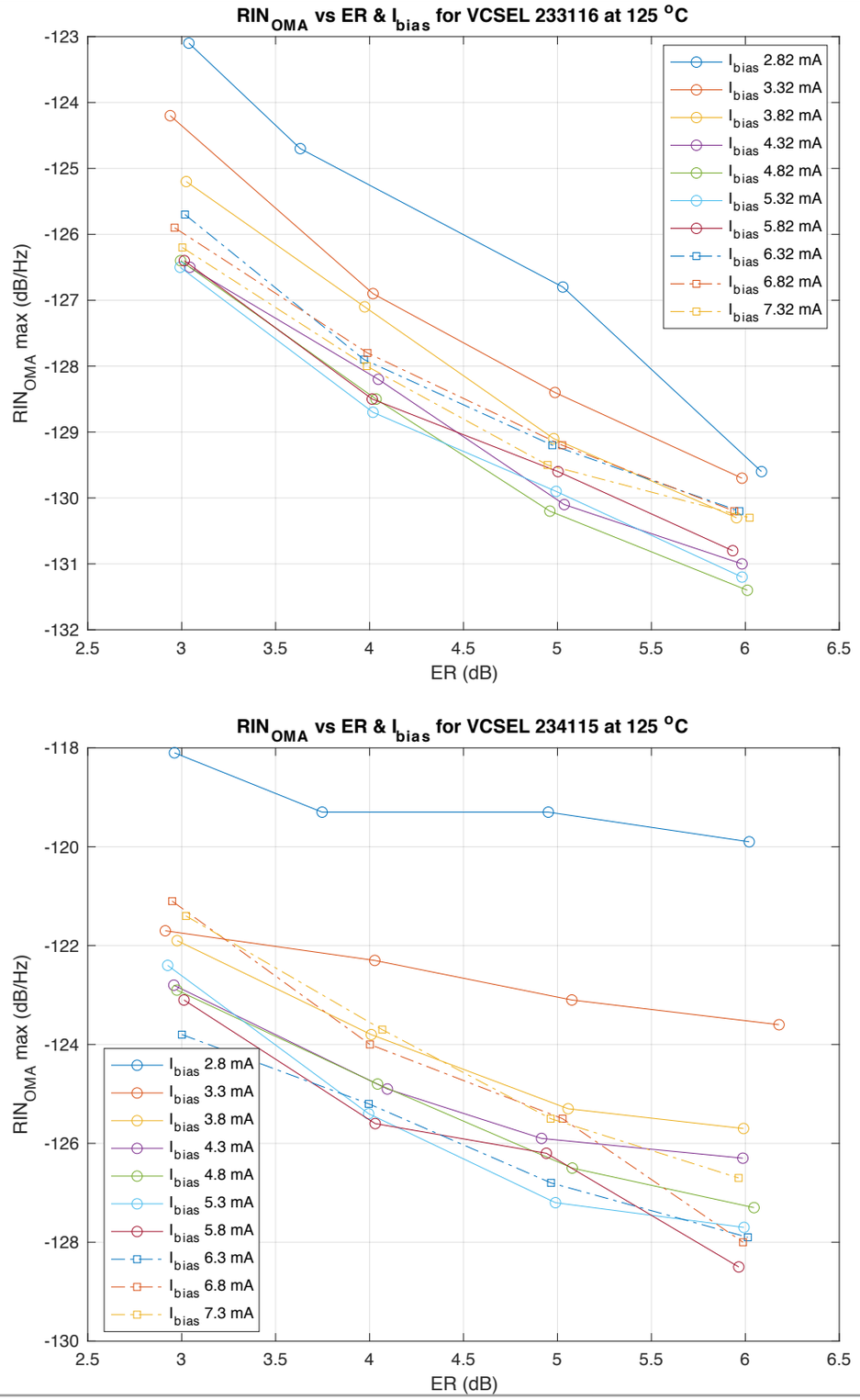
Relative intensity noise (RIN_{OMA}) at 25ºC



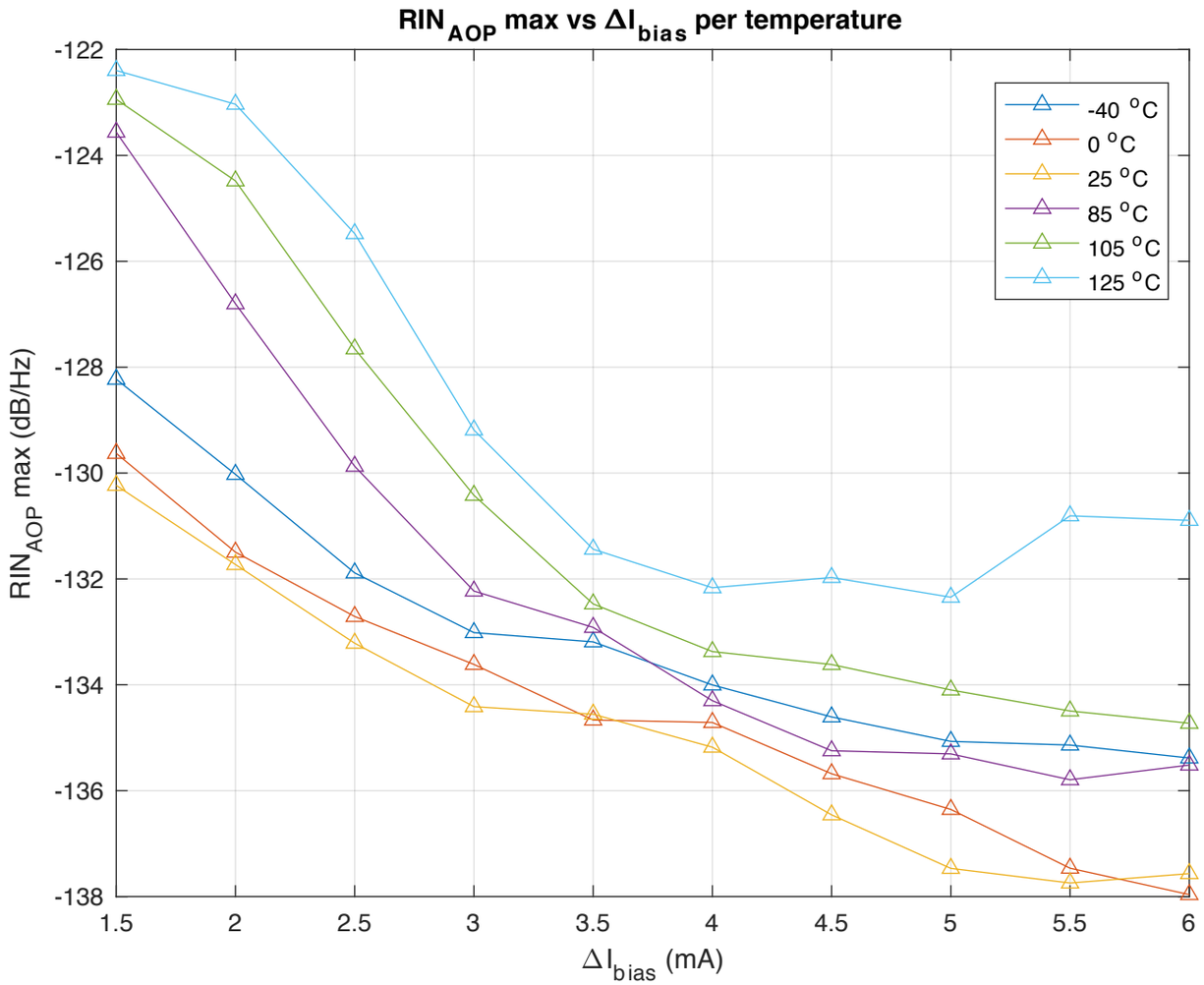


Relative intensity noise (RIN_{OMA}) at 125ºC





Normalized max RIN (RIN_{AOP})



$$RIN_{AOP}\left(dB/Hz\right) = RIN_{OMA}\left(dB/Hz\right) - 20\cdot\log_{10}\left(\frac{ER_L+1}{ER_L-1}\right)$$

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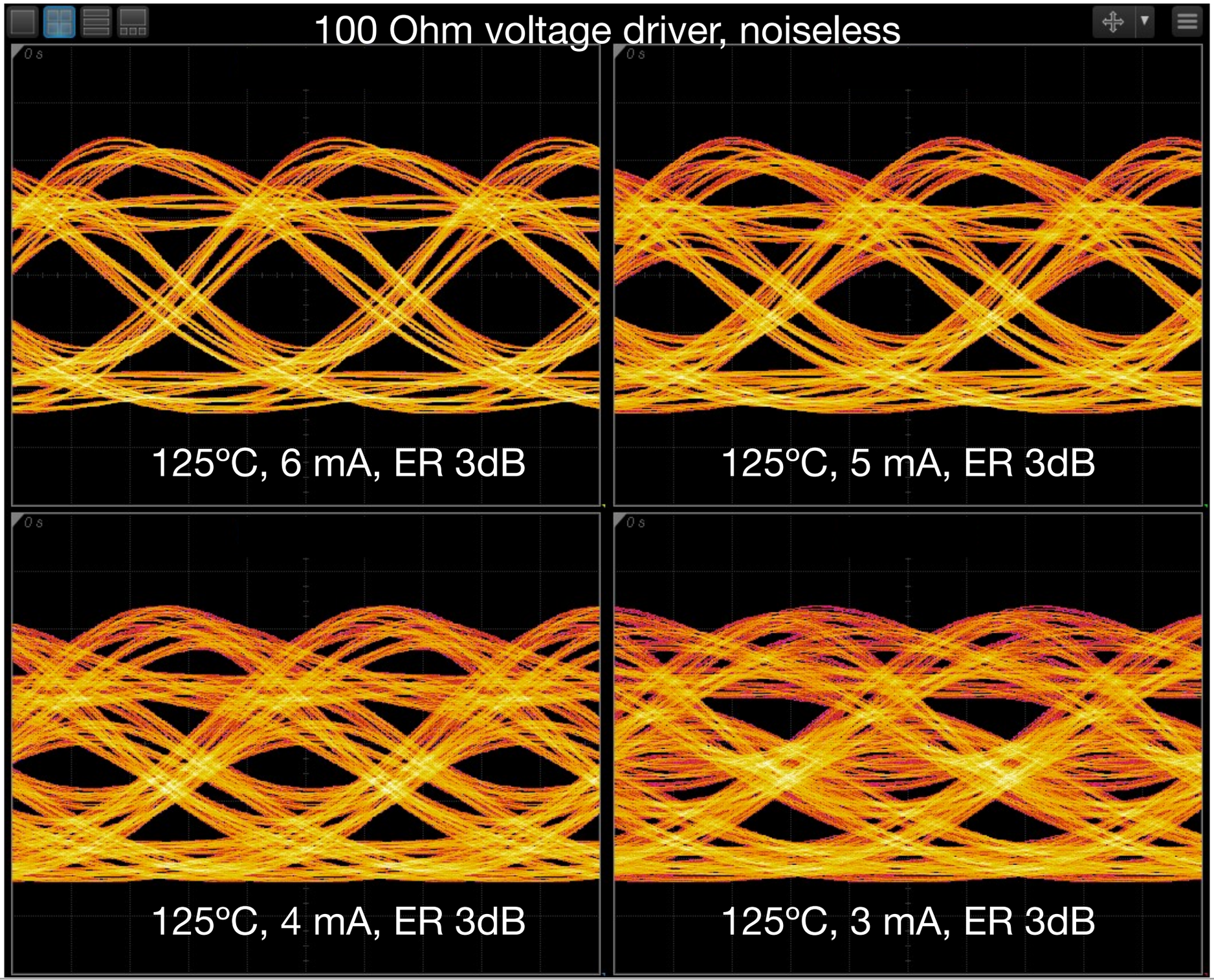
Eye diagram for 26.5625 GBd NRZ



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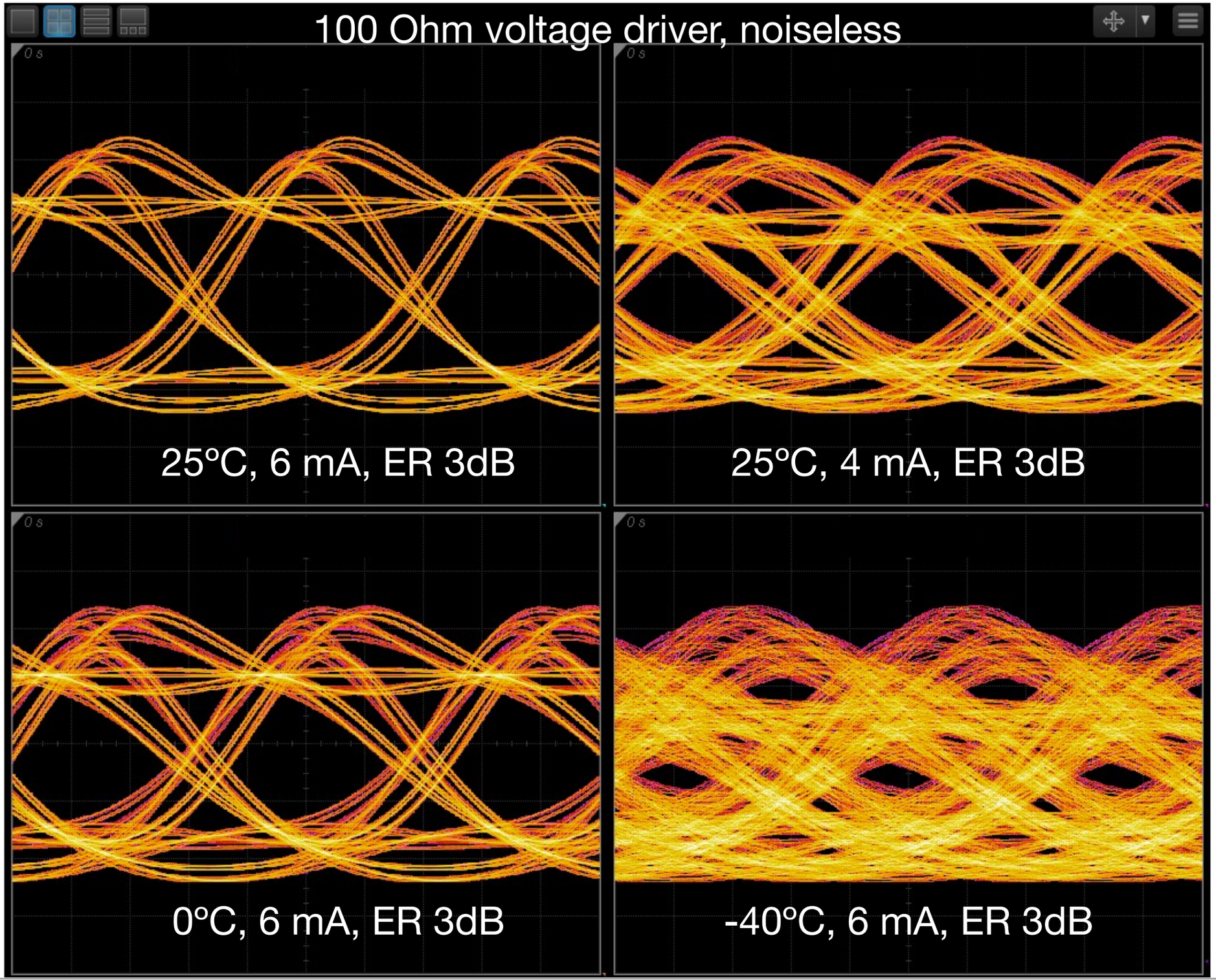

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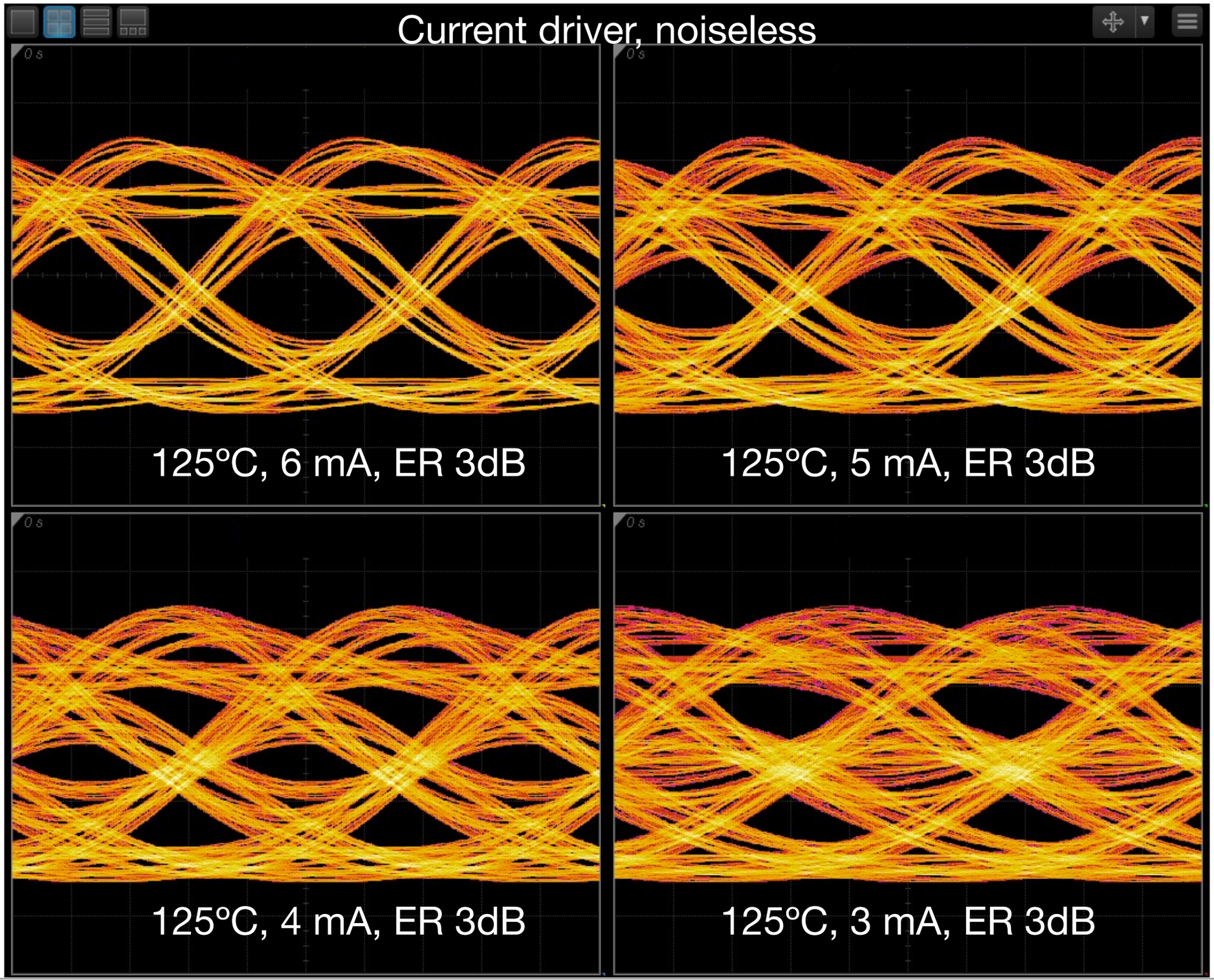

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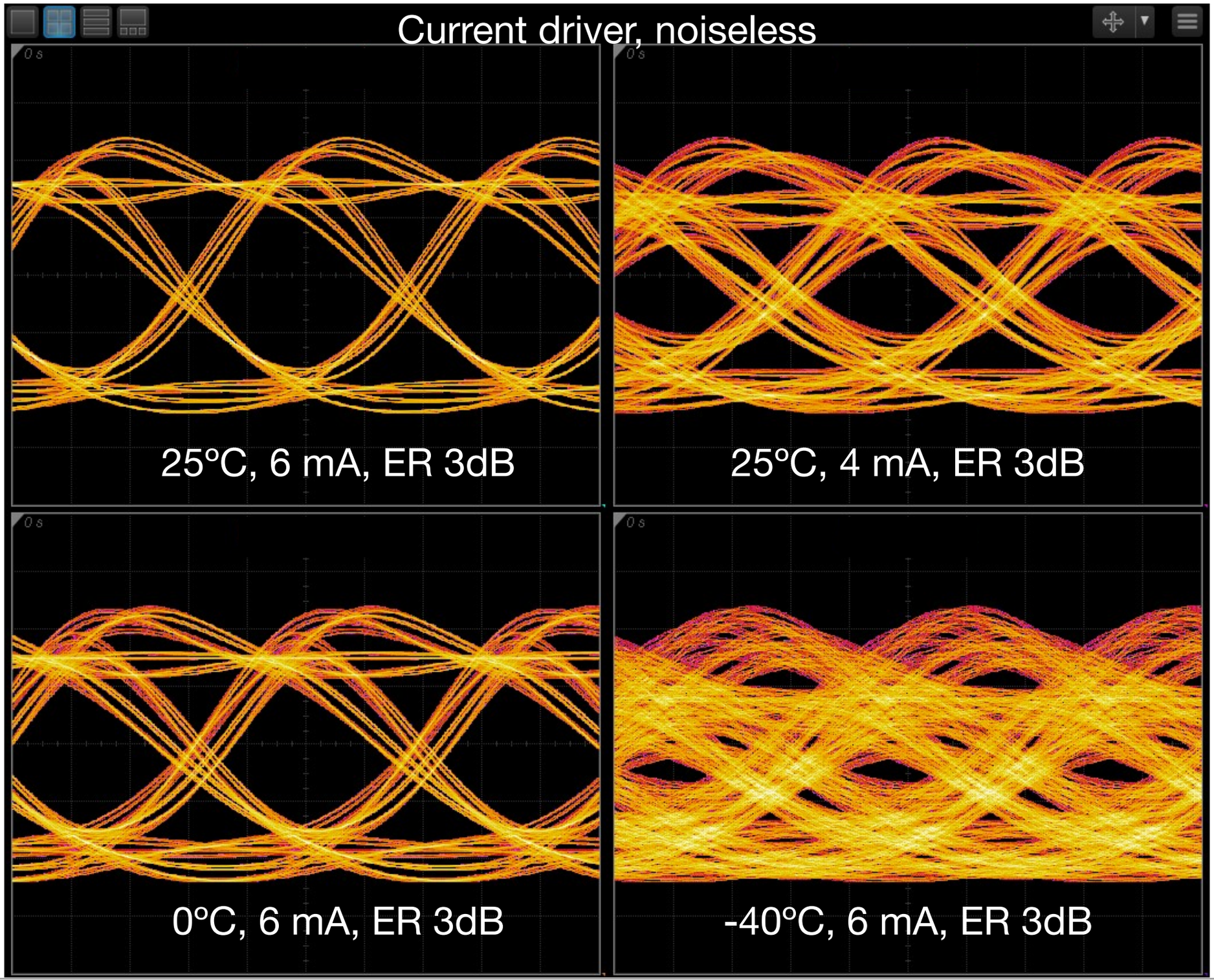

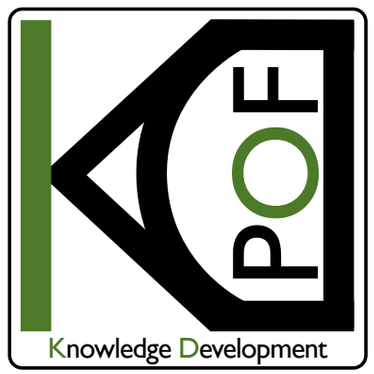

25Gbps multimode VCSEL for 990 nm

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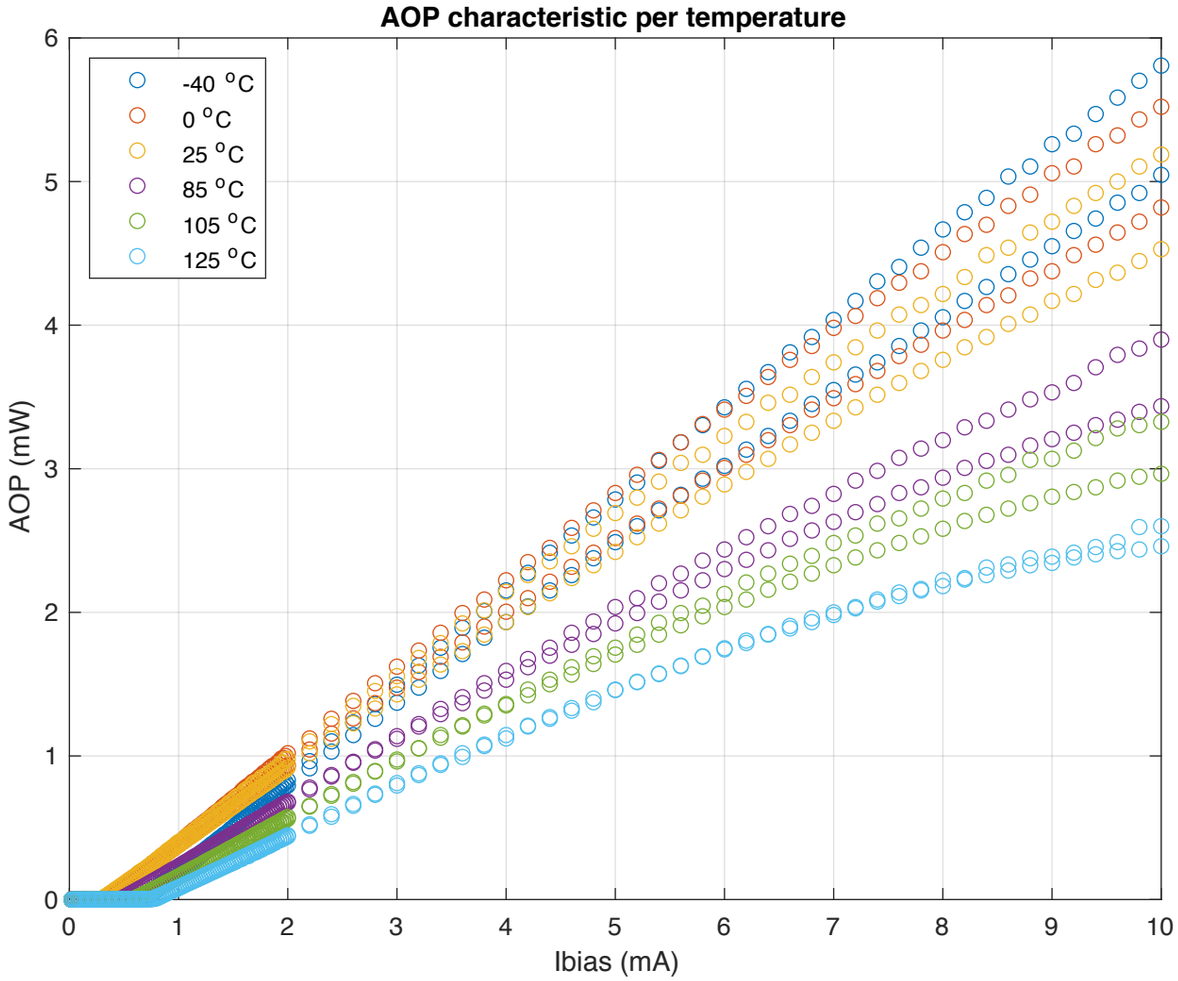
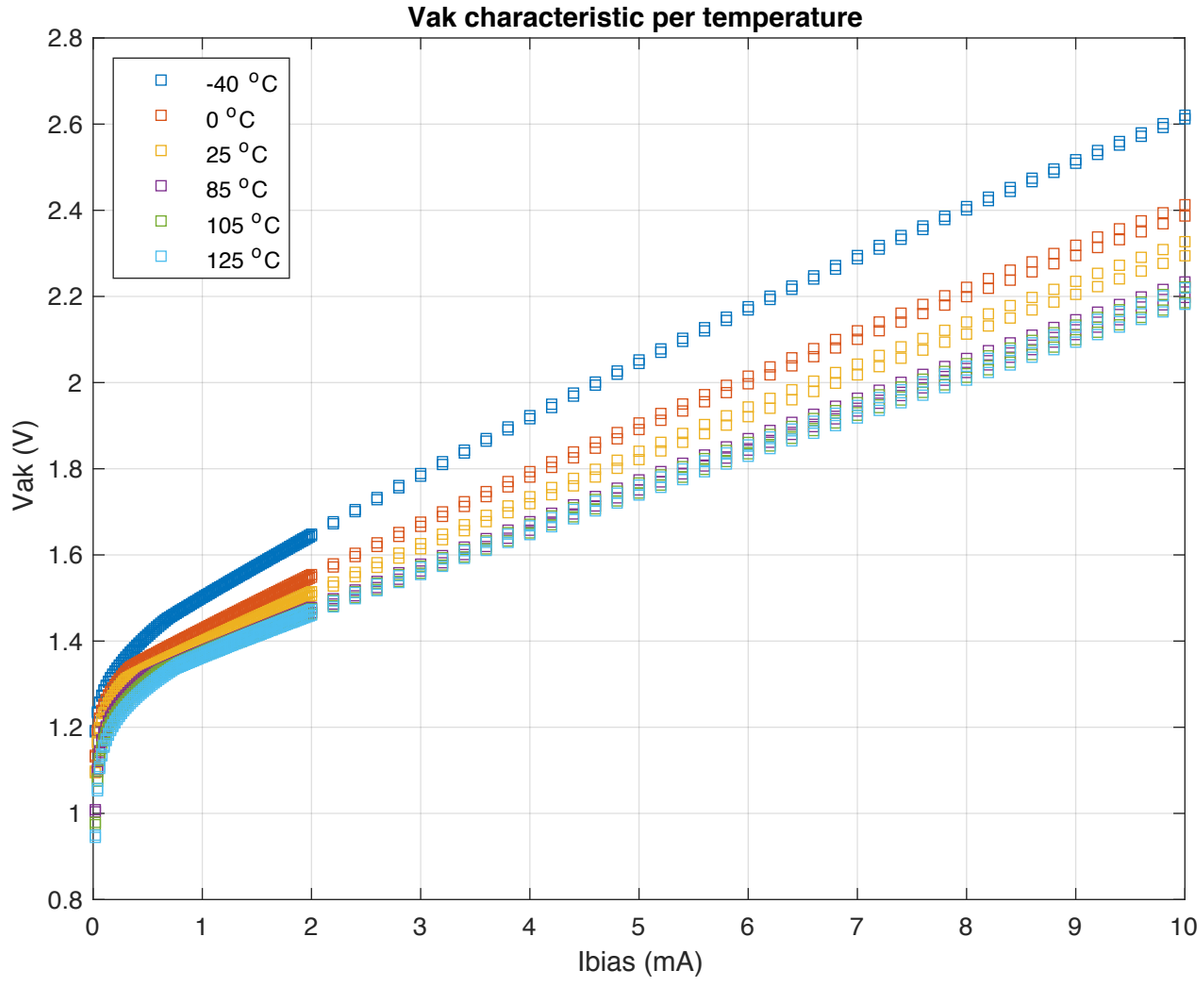
Special considerations

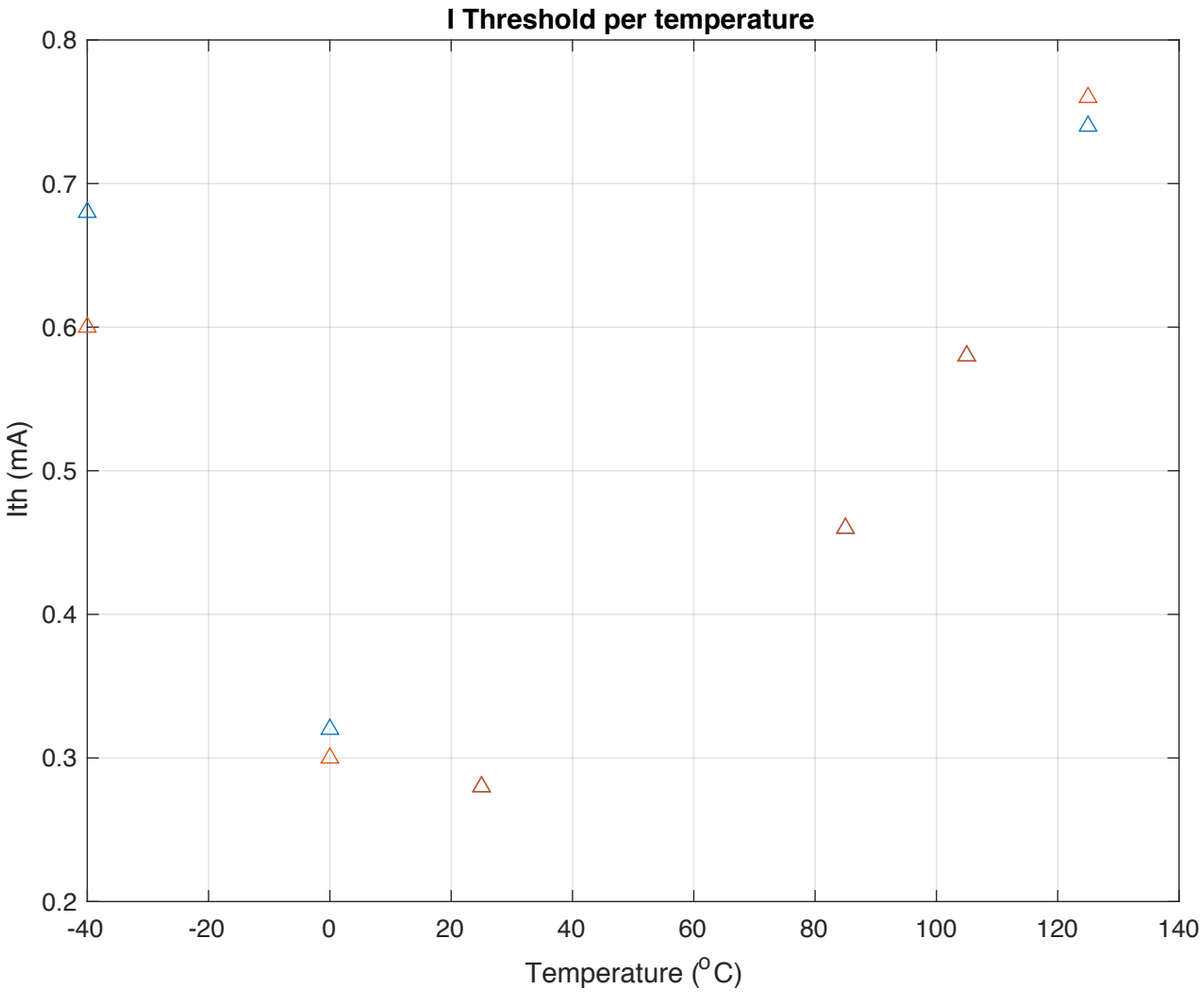
- The tested VCSEL devices are prototypes designed for bottom emitting assembly
- The VCSEL arrays have been assembled over a silicon sub-mount with metallization to make possible electrical connection by wire bonding to the PCB
- This special assembly imposes additional thermal resistances in the heat dissipation path that may affect the obtained performance in temperature
- Because of this fact, performance results in high temperature may have been degraded and performance results in low temperature may have been improved with respect to a lower thermal resistance assembly (i.e. more realistic condition)
- Further studies will be carried out on these devices

L-I-V characteristic

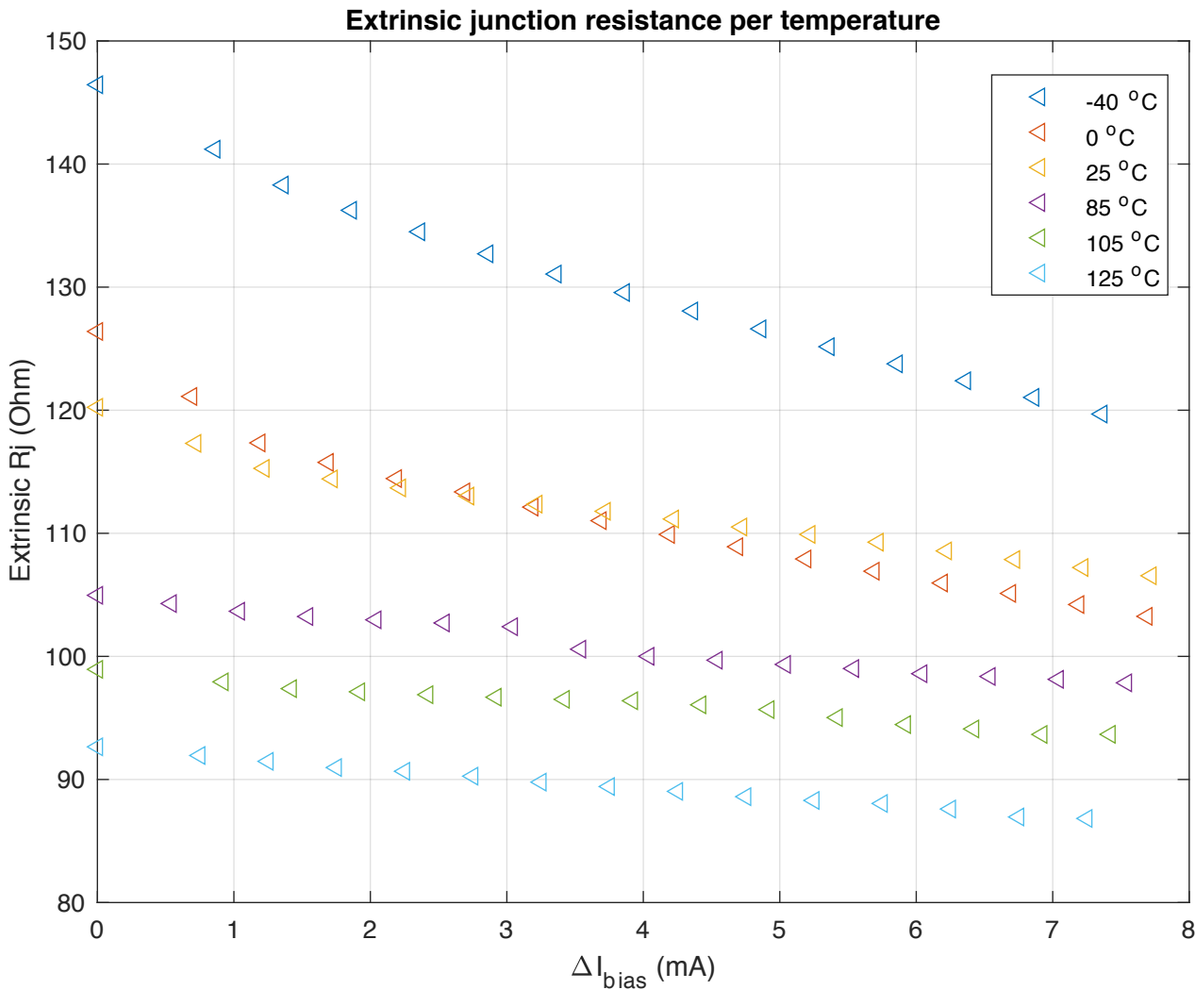


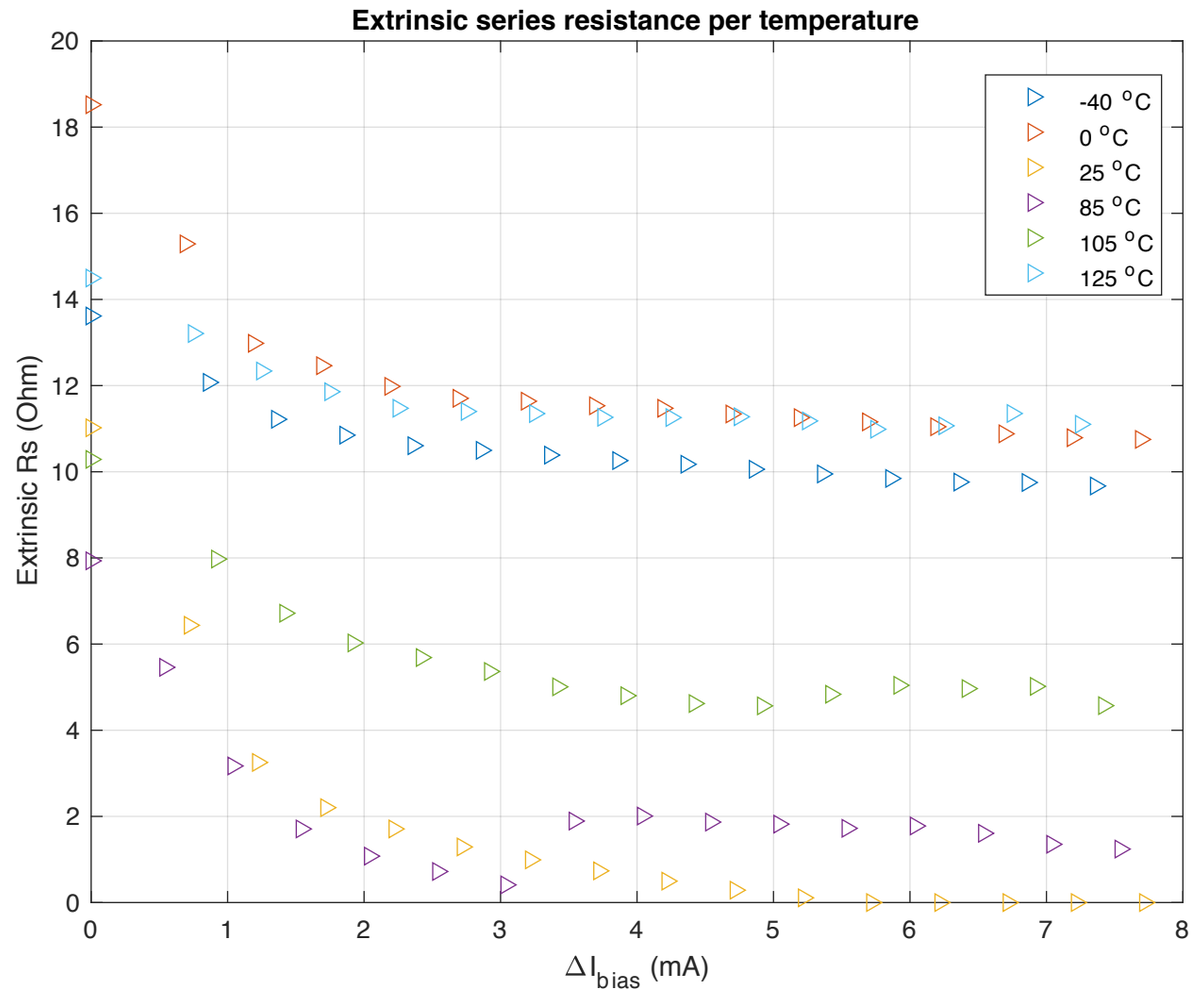


Threshold current characteristic



Small signal frequency response





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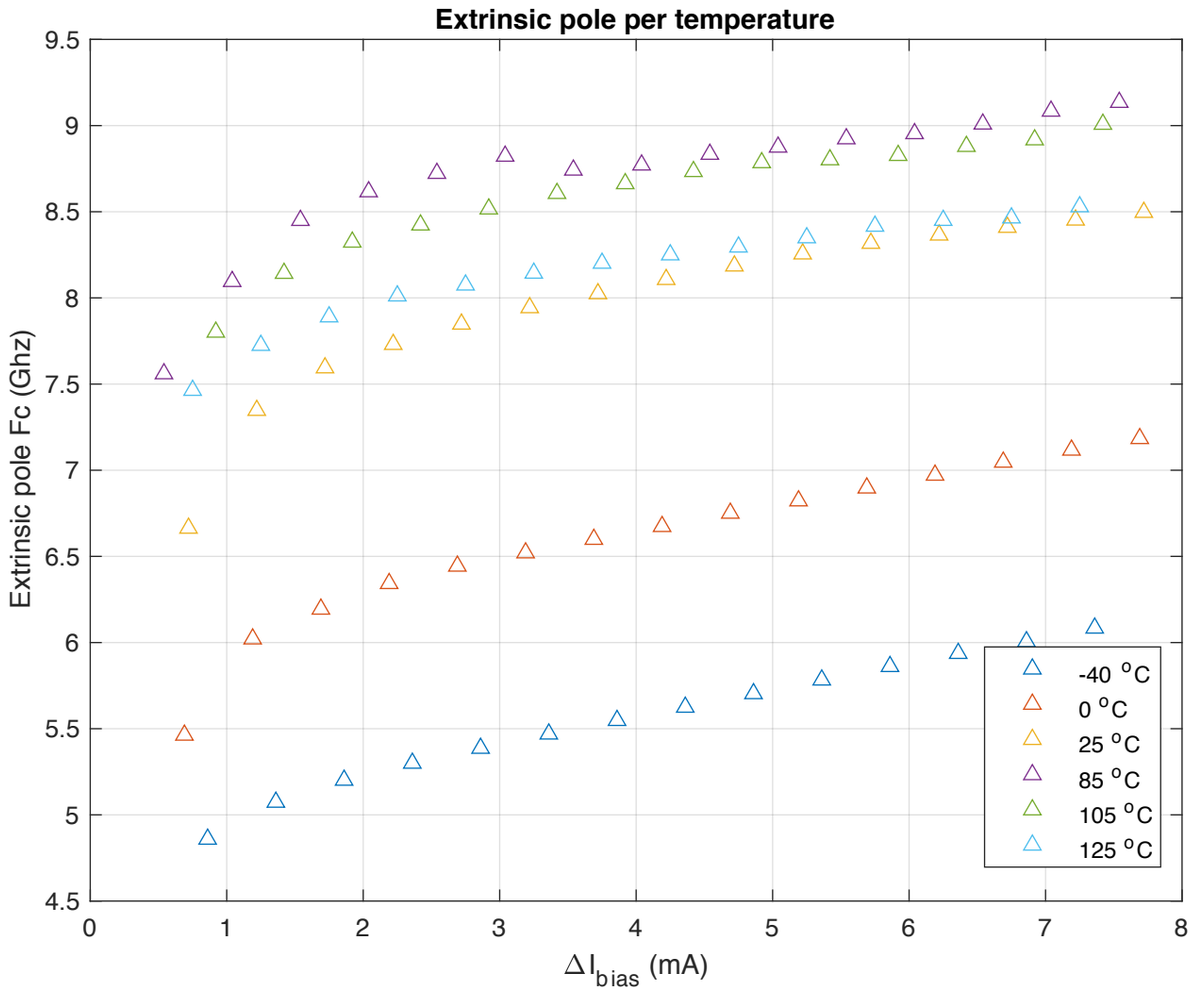

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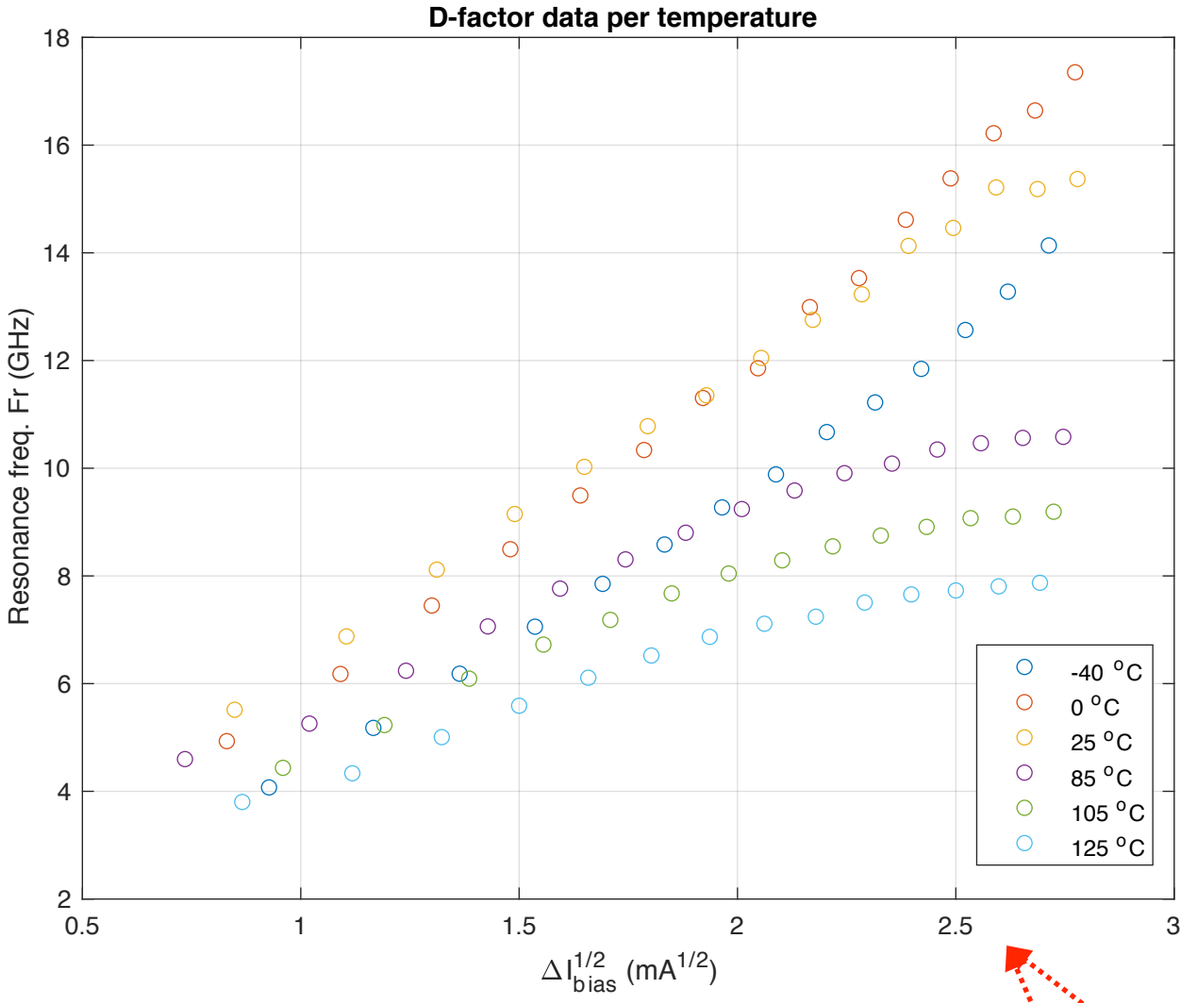

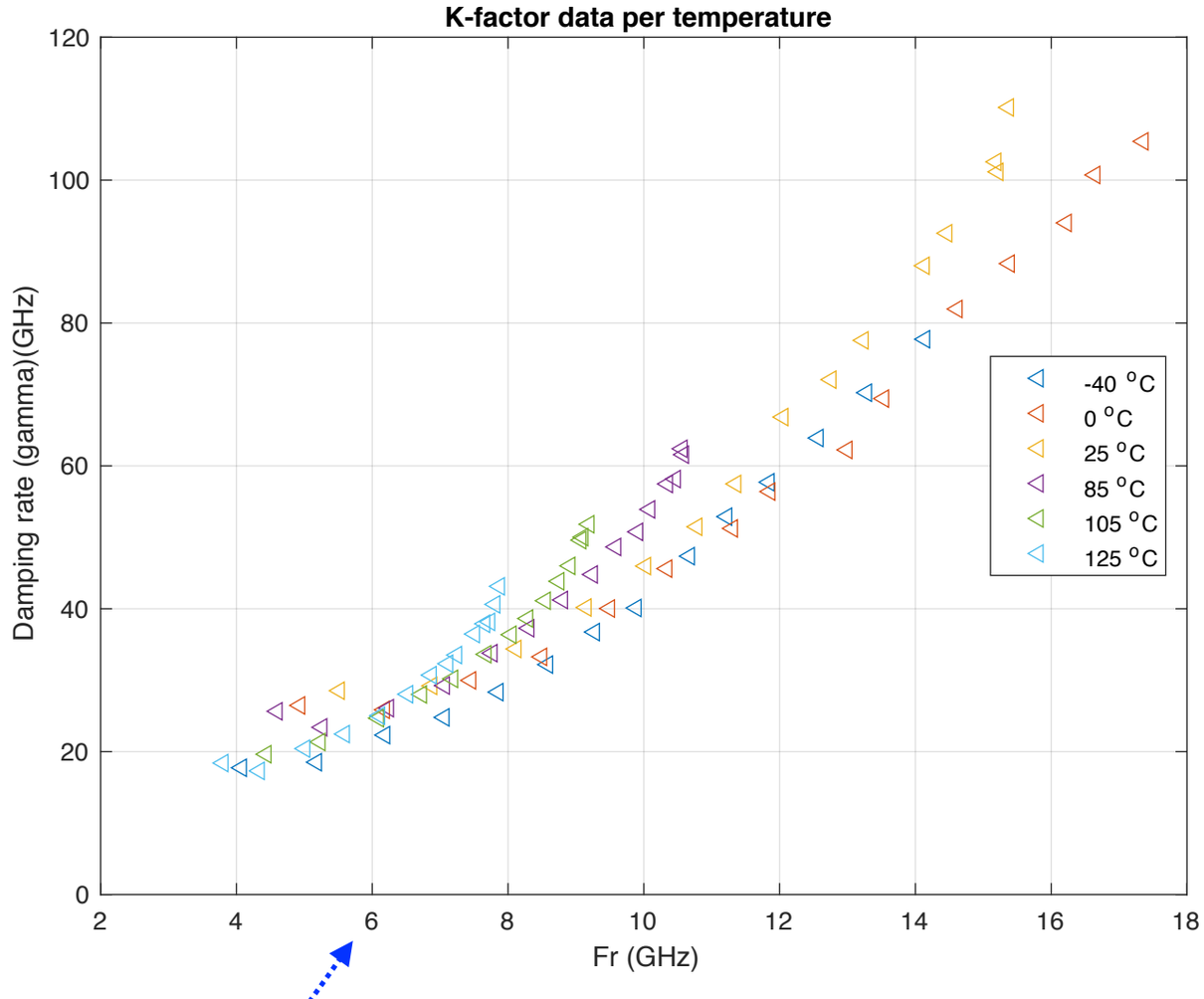

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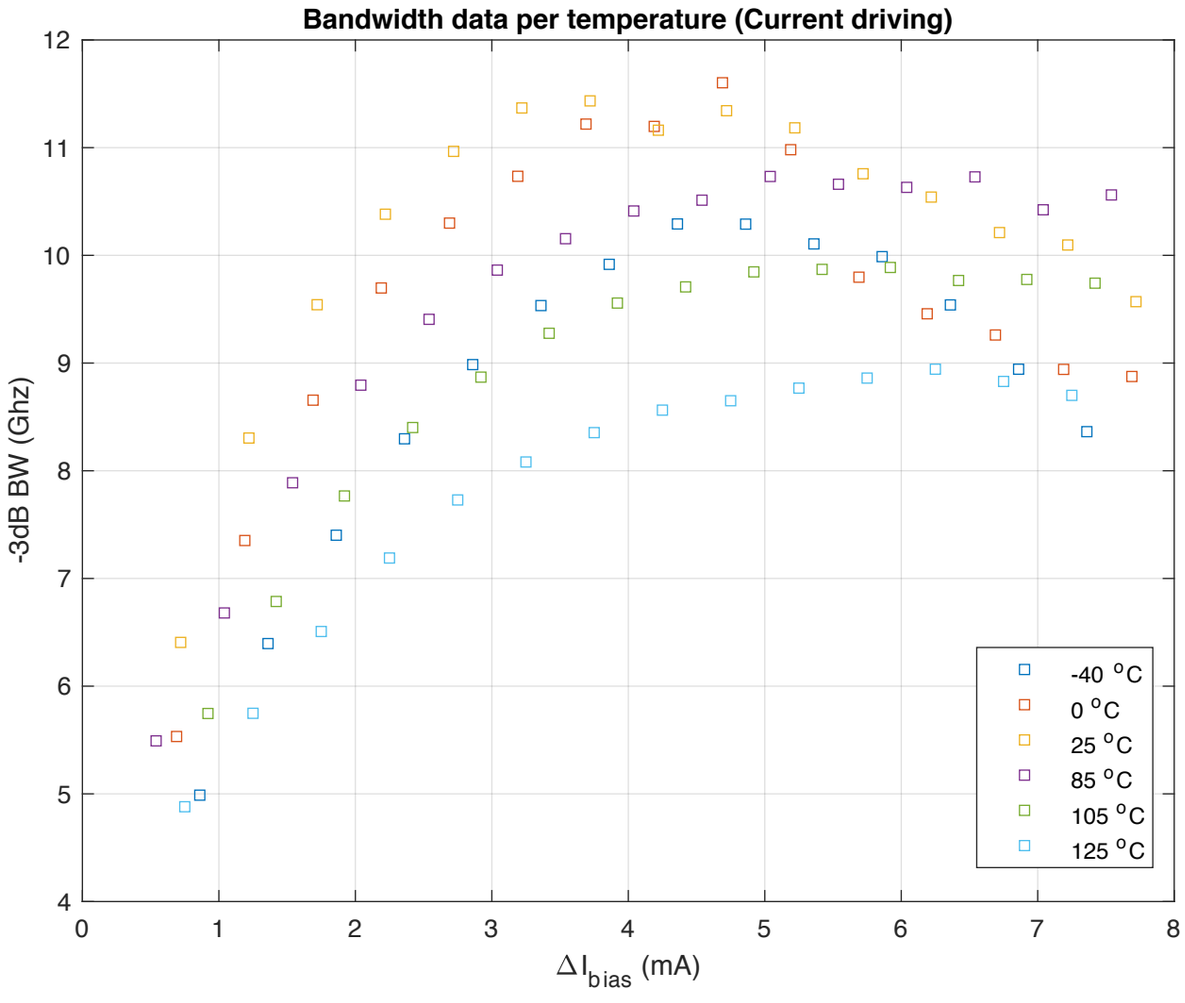
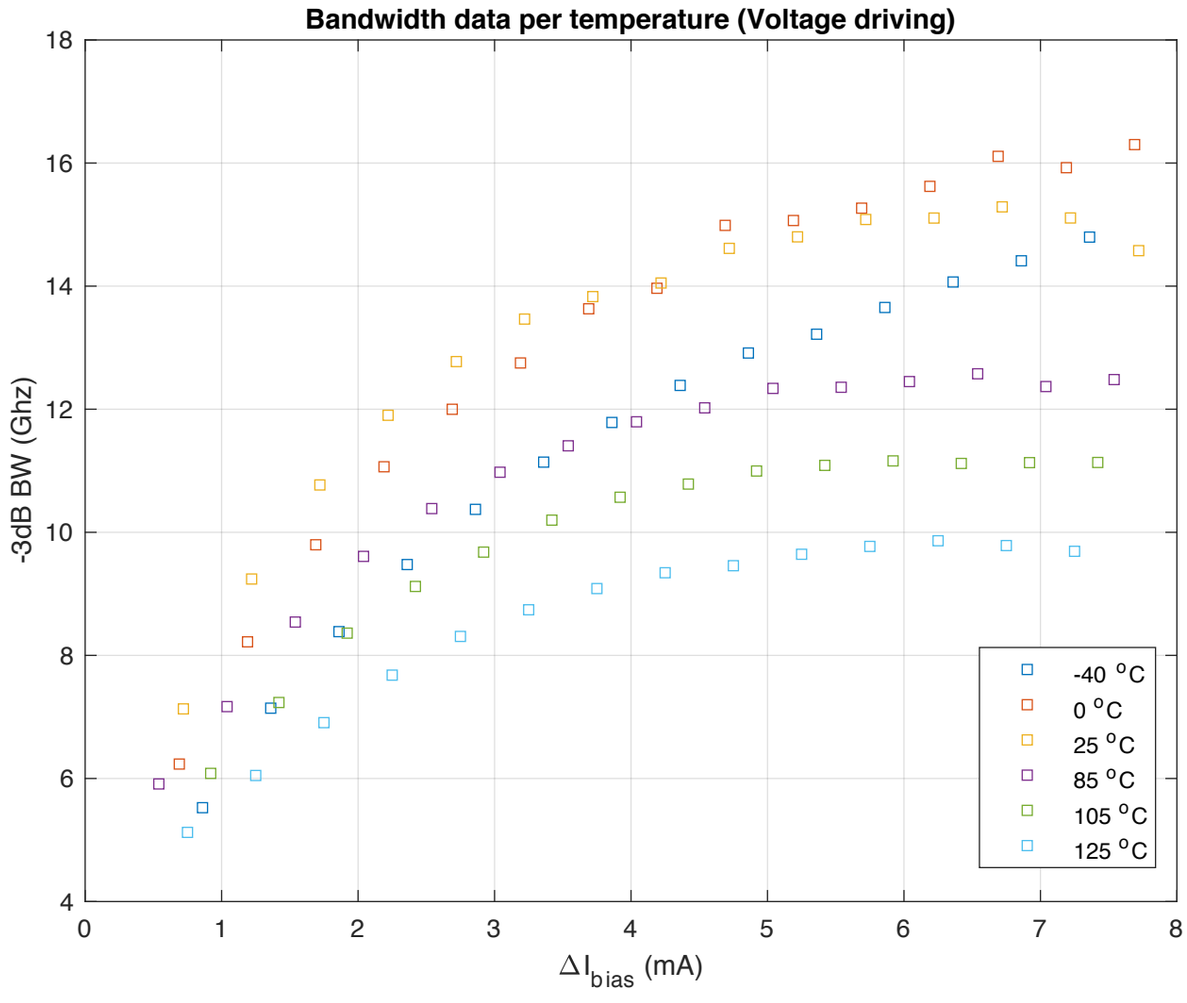
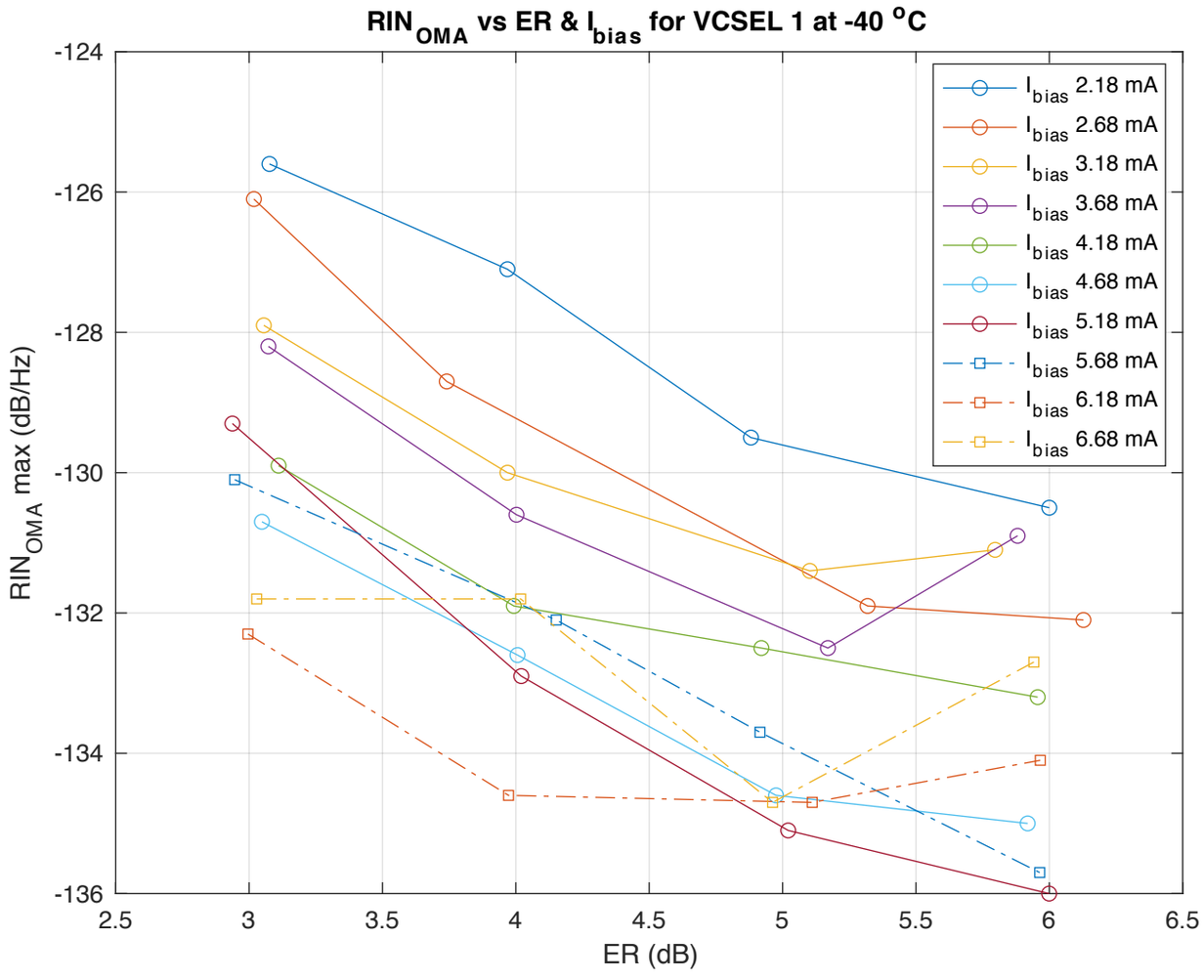
Small signal frequency response

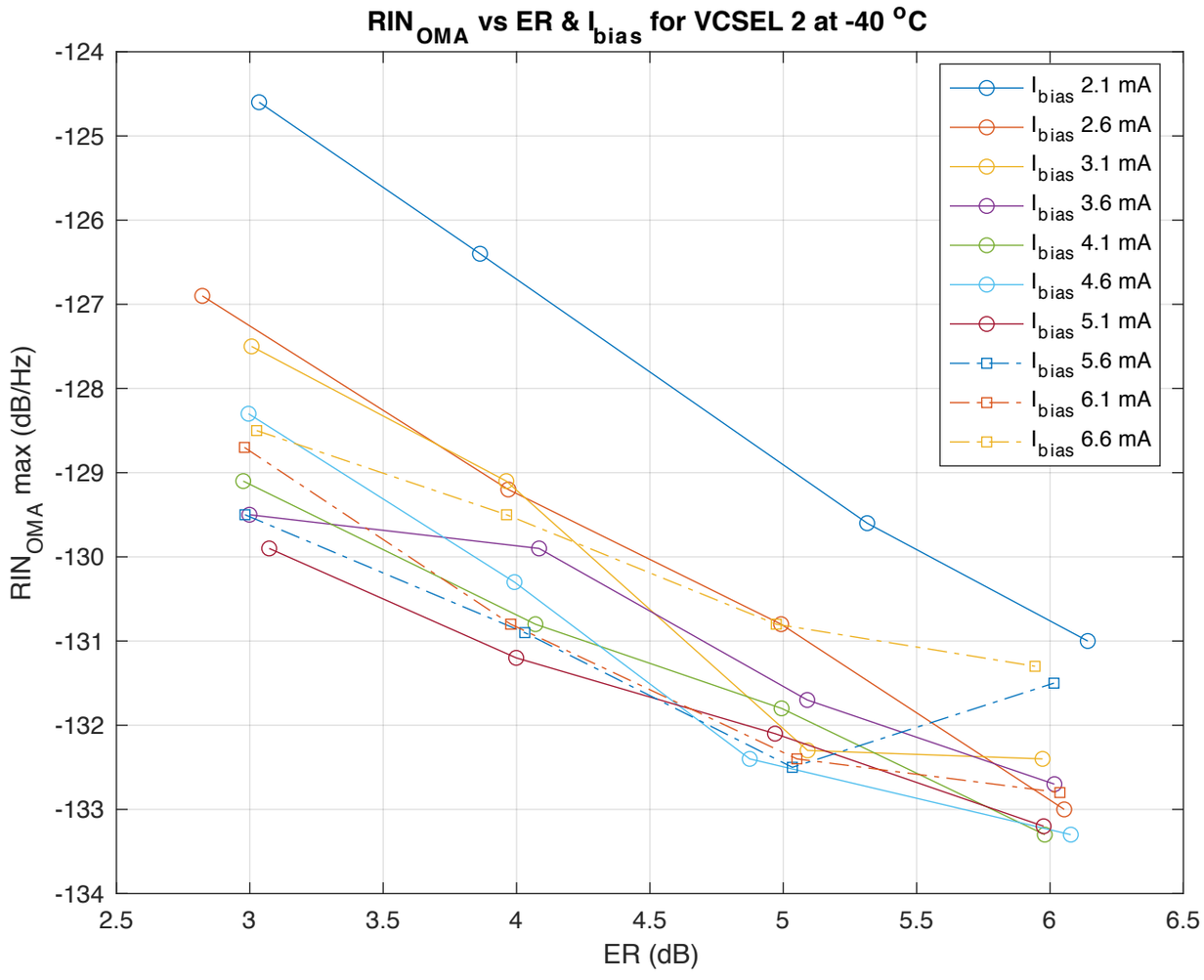




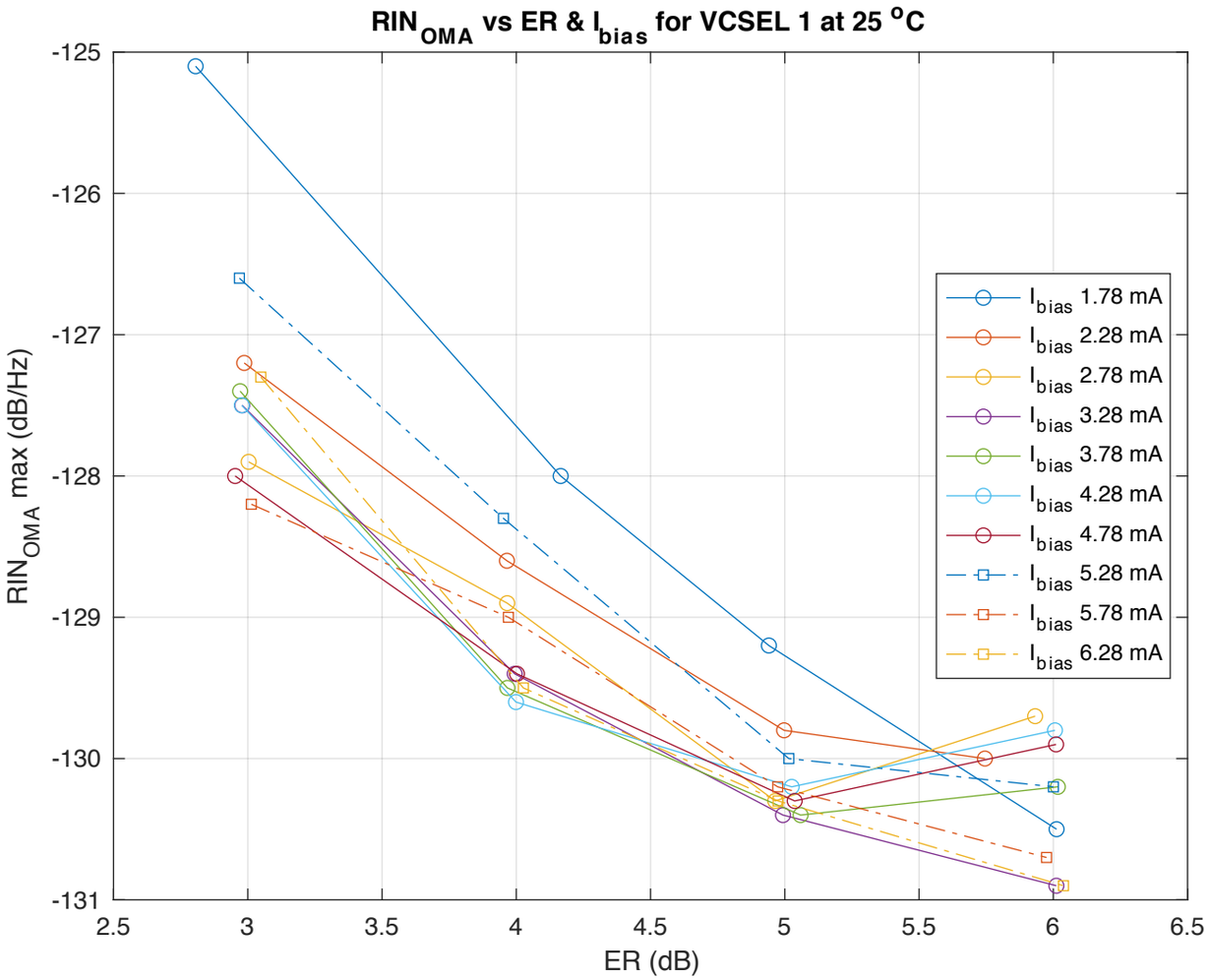
Considered source impedance 100 Ω

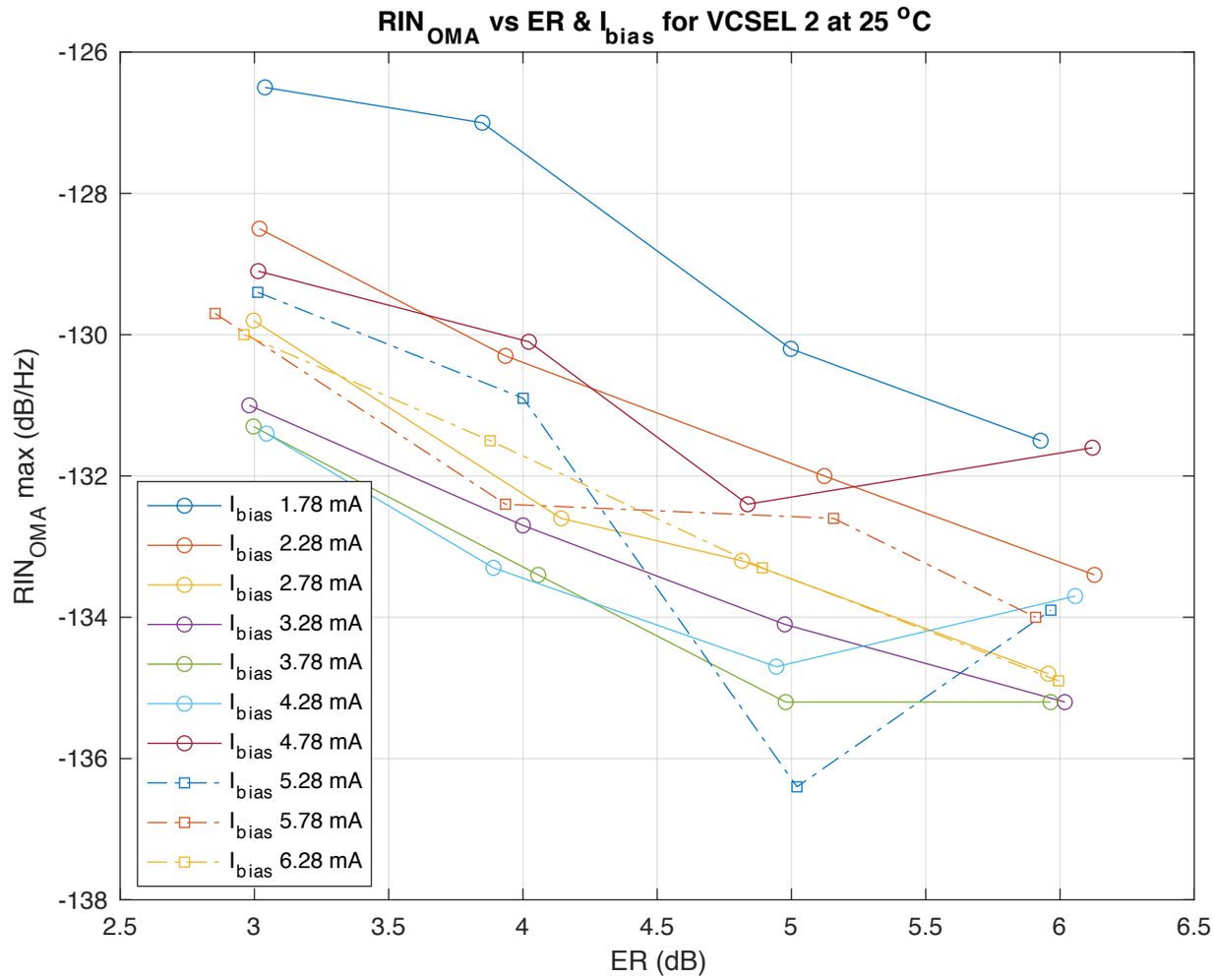
Relative intensity noise (RIN_{OMA}) at -40ºC



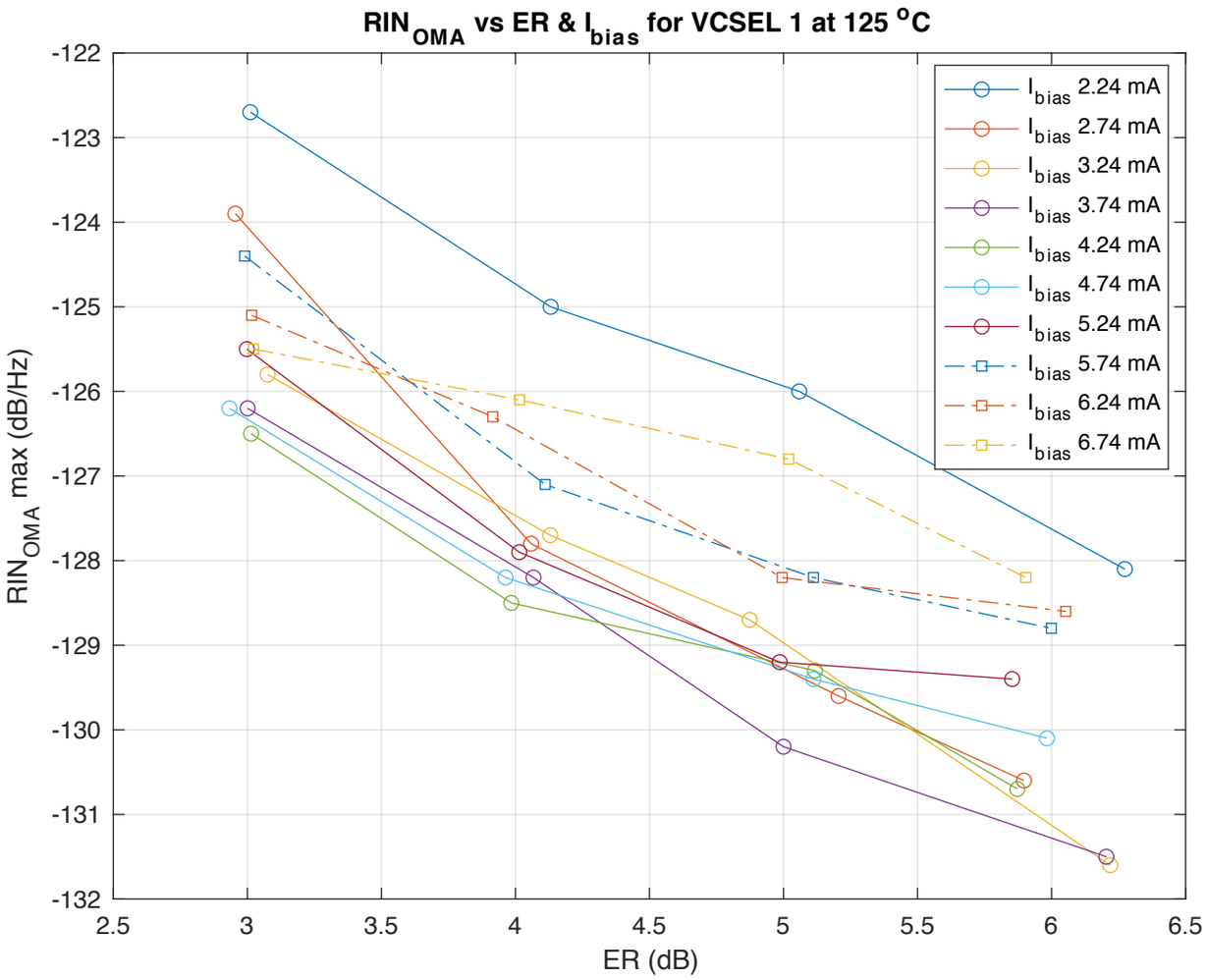


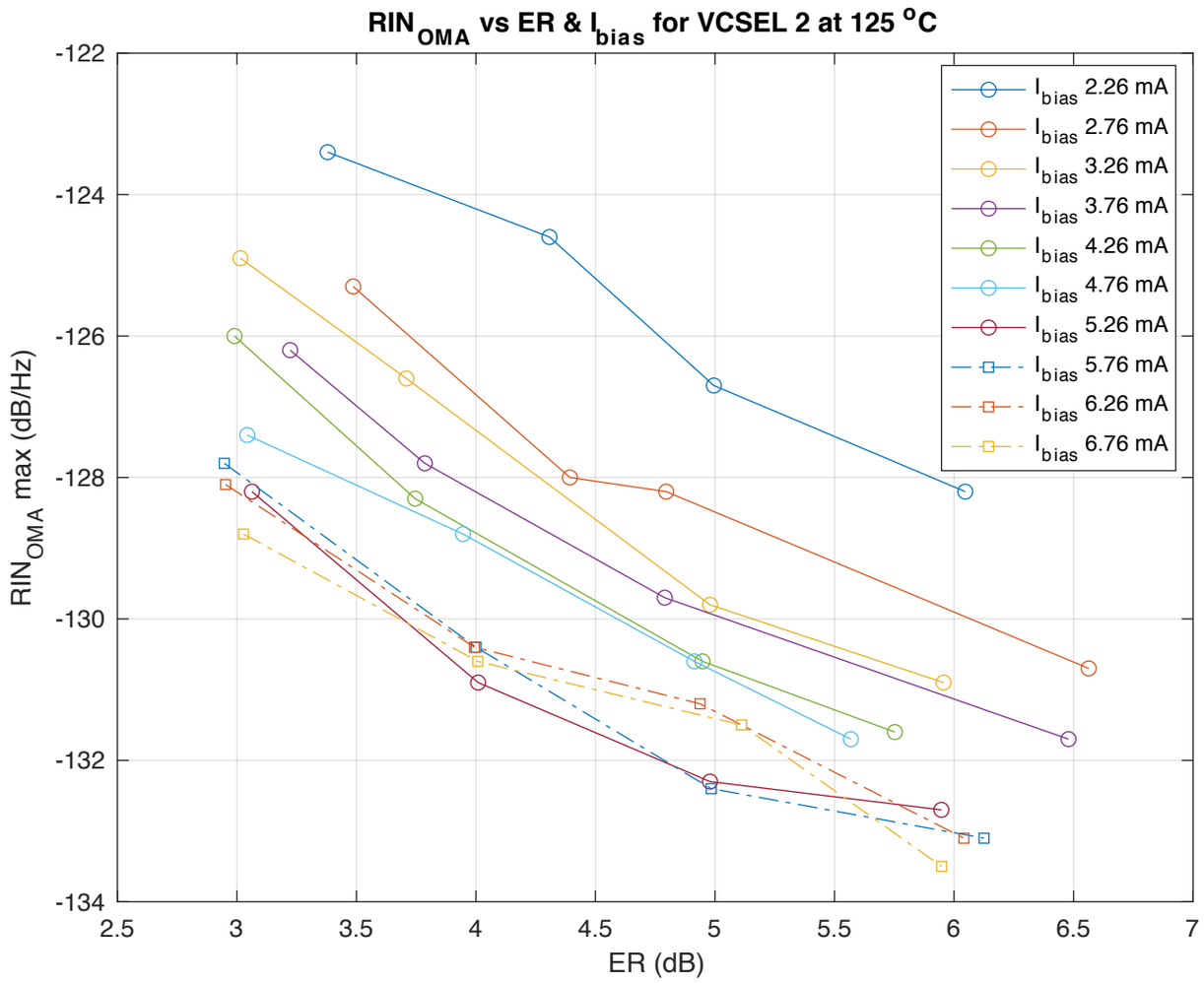
Relative intensity noise (RIN_{OMA}) at 25ºC



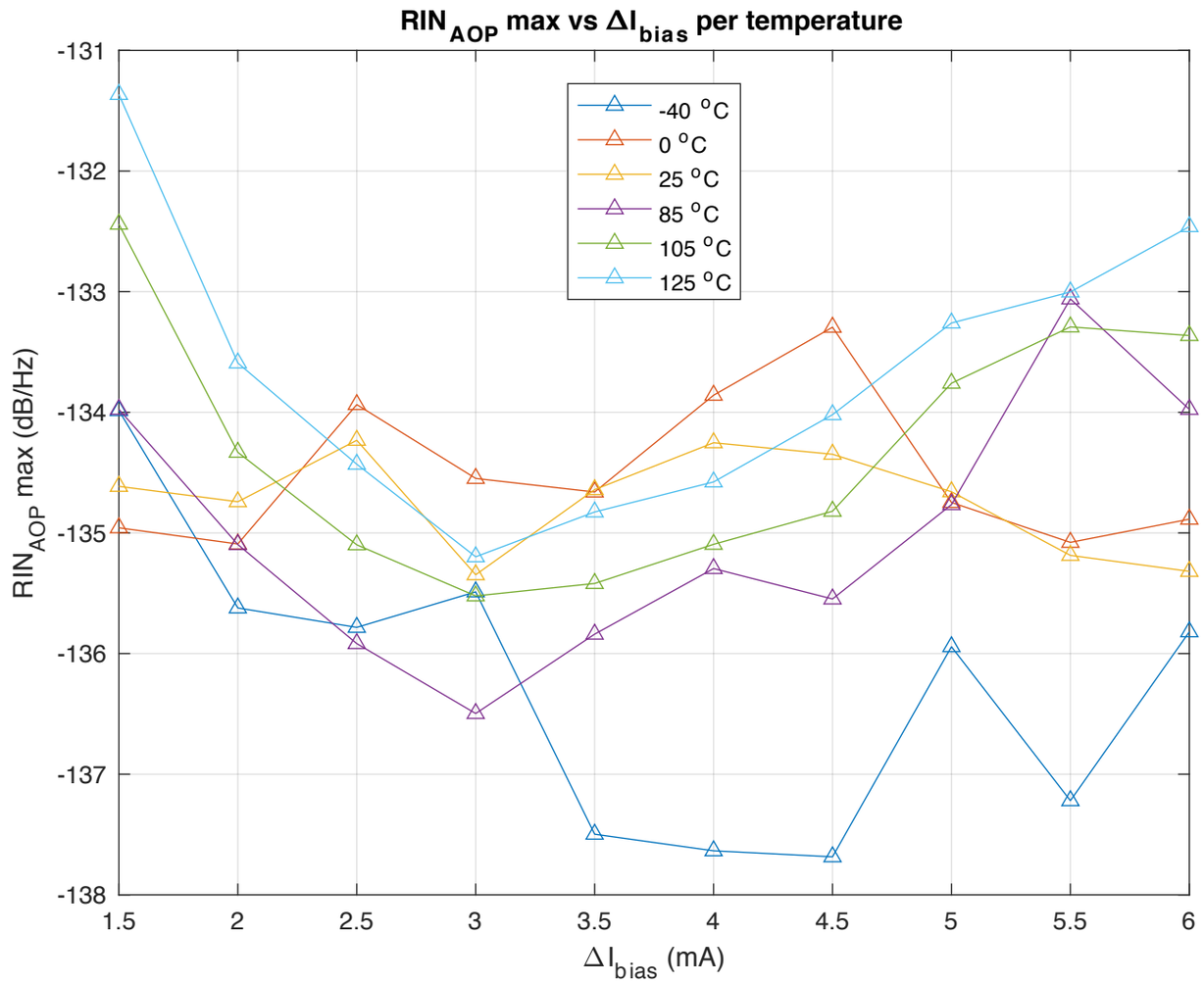


Relative intensity noise (RIN_{OMA}) at 125ºC





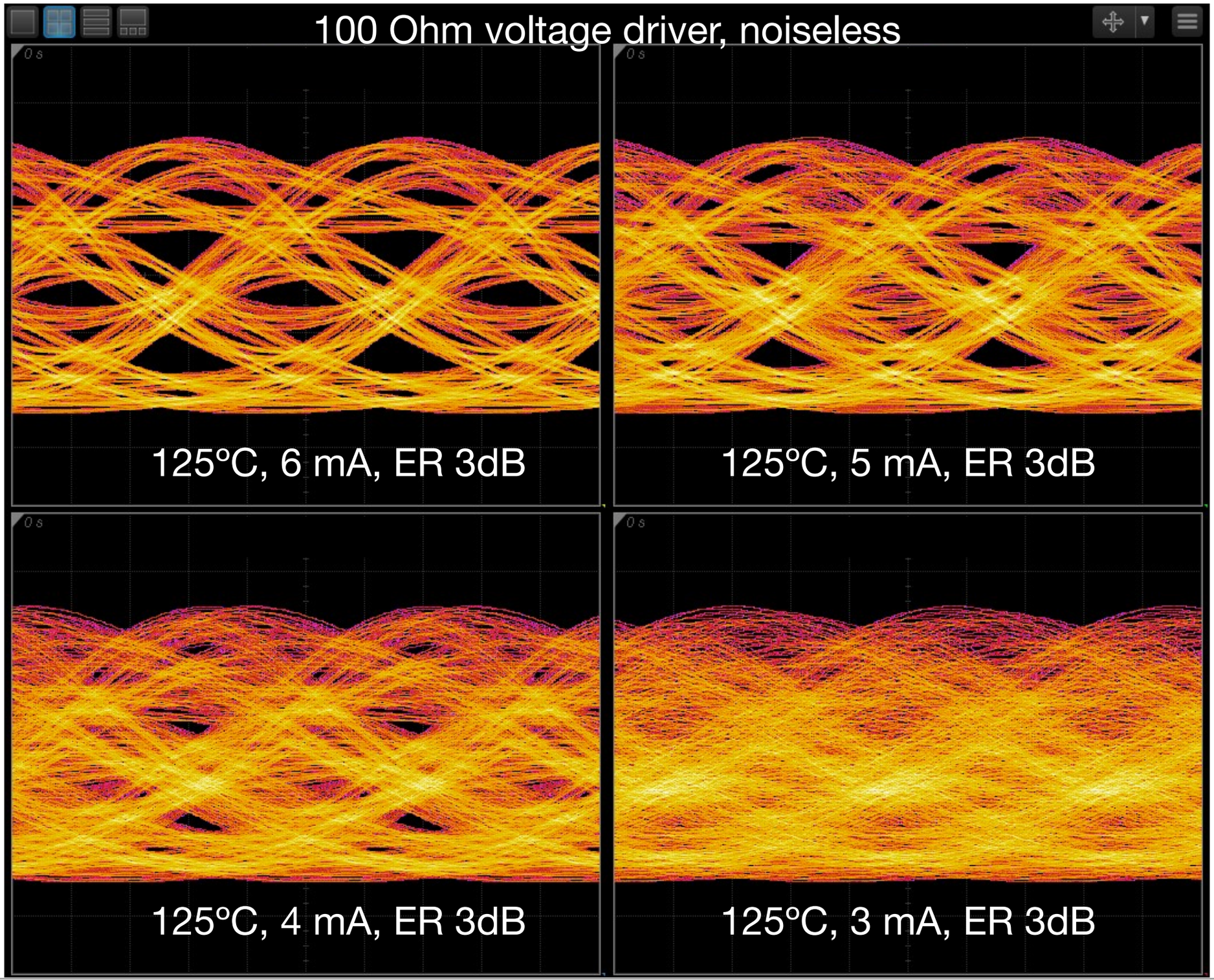
Normalized max RIN (RIN_{AOP})



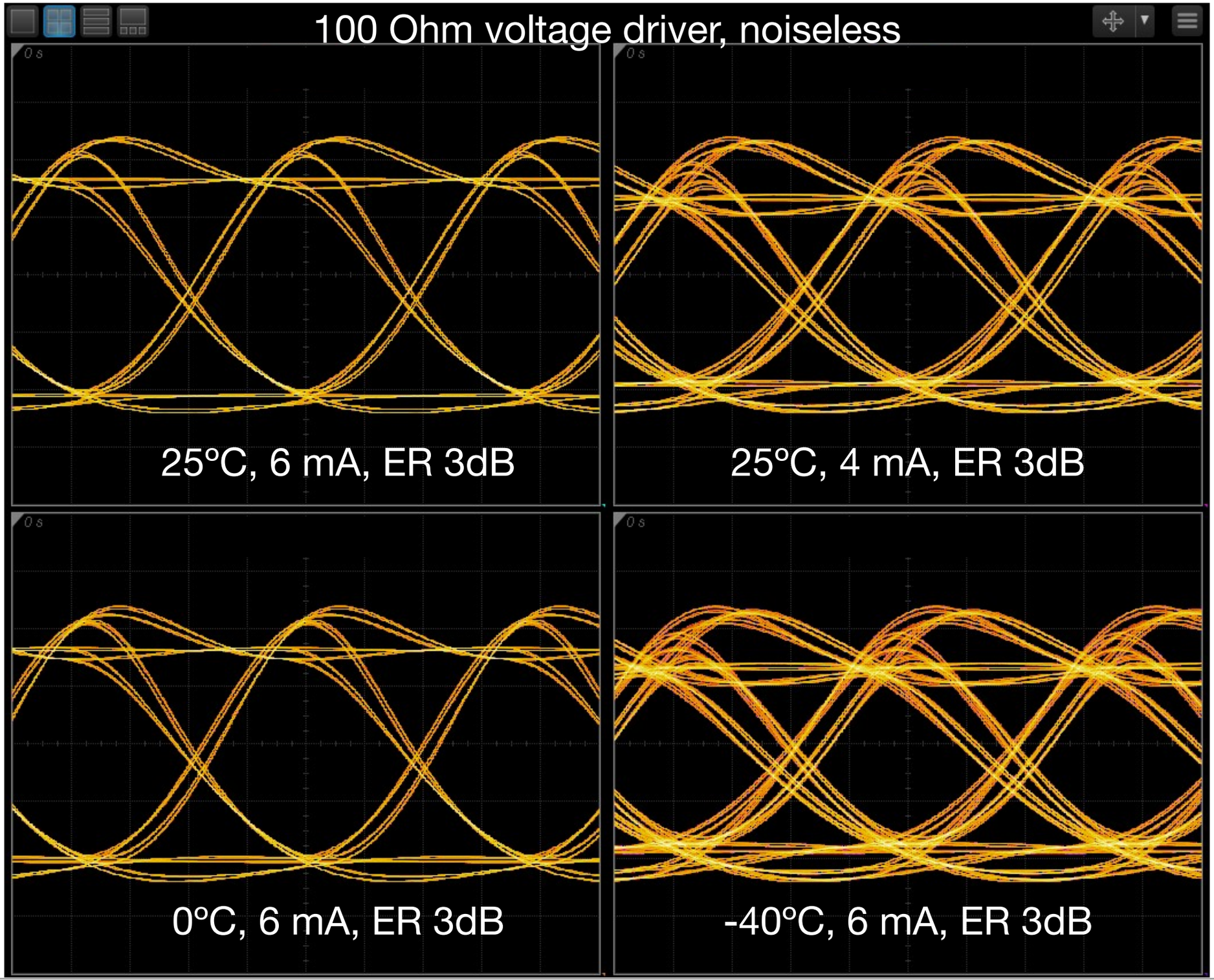
$$RIN_{AOP}\left(dB/Hz\right) = RIN_{OMA}\left(dB/Hz\right) - 20\cdot\log_{10}\left(\frac{ER_L+1}{ER_L-1}\right)$$

$$ER_L = 10^{ER(dB)/10}$$

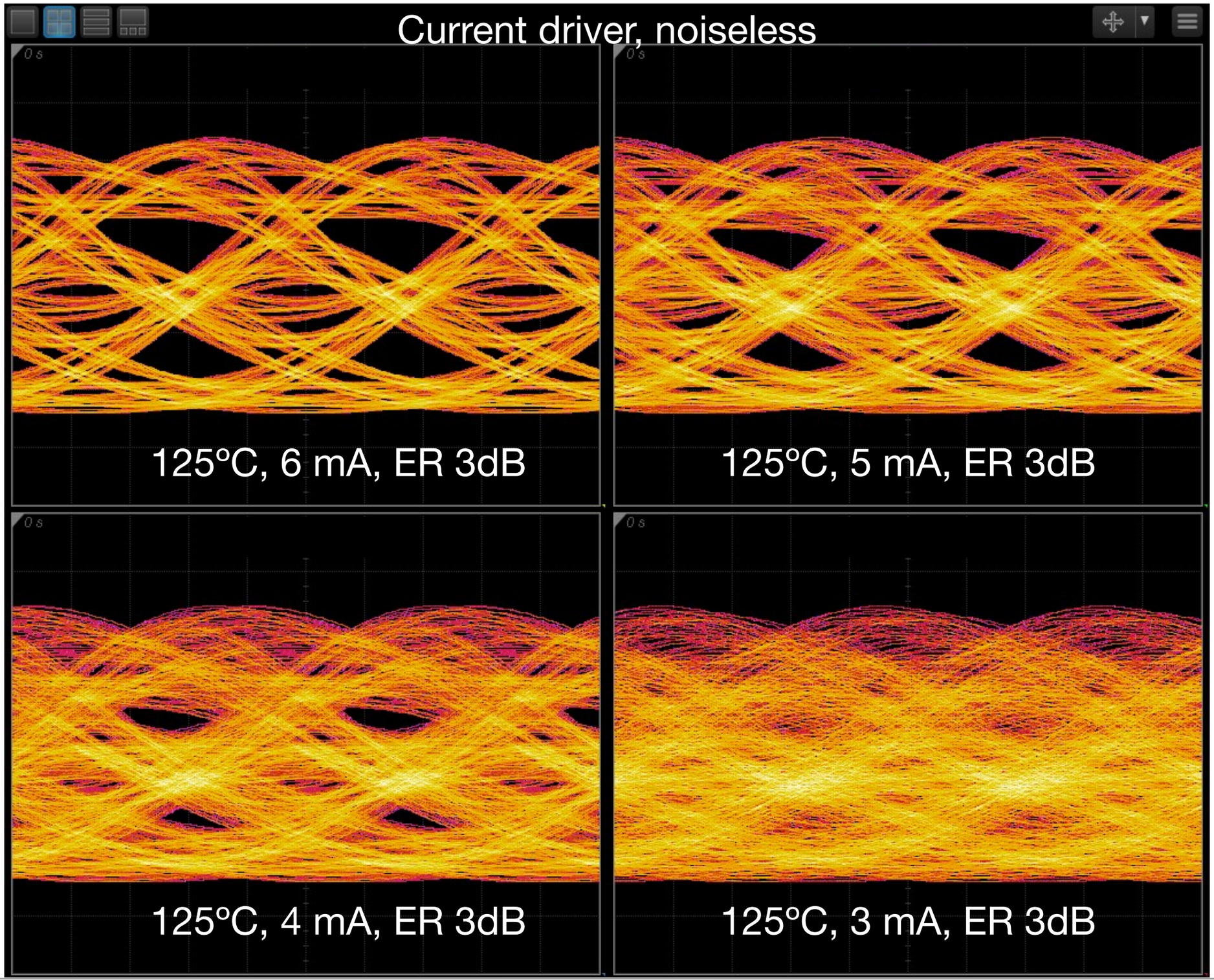
Eye diagram for 26.5625 GBd NRZ



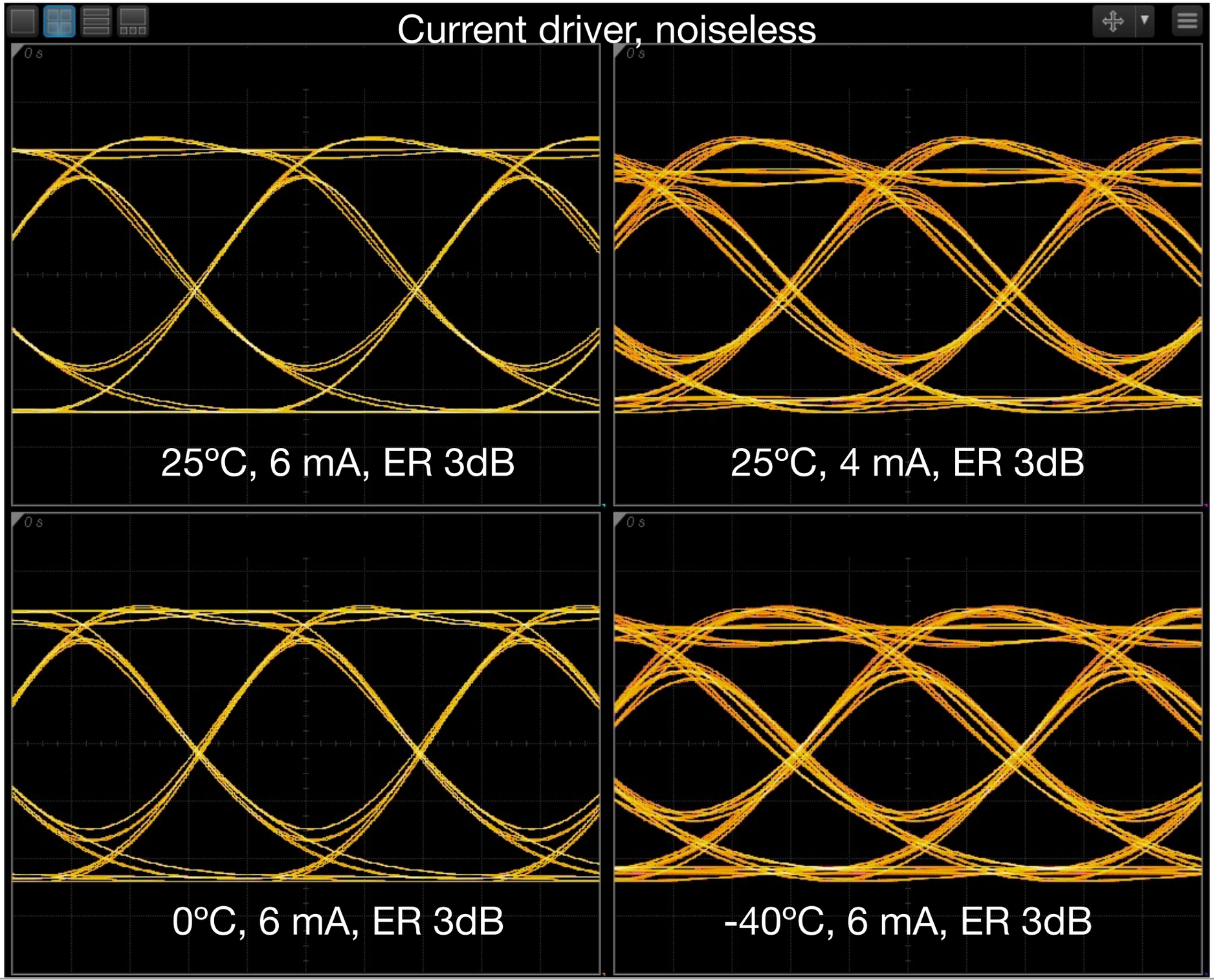
Eye diagram for 26.5625 GBd NRZ



Eye diagram for 26.5625 GBd NRZ



Eye diagram for 26.5625 GBd NRZ



References

- [1] Seyed Ehsan Hashemi, “Relative Intensity Noise (RIN) in High-Speed VCSELs for Short Reach Communication”, Master of Science Thesis in Photonics Engineering, Chalmers University of Technology